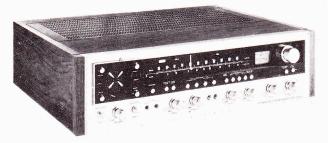


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PIONEER

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NOTE: THE MODEL QX-949A COMES IN TWO VERSIONS DISTINGUISHED AS FOLLOWS:

Round label on rear panel	Voltage	Type		
F	110V, 120V, 130V, 220V, and 240V (switchable)	General export model		
KCU	120V only	UL (U.S.A.) and CSA (Canada) approved		

1. SPECIFICATIONS

Semiconductors
FETs
ICs
Amplifier Section
Continuous Power Output from 20 Hertz to 20,000
(4 channels driven) 40 watts per channel (80hms)
50 watts per channel (40hms)
Continuous Power Output from 20 Hertz to 20,000 Hertz
(2 CHANNEL POWER BOOSTING SWITCH set at "2 CH")
(2 channels driven) 60 watts per channel (80hms)
75 watts per channel (40hms)
Continuous Power Output at 1,000 Hertz
(4-channels driven)
58 watts per charinel (4 ohms) Continuous Power Output at 1,000 Hertz
(2 CHANNEL POWER BOOSTING SWITCH set at "2 CH")
(2 channels driven) 65 watts per channel (80hms)
85 watts per channel (40hms)
Circuitry Direct Coupled Complementary OCL
Total Harmonic Distortion (20 Hertz to 20,000 Hertz)
(Continuous Rated Power Output) No more than 0.3%
(1 watt per channel Power Output,
8 ohms)
Intermodulation Distortion
(Continuous Rated Power Output) No more than 0.3%
(1 watt per channel Power Output,
8 ohms)
Output, Speaker FRONT: A, B, A+B
REAR: A, B, A+B
Headphones FRONT & REAR Low impedance
Damping Factor (1,000 Hertz, 80hms)
Input Sensitivity/Impedance
PHONO 1 2.5mV/50kohms PHONO 2 2.5mV/50kohms
PHONO 2 2.5117/50K01113 PHONO Overload Level (rms) 100mV
AUX
TAPE MONITOR (2CH, 4CH) 150mV/100kohms
Output Level
TAPE REC (2CH, 4CH)
Frequency Response
PHONO (RIAA equalization) 30 Hertz-15,000 Hertz ±1dB
AUX, TAPE PB 7 Hertz-25,000 Hertz $^{+0.5}_{-1}$ dB

Tone Control	
BASS ±10dB (
TREBLE ±10dB (10,	000 Hertz)
Loudness Contour	
(Volume control set at -40dB position) +6dB (100 Hertz) `
+3dB (10,	
Hum & Noise (IHF, Short-circuited, A Network)	,
PHONO	70dB
AUX, TAPE PB	
Filter	
LOW	(6dB/oct.)
HIGH 10,000 Hertz	(6dB/oct)
CD-4 Demodulator Section	(000/000)
	- dimetable)
Input Sensitivity 2.5mV (1–5mV	aujustable)
Input Impedance	
Harmonic Distortion	
Signal-to-Noise Ratio (IHF, A Network) More	than /UdB
Separation (STD Test Signal at 1kHz)	
Left ~ Right \ldots	
Front~Rear	30dB
FM Tuner Section	
Circuitry 2 MOS FETs, 1-stage RF Amplifier	
Tuning Capacitor, 6-sta	
Usable Sensitivity (IHF)	1 <i>.</i> 8μV
Capture Ratio (IHF)	
Selectivity (IHF)	
Signal-to-Noise Ratio	
Image Rejection (98MHz)	
IF Rejection (98MHz)	100dB
Spurious Rejection	100dB
Spurious Rejection	
AM Suppression	55dB
AM Suppression	55dB
AM Suppression Harmonic Distortion Mono Stereo	55dB 0.2% 0.4%
AM Suppression Harmonic Distortion Mono Stereo Frequency Response 50Hz-10kł	55dB 0.2% 0.4% Hz +0.2 -2.0 dB
AM Suppression Harmonic Distortion Mono Stereo	55dB 0.2% 0.4% Hz +0.2 -2.0 dB
AM Suppression Harmonic Distortion Mono Stereo Frequency Response 50Hz-10kł	55dB 0.2% 0.4% Hz ^{+0.2} Hz ^{+0.2} Hz ^{+0.2} -2.0 dB Hz ^{+0.2} dB
AM Suppression Harmonic Distortion Mono Stereo Frequency Response Stereo Separation	55dB 0.2% 0.4% Hz +0.2 Hz +0.2 Hz +0.2 dB tz -2.0 dB
AM Suppression Harmonic Distortion Mono Stereo Frequency Response Stereo Separation 1kHz 50Hz~10kHz	55dB 0.2% 0.4% Hz ^{+0.2} dB Hz ^{+0.2} dB 40dB 30dB
AM Suppression Harmonic Distortion Mono Stereo Frequency Response Stereo Separation 1kHz S0Hz~10kHz Sub-carrier Suppression	55dB 0.2% 0.4% Hz +0.2 dB Hz +0.2 dB Hz +0.2 dB 40dB 30dB 65dB
AM Suppression Harmonic Distortion Mono Stereo Frequency Response Stereo Separation 1kHz 50Hz~10kHz	55dB 0.2% 0.4% $z^{+0.2}_{-2.0}$ dB $z^{+0.2}_{-0.5}$ dB 40dB 30dB 65dB nbalanced

AM Section

Circuitry 1 Stage RF Amplifier, 3-
Sensitivity
(IHF, Ferrite Antenna)
(IHF, Ext. Antenna)
Selectivity
Signal-to-Noise Ratio
Image Rejection
IF Rejection
Antenna Built-in Fe
Miscellaneous
Built-in CD-4 Demodulator, Regular Matrix
SQ Full Logic Decoder
Power Requirements
or 110V, 120V

Power Consumption KCU type
AC Outlets
Dimensions
Weight: Without Package
With Package
Furnished Parts
FM T-type Dipole Antenna
CD-4 Test Record (PQX-1014)
FUSE 6A
FUSE 3A
Operating Instructions
NOTE:

Specifications and the design subject to possible modification without notice due to improvements.

QX-949A

3-ganged Tuning Capacitor

	•					•		•	•	3	00µV/m
•				•					•		. 15µV
				•							40dB
											50dB
											65dB
											85dB
errite Loopstick Antenna											

rix Decoder,

.... AC 120V 60 Hertz 20V, 130V, 220V and 240V (Switchable) 50/60 Hertz

..... 400W (450VA) 530W

. Unswitched 2, Switched 1 D(W) x 160(H) x 440(D)mm 1/16 x 6-5/16 x 17-5/16 in. 22.4kg, 49 lb 5oz 27.2kg, 59 lb 14oz

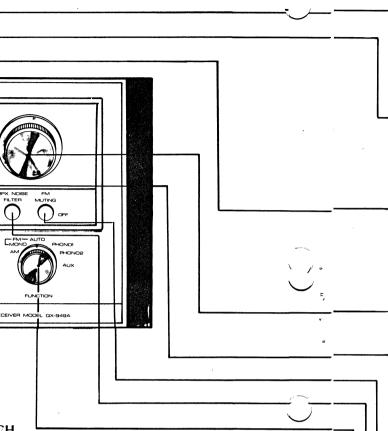
. 1 . 1 \cdot $\frac{1}{1}$ (5-line voltage model) . 1 . 1

4

2. FRONT PANEL FACILITIES

5

POWER SWITCH		
Push button switch for turning on AC power. Also activates switched AC outlets on the rear panel. Depress once for power ON; press again for power OFF.		
once for power on, press again for power of the		
BALANCE CONTROLS Individual balance controls for each of the four stereo channels.		
4-CHANNEL LEVEL INDICATOR	CD-4 CD-4 SEPARATION PHONES SEPARATION PHONES FLTER LOW HIGH	
All channels simultaneously displayed; relative intensity easily compared and adjusted.		MODE
VOLUME CONTROL		PIONEER 4 CHANNEL R
Control for adjusting sound volume. When rotated clockwise, 4-channel speaker sound in- creases.	INDICATOR LEVEL BUTTONS	
CD-4 SEPARATION CONTROLS Controls for adjusting front and rear separation when playing CD-4 records using a CD-4 cartridge.	Step attenuator switches convenient for reading of the 4- Channel Level Indicator. If both buttons are depressed, their values are added. Both positions Attenuation	MODE SWITC
Please refer to page 16 section on CD-4 channel separation adjustment procedures for detailed information. After adjustment, 2-channel records and matrix 4-channel records can also be played at the same setting.	Both undepressed0dB-10dB only depressed-10dB-20dB only depressed-20dBBoth depressed-30dBLOUDNESS BUTTONDepress when listening at low volume levels for proper sound balance relative to human ear sensitivity.	channel reproc 2CH: [4CH: CD-4; F
When playing records employing a conventional 2-channel cartridge, set these controls (left & right) to center position. LEFT Control: Front left (CH 1) and rear left (CH 2)	SPEAKER SWITCHES Up to four pairs of speakers can be connected and switched on and off (in pairs) with the SPEAKERS TAPE MONITOR BUTTONS (2CH, 4CH-1, 4CH-2)— These buttons are set to ON for checking the recording conditions or for playback with tape decks.	c
separation adjustment. RIGHT Control: Front right (CH 3) and rear right (CH 4)	SWITCH buttons. Button depressed: respective pair of speakers in opera- tion.2CH:This button is set to ON for monitoring a recording in progress or for playback with a 2-channel tape deck connected to the 2 CH	f C
separation adjustment. Be sure to readjust when replacing cartridge or stylus.	Button released: respective pair of speakers off. TAPE PB and REC terminals.	RM; [
	speaker systems can be used simultaneously (in different recording in progress or for playback with a	T
These SEPARATION CONTROLS are effective only when playing CD-4 record. When playing the other records, set	rooms, etc.). 4-channel tape deck connected to the 4CH-1 TAPE PB and REC terminals.	a SO ELULI E
MODE switch according to record type.	Separate controls are provided for front and rear bass and treble 4CH-2: This button is set to ON for monitoring a recording in progress or for playback with a	SQ FULL F LOGIC; re e
PHONES JACKS (FRONT & REAR)	FILTER BUTTON 4-channel tape deck connected to the 4CH-2 TAPE PB and REC terminals.	p
Accept stereo headphone jacks Front left and right (CH 1 & CH 3) can be heard when using FRONT jack.	LOW: Use this filter to cut out low-frequency noise (hum, rumble). NOTE: For record/playback or listening to broadcasts, leave	NOTE: Sound will n & CH 4) at c
Rear left and right (CH 2 & CH 4) can be heard when using REAR jack.	HIGH: Use this filter to cut out high-frequency noise (hiss). these buttons set to the OFF position. With the button set to ON no sound will be heard.	2 CH Power QX-949A has



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ch for 2-channel and each type of four duction method.

During 2-channel stereo reproduction (sound does not emerge from rear speakers.)

For reproduction of discrete 4-channel tape, cartridge tape, or CD-4 records. 2-channel source can also be played in this position. At this time the same sounds are obtained from the rear left and right speakers as from the front left and right speakers (CH2 - CH1; CH4 - CH3).

During 4-channel reproduction of Regular Matrix (RM) records and FM broadcasts. The matrix effect can also be obtained with a 2-channel program source.

or 4-channel reproduction of SO system ecords and FM broadcasts. The matrix ffect can also be obtained with a 2-channel rogram source.

not be heard from the rear speakers (CH 2 any setting of the Mode switch when the Boosting switch on the rear panel of the been set to 2 CH.

CD-4 INDICATOR LAMP

This lights to indicate that CD-4 record is being played (only when the MODE switch is set at 4CH CD-4).

└─ MODE & FUNCTION INDICATORS

Separately lighted indicators provide one-glance recognition of the QX-949A operating mode and function. Left to right: 2CH, 4CH, CD-4, RM, SQ, AM, FM, PHONO, AUX, STEREO (FM stereo indicator)

TUNING/SIGNAL METER

When selecting an AM broadcast, tune so that the dial pointer of the lower meter deflects as far to the right as possible. For an FM broadcast, use the lower meter in the same way. Precise FM tuning is also possible by adjusting so that the dial pointer of the upper meter is centered.

TUNING KNOB

Rotate to tune in AM or FM broadcasts.

DOLBY NR ADAPTOR BUTTON

Used when employing separately sold Dolby NR Adaptor. Set to ON (depressed) for listening to FM Dolby broadcasts, playing Dolby encoded tape, or monitoring Dolby recording via the adaptor.

- FM MUTING BUTTON

Circuit for eliminating inter-station noise and weak interfering stations when tuning FM broadcast. Up position is ON; depress button (OFF) when weak station reception is desired.

--- MPX NOISE FILTER BUTTON

Push this button to ON to eliminate high-frequency noise during FM stereo reception.

-FUNCTION SWITCH

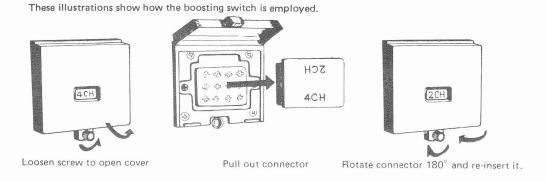
Switch for selecting program source for playing.

- AM: When listening to AM broadcasts
- FM MONO: When listening to FM monophonic broadcasts
- FM AUTO: Select when listening to FM stereo broadcasts. During FM monophonic broadcasts, automatically receives monophonic signals. Stereo indicator lights during FM stereo broadcasts.
- PHONO 1: When playing records on turntable connected to the PHONO 1 terminals.
- Same as above for PHONO 2 terminals. PHONO 2:
- AUX: When playing component connected to the AUX terminals.

7

ABOUT 2CH POWER BOOSTING SWITCH

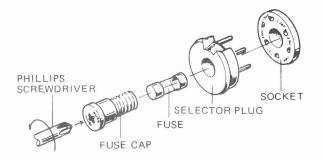
To increase available power when using the QX-949A for 2-channel reproduction, a convenient power select feature is incorporated. The covered compartment on the rear panel houses a reversable connector panel. When added power is desired during 2-channel operation turn off set power. Open the cover, remove the connector panel and rotate it 180° , then re-insert it and close the cover. Be sure to reverse the connector again before returning to 4-channel operation.



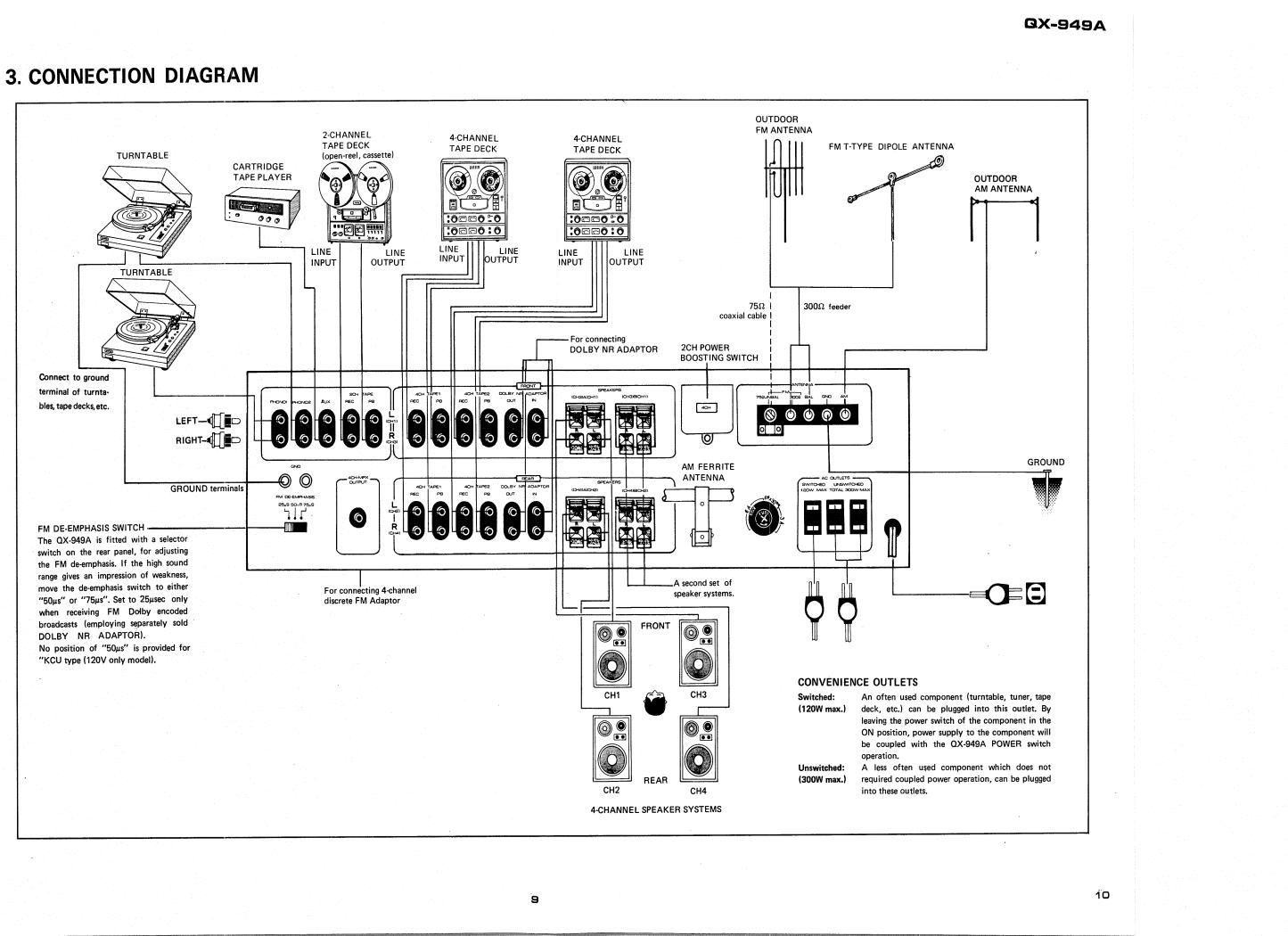
CHANGING LINE VOLTAGE SETTING AND FUSE (F MODEL)

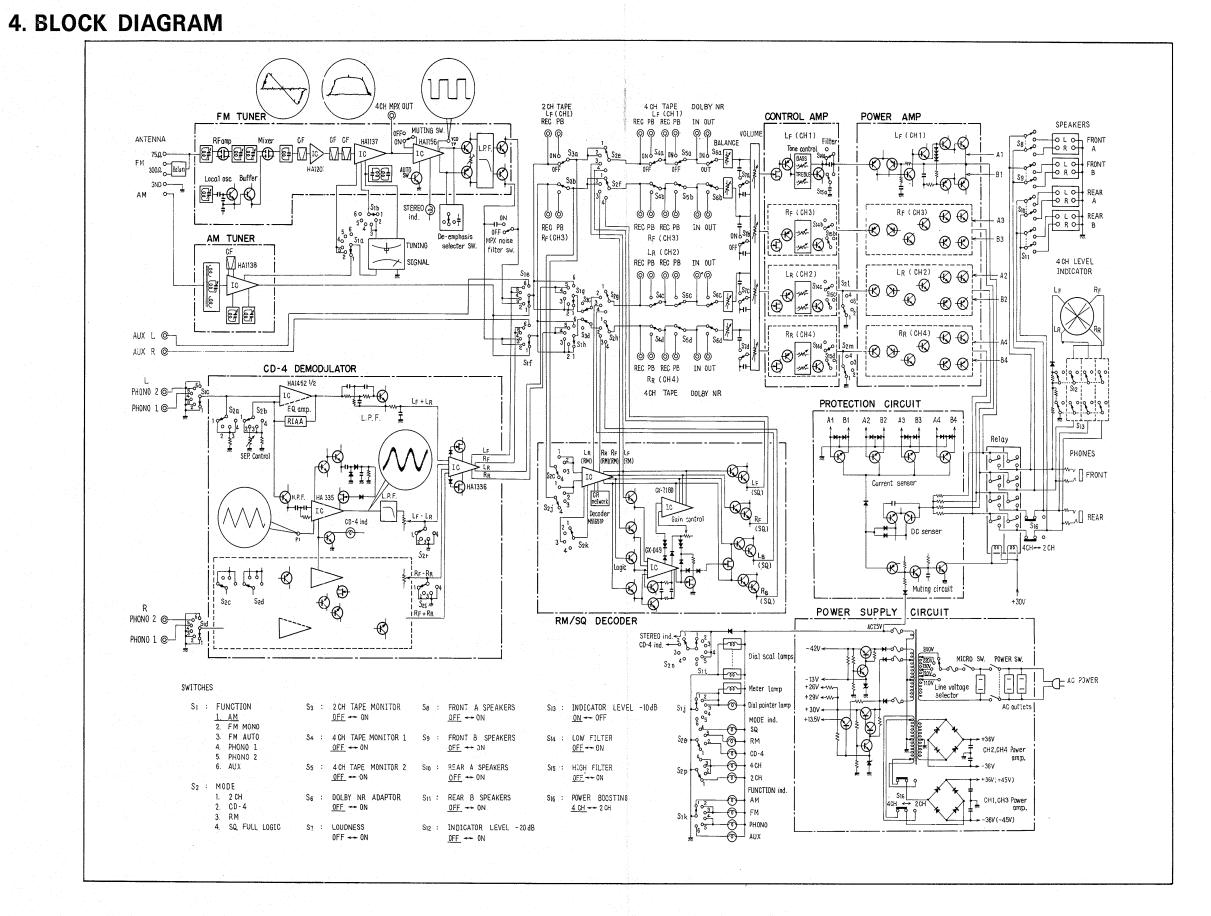
To remove the fuse, unscrew the fuse cap located in the center of the line voltage selector and withdraw it, together with the fuse. Next, pull the line voltage selector plug out of its socket, rotate it until the cutaway aligns with the appropriate line voltage marked on the back of the unit, then push it back into its socket. It is important to check the rating of the fuse; a 3A fuse should be used with either 220V or 240V, while a 6A fuse should be used for 110V, 120V, or 130V operation. If the fuse rating is correct, reinsert it and screw in the fuse cap.

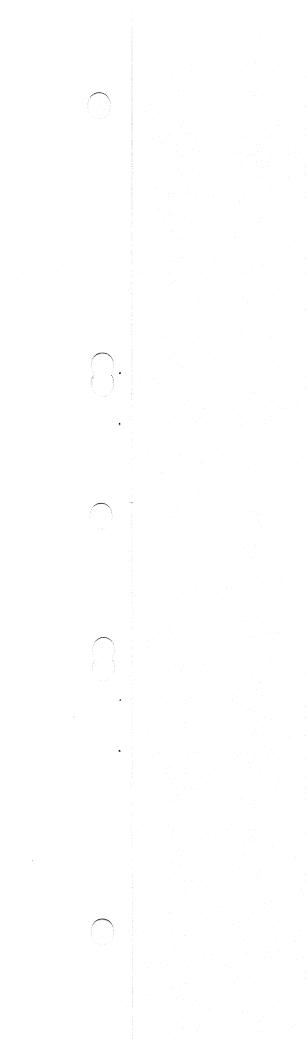
No selector plug is provided for "KCU" type (120V only model).



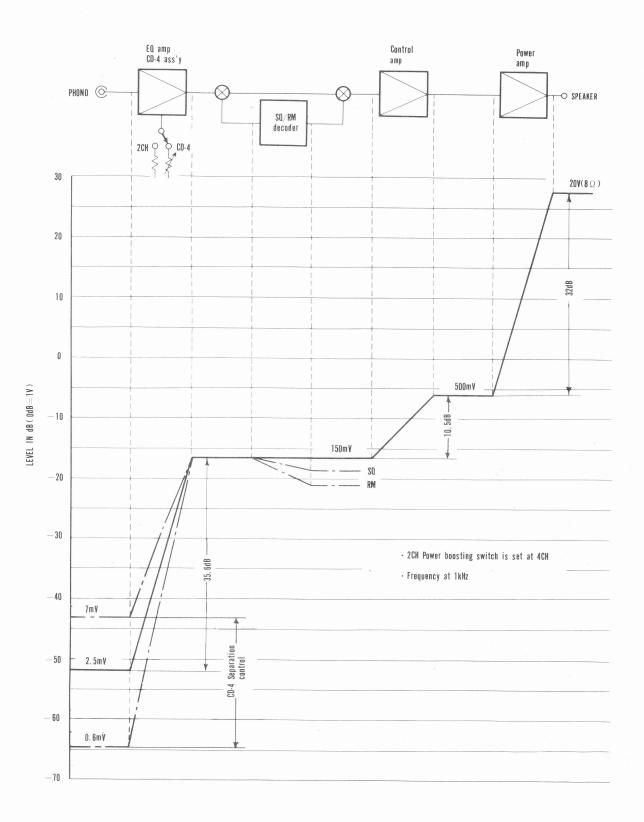
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5. LEVEL DIAGRAM



13

6. CIRCUIT DESCRIPTIONS

6.1 FM TUNER SECTION

Front End

This consists of a 4-gang variable capacitor tuning circuit, dual-gate MOS FET RF amplifier and mixer, and local oscillator with buffer. By employing a grounded gate-2 of the dual-gate MOS FET, the circuit becomes equivalent to a cascade amplifier, providing large gain with stable operation in the RF amplifier.

In the mixer stage, the signal is applied from the local oscillator to gate-2. This method allows input power from the local oscillator to be minimized and features low mutual interference. A variation of a Clapp circuit forms the local oscillator and by inserting a buffer amplifier between it and the mixer, the oscillator load is reduced and waveform distortion suppressed. The oscillation frequency drawing effect is also eliminated, to provide extremely stable operation even with strong inputs.

IF Amplifier and Detector

These are composed of three dual-element ceramic filters and two integrated circuits. The first stage IC (HA1201) incorporates a current limiter, while the second stage IC (HA1137) is shown in Fig. 2. When pin 12 of HA1137 is at more than ± 70 kHz detuning and with an extremely low input level,

a DC voltage is produced. By setting the FM Muting switch to ON, pin 12 is connected to pin 5, and the analog switch in HA1137 is operated ON-OFF to perform muting.

Multiplex Decoder

Demodulation is performed by switching detection with the circuit contained in the IC (HA1156), depicted in Fig. 3. A phase locked loop (PLL) produces a 38kHz square wave synchronized to the pilot signal. The two gates are alternately switched ON-OFF by this signal to derive the L and R channels from the composite signal. By detecting the pilot signal level, the switching signal from PLL to demodulator is operated ON-OFF. The STEREO indicator lights at the same time.

6.2 AM TUNER SECTION

This consists of a 3-gang variable capacitor tuning circuit, a dual element ceramic filter and an IC (HA1138). The IC (Fig. 4) contains an RF stage and two IF amplifier stages.

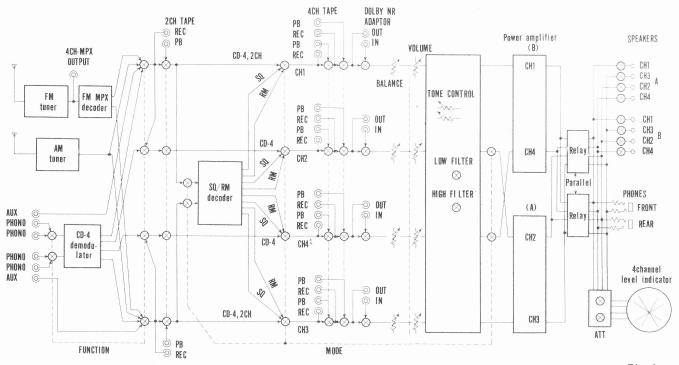
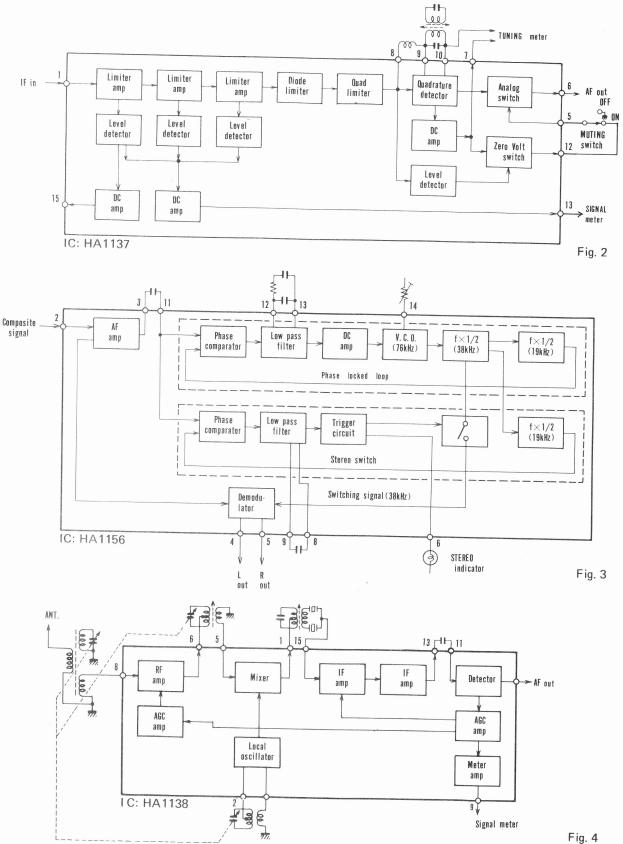


Fig. 1



φ.

Fig. 4

6.3 CD-4 DEMODULATOR SECTION

Fig. 5 illustrates the composition of this section.

Sum Signal System

Input o

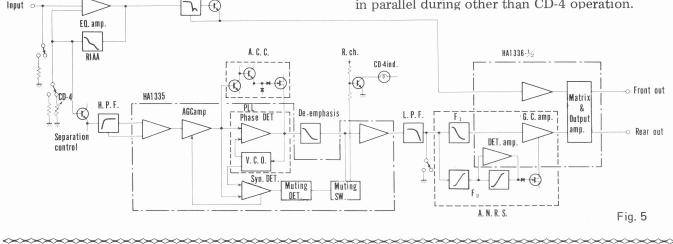
HA1452.1/2

IC HA1452 is an orthodox 2-channel equalizer amplifier. In CD-4 operation, a variable resistor is inserted in the NFB circuit to provide separation control by varying the main signal (sum signal) gain. Although the final objective of the CD-4 demodulator is to matrix the sum and difference

I.P.F.

signals, as the difference signal is demodulated from a frequency modulated 30kHz carrier (sub signal), and the sum signal varies according to the cartridge output level (though indirectly related), level matching becomes necessary.

In other than the CD-4 mode, a fixed resistor replaces of the variable resistor to provide a fixed gain (35.6dB at 1kHz) equalizer amplifier. The inclusion of a balanced power supply with this circuit maintains input and output point potentials at 0V, preventing click noises when switches are operated. The $100k\Omega$ impedance of this circuit is changed to $50k\Omega$ by inserting two $100k\Omega$ resistors in parallel during other than CD-4 operation.



RECORDING AND PLAYBACK OF CD-4 DISCS

The CD-4 disc is a recent development. Being a "Discrete" 4-channel medium, it features excellent channel separation when played over suitable 4channel equipment, but can also be played as a conventional 2-channel stereo record.

Fig. 6 shows the configuration of signals present in a CD-4 record.

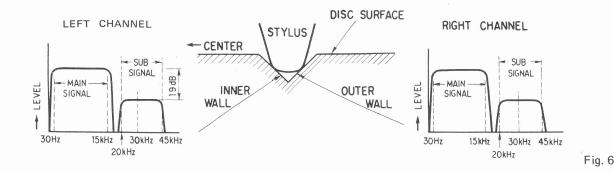
Each of the two sub-signals occupies a frequency modulated supersonic carrier with a center frequency of 30kHz.

The sub-signal conveys the "Front-Rear" difference information. The main signals are recorded as a conventional stereo record, occupying the 30Hz ~ 15 kHz audio band and conveying the "Front+Rear" sum information.

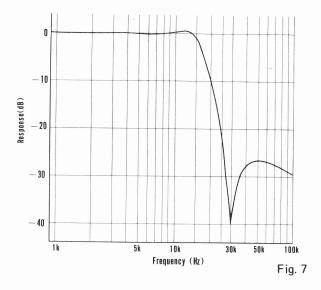
From these sum and difference signals, the original 4 channel signals are retrieved in a series of algebraic operations performed in the demodulator:

> (Lf + Lr) + (Lf - Lr) = 2Lf(Lf + Lr) - (Lf - Lr) = 2Lr(Rf + Rr) + (Rf - Rr) = 2Rf(Rf + Rr) - (Rf - Rr) = 2Rr

where "R" stands for Right, "L" for Left, "f" for front, "r" for rear.



The equalizer amplifier output goes through a low pass filter (LPF) to remove the sub signal (30kHz FM signal). This LPF is an active filter whose frequency response is shown in Fig. 7.



Difference Signal System

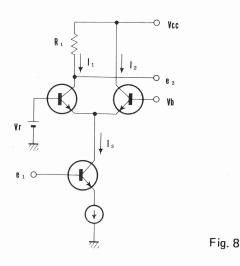
The sub signal is taken from the equalizer amplifier NFB circuit. As it does not pass through the RIAA playback standard equalizer, it possesses a flat frequency response. After passing through a high pass filter (fc = 27kHz, 12dB/oct.), the sub signal enters IC HA1335.

This IC contains a phase locked loop (PLL) FM demodulator circuit, an automatic gain control (AGC) circuit to stabilize the PLL input signal, a muting circuit to cut the demodulated output in the absence of an input signal, and a demodulated signal amplifier. In addition to the IC, a de-emphasis circuit, automatic capture range control (ACC) circuit, LPF, HPF, indicator lamp drive, and other circuits are used to demodulate the difference signal from the sub signal.

***AGC** Amplifier

Fig. 8 shows the AGC amplifier principle. In this circuit, e_1 is the input signal voltage, e_2 the output signal voltage, Vr the reference voltage, and Vb the control voltage.

If Vb is much greater than Vr, I_3 becomes approximately equal to I_2 and $e_2 \approx 0$. Conversely, if Vb is much less than Vr, I_3 becomes approximately equal to I_1 and e_2 reaches a maximum (determined by the maximum gain of the AGC amplifier). The amplifier gain can therefore be controlled by Vb in this manner, Vb being obtained from a synchronous detector.

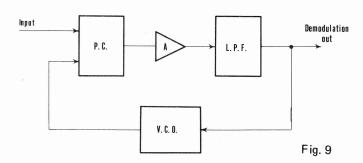


***FM Demodulator**

The block diagram of the PLL FM demodulator circuit is depicted in Fig. 9. This circuit consists of a voltage control oscillator (VCO), phase comparator (PC), DC amplifier (A) and low pass filter (LPF), with a type of NFB loop following the input signal. The VCO oscillates at a controlled frequency according to the LPF output voltage. A voltage proportional to the phase difference between the input signal and VCO oscillation output is generated in the PC. By using this voltage to control the VCO oscillation, the oscillation becomes locked to the input signal phase.

If the input signal is frequency modulated, the control signal obtained from the LPF becomes the FM demodulated output. With an excessively large frequency deviation of the input signal, which the PLL circuit cannot follow, the lock becomes disengaged. The frequency range in which locking can be performed is termed the lock range.

Locking also becomes impossible when the VCO free running frequency (oscillating frequency without an input signal) and input signal frequency are excessively separated. The frequency range in which locking can be performed is termed the capture range. The locking and capture ranges are determined by the PLL loop gain and LPF constant.



***Synchronous Detector**

The PLL produces a signal in phase with the input signal. By employing this to switch the input signal, full-wave rectification and a DC voltage proportional to the input signal oscillation are obtained. The same in-phase frequencies are required at this time. The frequencies become the same if the PLL is locked, they then become inphase by shifting the VCO output phase by 90° .

A DC voltage rise proportional to the input level is obtained as AGC from this circuit, together with muting in the form of a DC voltage drop inversely proportional to the input level.

*Muting Circuit

The muting circuit is shown in Fig. 10.Q1 and Q2 form a Schmidt trigger. Q5 is inserted between the difference signal demodulator circuit signal line and ground. The collector of Q4 is connected to the CD-4 indicator circuit and its potential employed to determine whether or not the CD-4 demodulator circuit operates. The synchronous detector provides the input to this circuit.

DC voltage is supplied to the muting circuit from the synchronous detector when the sub signal is absent. Q1 then switches ON, Q2 OFF, and Q3, Q4 & Q5 ON. The difference signal demodulator circuit line is thus shorted to ground and Q4 collector potential reduced.

When a CD-4 record is played and the sub signal is applied to the synchronous detector, the input DC voltage of the muting circuit declines in inverse proportion to the sub signal level. If the sub signal is above a certain level, the Q1 & Q2 Schmidt trigger circuit reverses: Q1 switches OFF, Q2 ON, and Q3, Q4 and Q5 OFF. This removes the short to ground of the difference signal demodulator circuit output line and Q4 collector voltage increases.

+ Vcc (CD-4 Indicator

*CD-4 Indicator Circuit

Q6 in Fig. 10 is the lamp drive transistor. With a high Q4 collector voltage (during CD-4 play), Q6 is switched ON and the CD-4 indicator lamp lights. This lighting operation is synchronized to the previously described muting circuit operation (in practice, it is slightly delayed). The lamp lights if either the right or left channel gate is open, and extinguishes when both gates are closed.

*ACC (Automatic Capture Range Control)

The PLL does not lock to frequencies out of the capture range and cannot follow frequency variations exceeding the lock range. Automatic control of the PLL capture range is provided by the ACC. It also functions to suppress noise and prevent misoperation with sources other than CD-4.

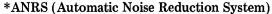
Peak values associated with amplitude variations in the PLL input sub signal, transients with which AGC is ineffective, noise, main signal interference with the sub signal (sub signal modulated by the main signal) and other causes are converted into a DC voltage. By using this voltage to regulate the equivalent internal resistance of the FET in the PLL load circuit, the PLL capture range (lock range) can be automatically controlled.

There is no PLL detector output with respect to sub signal AM components. However, if the sub signal is AM modulated by noise or the main signal, this can also be considered as phase modulation. This effect is minimized since amplification of the sub signal AM component narrows the PLL lock range (playback bandwidth becomes narrow).

AGC amplifier gain is maximum with no input signal. If some sort of input becomes available at this time, a large output can be temporarily obtained (until the AGC takes effect). For this reason,

> the PLL capture range is narrowed by the ACC and remains completely unlocked with an input other than the sub signal. The PLL locks with a sub signal input and when the AGC takes effect, the PLL lock range becomes widened by the ACC.

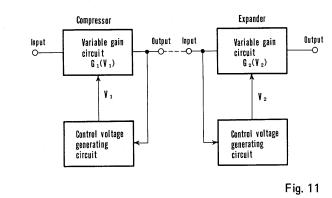
· .



The ANRS is employed in the difference signal system for CD-4 records in order to improve SN ratio and reduce crosstalk distortion from the cartridge. It is not used in the sum signal system in order to preserve compatibility with 2-channel stereo records.

The ANRS consists of a mutually reciprocal compressor and expander compose the ANRS (Fig. 11). In CD-4 application, compression and expansion are performed in the area of 700Hz and above 2kHz. Fig. 12 shows the ANRS composition used in this set.

Although expansion is normally performed separately for middle and high frequencies, it is not divided in this set (in practice, this poses no difficulty). Filter F1 possesses ANRS expansion properties when compensation is maximum. F2 is a middle and high frequency bandpass filter (bands at which ANRS is employed). The output of this section is amplified and rectified, then used to control the equivalent internal resistance of the FET.



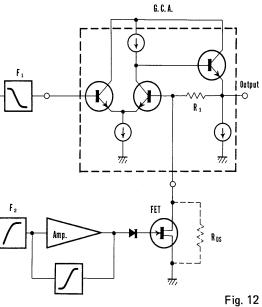
This FET regulates the NFB in the gain control amplifier (GCA). Its equivalent internal resistance declines with a middle and high frequency input to the circuit, decreasing NFB to the GCA and increasing GCA gain. As these frequencies increase further, the resistance continues to decline and eventually saturates. At this point, the F1 frequency response is cancelled by GCA frequency response, resulting in a flat response in the ANRS expander circuit. In this manner, the GCA compensates F1 frequency response according to the input level.



Consequently, the ANRS frequency response becomes flat above a certain level and when middle and high frequency levels decline, it approaches the frequency response of F1. Below a certain level, the response of F1 is attained. Applying ANRS reduces noise level by an average of 8dB. Also, if 15dB separation is available in the cartridge, crosstalk distortion becomes negligible.

18

QX-949A



*Matrix Section

Matrixing (adding or subtracting) the front and rear sum signals of the main signal system, and the front and rear difference signals of the sub signal system, the front and rear signals are derived.

 $\mathbf{M} = \mathbf{F} + \mathbf{R}$ S = F - RM + S = (F + R) + (F - R) = 2FM - S = (F + R) - (F - R) = 2R

6.4 SQ FULL LOGIC/RM DECODER SECTION

SQ System

The Matrix four channel system utilizes 2-channel media (tape, records, broadcasts, etc.) to transmit 4 or more channel signals. Four channel playback systems employ matrixing 4-2-4 (n-2-4) to convert 2-channel into 4-channel. The main systems currently available for this purpose are RM (Regular Matrix) and SQ (Stereo Quad).

With the RM system, if the only sound source is LF (left front), -3dB crosstalk occurs in the RF (right front) and LB (left back). In the SQ system however, -3dB occurs in LB and RB (right back). RM and SQ are therefore not compatible.

Fig. 13 shows the basic SQ decoder construction and signal vectors. LT and RT are combined in LB and RB, while LF' and RF' are taken directly from LT and RT. LB' and RB' are obtained from LT and RT by phase shifting and blending. But LB' and RB' contain respective LF, RF other than necessary components. Left and right separation remains good since LF' does not combine with RF, and RF' does not combine with LF. If the sound source is CF (center front) or CB (center back), front to rear separation cannot be obtained since LF', RF', LB' and RB' all become the same volume. The logic circuit is provided for improve this effect.

With CF crosstalk to LB and RB is at out of and since with CB crosstalk to LF and RF is also at out of, only these anti-phase components are cancelled. This is termed front-back logic. The objective of full logic is to deal not only with CF and CB sound sources, but also with various other directions.

Front-back logic performs CF and CB detection, while wave matching logic performs LF, RF, LB and RB detection. The combined detector signal passes through a time constant circuit and is applied to the gain control circuit, where gain is controlled in order to adequately reduce the crosstalk level.

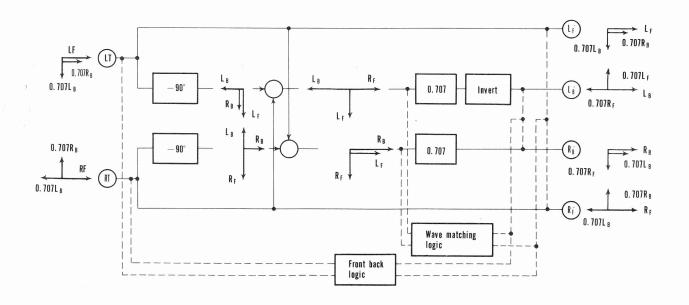
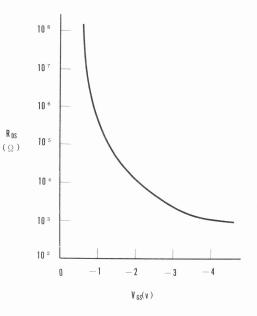


Fig. 13

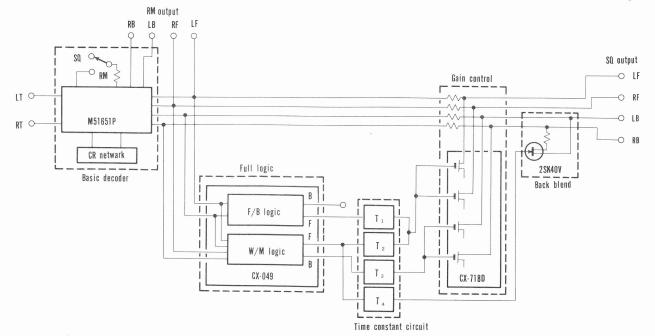
Circuit Composition

Three ICs are employed, as shown in Fig. 15. M51651P is an SQ basic decoder and can function as an SQ decoder without independent logic. Although a phase shift network is not included, by a CR network, this IC perform to shift the phase 90° with cover wide range. A selector switch also permits the IC to be used as an RM decoder. During RM, a blend resistor is added at the front, while the rear is blended internally by the IC and taken from separate terminals.

CX-049 is a high density full logic IC incorporating both wave matching and front back logic. CX-718D is a gain control IC and contains four MOS FETs to form a variable resistance voltage control circuit. Since these MOS FETs are P channel enhancement types, equivalent internal resistance becomes infinite when gate voltage is zero. By applying a negative voltage to the gate (Fig. 14), the equivalent internal resistance can be varied from infinity to several hundred ohms. 2SK40V (FET) is employed for back blending. With a CF sound source, it functions to cancel the mutually opposite crosstalk phase to LB and RB. This is an N channel depletion type junction FET and when the gate voltage is zero, the channel is already established. LB and RB become normally blended for this reason, and the gate becomes open only in the case of a single signal from LB or RB.







Operating Description

The input signal (LT & RT) enters the SQ basic decoder (M51651P), where 4-channel signals LF, RF, LB and RB are obtained by the SQ decode matrix, then these signals enter the gain control, back blend and logic circuits. The front-back logic produces a positive voltage with a CF sound source, and a negative one with a CB source. This voltage passes through the time constant circuit and is applied to the gates of the MOS FETs for LF and RF gain control.

As these FETs are P channel enhancement types, their equivalent internal resistance decreases only when a negative voltage is applied. Front (LF & RF) output signal levels are attenuated with a CB sound source. For rear control, wave matching logic produces a negative voltage with respect to a front single signal (LF or RF) and a positive voltage with respect to a rear single signal (LB or RB). Front control is also performed by producing the reverse polarity of these voltages.

The rear control voltage passes through the time constant circuit and is applied to the gates of MOS FETs for LB and RB gain control. The front control voltage passes through the time constant circuit and is applied to the gates of the junction FET for back blend and the MOS FETs for LF and LB gain control. As the junction FET is an N channel depletion type, LB and RB are normally blended, but the device becomes open when a negative voltage is applied.

The detector outputs of the full logic IC (CX-049) with respect to sound source are as shown in the following table.

	1	LF	RF	LB	RB	CF	СВ	Gain control*
F/B	F	0	0	0	0	+		LF, RF
logic	В	0	0	0	0	-	+	* *
W/M	F	+	+	-	water	0	0	LF, RF***
logic	В	-		+	+	0	0	LB, RB

*Gain control operates (attenuates) with (-) detecting mode.

**Front back logic output B is not employed.

***Back blend is not performed only when wave matching logic output F mode is (-).

CAUTION

The gain control IC (CX-718D) is an MOS (metal oxide semiconductor) type and subject to dielectric breakdown from static electricity. Note the following precaution when handling. *Do not remove the aluminum cap from the IC until it has been installed in teh circuit. First solder the IC to the circuit board, then remove the aluminum cap.

6.5 CONTROL AMPLIFIER CIRCUIT

The control amplifier circuit of the QX-949A is the NFB type, using a FET (field effect transistor) in the first stage.

The FET amplifier being a controlable voltage type, which holds the input impedance constant, even if the level of the NFB changes, and has additional advantage as a coupled circuit, as the input impedance can be raised.

Low Frequency Control

The low frequency control circuit is shown in Fig. 16, and the equivalent circuit, when boosting low frequency, is shown in Fig. 17.

As the parallel impedance of VR1 and C29, in Fig. 17, is high at low frequency, the volume of the NFB decreases and the gain in the low frequency range increases.

The equivalent circuit, when cutting out low frequencies, is shown in Fig. 18. In this case, the input signal is applied to Q9, through the parallel impedance of VR1 and C33, which is high in the low frequency range and suppresses the lower frequency signals.

High Frequency Control

The high frequency control circuit is shown in Fig. 19, and the equivalent circuit, when boosting high frequencies, is shown in Fig. 20.

In this circuit, the input signal is applied to Q9 through the parallel impedance circuit. This impedance is small in the high frequency range and produces a signal with an enhanced high range. Fig. 21 shows the equivalent circuit when cutting out high frequencies. As the impedance of R53, R41 and C41 of the circuit becomes small, the level of the NFB increases and the gain of the circuit decreases.

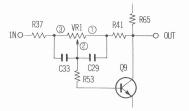


Fig. 16

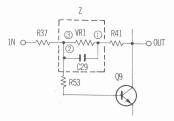


Fig. 17

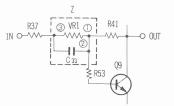


Fig. 18

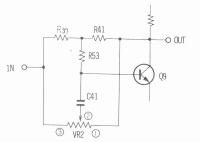


Fig. 19

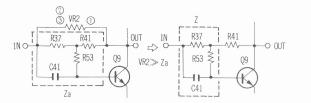


Fig. 20

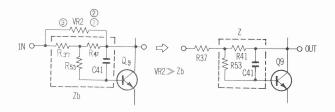


Fig. 21

6.6 POWER AMPLIFIER SECTION

This unit possesses four power amplifiers. The circuitry employs a balanced power supply and consists of direct-coupled Darlington connection pure complementary OCL amplifiers. By applying 100% DC NFB from the output stage center point to the first stage differential amplifier, circuit DC gain becomes 0dB. Since the center point potential is determined by the first stage base potential, temperature compensating and fine adjustment circuits are included in the first stage base bias circuit to maintain the center point potential at 0V.

2-channel Power Boosting Circuit

The power supply can be boosted when using this unit as a 2-channel stereo amplifier (using only ch1 and ch3, and with the MODE switch set to 2CH). Power transistors of channels 1 and 3 are of higher rating than those of channels 2 and 4. Their supply voltage can be raised during 2-channel operation to provide increased power to each channel.

Power boosting is available by turning over the rear panel plug. This raises the power transformer secondary winding taps and opens CH2 and CH4 power amplifier output circuits.

For safety reasons, a microswitch in the power transformer primary side cuts off the power supply when the selector plug cover is opened.

6.7 PROTECTION CIRCUIT

This protection circuit functions to protect the speakers from damage due to short-circuit of the load, etc., and performs a muting operation to cut noise and distortion which occur when switching the power on and off.

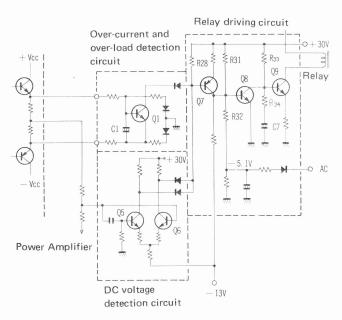
The circuit is shown in Fig. 22, and consists of a bridge type over-current and overload detector, a differential amplifier DC voltage detector, and a power switch on/off detector section.

Relay Driving Circuit

Q7 - Q9, in Fig. 22, comprise the relay driving circuit.

In the normal condition reverse bias is applied to the base of Q7, and Q7 is in a cutout condition. When one of the above mentioned detection circuits goes on, current flows through R28, the base potential falls and Q7 is turned on. Consequently Q8 comes on and Q9 goes off. When Q9 goes off, the current of the relay circuit is cut, to release the switch of the output circuit.

When the power switch is turned on, a delay operation occurs in this circuit. R33, R34 and C7, in the base circuit of Q9, are the time constant elements which determine the delay time. When the power switch is switched on, C7 charges to a potential of +30 volts through R33 and R34, and Q9 is kept in the OFF condition during this time. When the power source is switched off the muting operation of Q8 prevents shock noise. In the normal condition, the potentials of +30volts and -5.1 volts are applied to Q8 through R31 and R32. The resultant potential at the base of Q8 is -1 volt in the cutout condition. When the power supply is turned off, the potential of -5.1volts disappears immediately, due to the small time constant of the power circuit. Thus a positive base potential remains, switching Q8 on, which in turn switches off Q9 and hence the relay.





QX-949A

Over-current and Overload Detection

The equivalent circuit of this detector section is shown in Fig. 23, and Fig. 24 shows the equivalent circuit at the time of a positive half cycle. When this equivalent circuit is overloaded, the balance of the bridge, formed by RE1, R1, R9 and RL, is disturbed, and a potential is produced between b and a in such a direction that Q1 is turned on. When Q1 is turned on, the collector current increases, the relay driving circuit functions and the relay switch of the output circuit is turned off. After the cause of the overload is removed, the bias of Q1 is reduced and the relay switch turns on to automatically restore normal operation. Fig. 25 shows the equivalent circuit at the time of a negative half cycle. In this circuit a potential is produced between b and e as above, and Q1 is turned on.

Detection of DC Voltage

This is a differential amplifier consisting of Q5 and Q6, as shown in Fig. 26. The bases of Q5 and Q6 are connected to the junction-points of the power amplifiers. When the DC balance of the power stage is lost for some reason, a potential difference is produced in the input signal to the differential amplifier, and the collector currents of Q5 and Q6 are put out of balance. Thus, the relay driving circuit functions, and the relay switch is turned off.

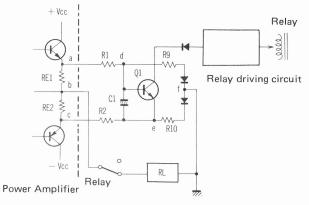
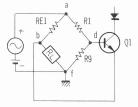


Fig. 23





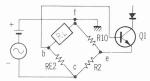


Fig. 25

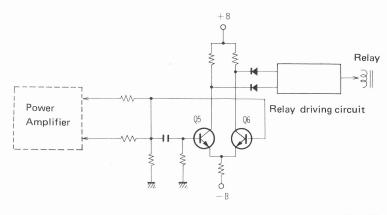


Fig. 26

7. DISASSEMBLY

Que o

7.1 WOODEN CABINET

Unscrew the two screws holding each side, then lift the back of the wooden cabinet upward.

7.2 BOTTOM PLATE

Unscrew a total of the 14 screws holding it in place.

(a)

9

9

Ŷ

9

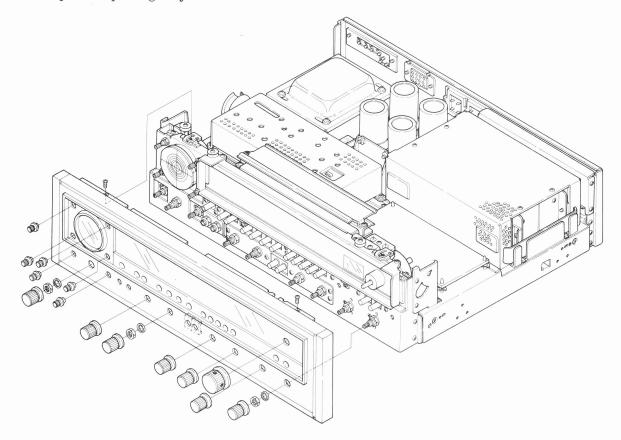
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2 Bolton

7.3 FRONT PANEL

Pull off knobs. For TUNING knob, loosen the setscrews with a hexagonal wrench before removing it. Unscrew the two screws in the upper edge of the front panel, and the three nuts from the shafts. Then pull the panel gently forward.



8. ADJUSTMENTS

*Do not attempt to adjust the CD-4 assembly or RM/SQ assembly. These adjustments require special test equipment, including a CD-4 signal generator, SQ encoder and other apparatus.

Required Measuring Instruments

- FM signal generator
- MPX signal generator
- AM signal generator
- Millivolt meter
- Distortion meter

8.1 AM SECTION

- 1. Set AM signal generator at 400Hz 30% modulation. Connect to AM antenna terminal via 1kohm resistor.
- 2. Connect oscilloscope and voltmeter in parallel to unit's TAPE REC terminals.
- 3. Tune signal generator and unit to 600kHz. Set signal generator output level at approx. 30dB.
- 4. Adjust T8 and T7 on tuner assembly and core of ferrite bar antenna for maximum output level reading.
- 5. Now tune unit and signal generator to 1,400kHz.
- 6. Adjust TC5, TC6 and TC7 on tuner assembly for maximum output level reading.
- 7. Repeat steps 3 thru 6 several times to obtain maximum readings at both frequencies.

8.2 FM SECTION

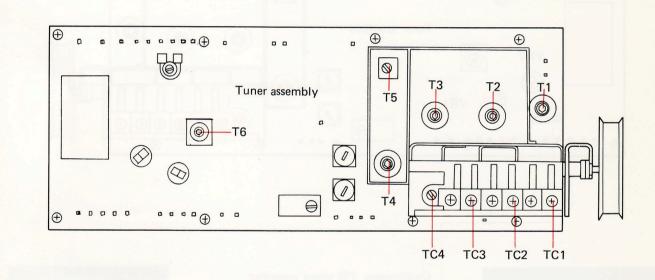
1. Set the FM signal generator for 400Hz modulation at 100%.

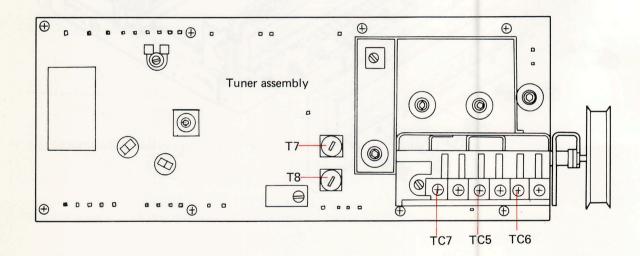
Connect generator output to the FM antenna terminals through a 300Ω balanced dummy antenna.

- 2. Connect the oscilloscope, voltmeter, and distortion meter in parallel across TAPE REC jack.
- 3. Set the signal generator output level to $8 \sim 10$ dB.

Set the signal generator and set dials to 90MHz.

- 4. Adjust cores of T4 (tuner assembly) and T1, T2, and T3 to obtain peak output.
- 5. Set signal generator and set dials to 106MHz.
- 6. Adjust TC4 (tuner assembly) and TC1, TC2, and TC3 to obtain peak output.







- 7. Repeat steps (3) through (6) several times, to obtain optimum tracking.
- 8. Set the frequency to 90MHz and adjust the T5 core of the tuner assembly to obtain peak output.
- 9. Detune the set so that noise only is received. Adjust the primary (bottom) core of T6 so that the tuning meter pointer indicates the center position.
- 10. Set signal generator and set dials to 98MHz. Set signal generator output level to 60dB. Carefully tune the set to this frequency as indicated by the tuning meter.
- 11. Adjust the secondary (top) core of T6 (tuner assembly) for minimum distortion.

 300Ω

 J00Ω

 dummy

 Oscilloscope Distortion meter

 Oo

 Oo

 Oo

 Oo

 Oo

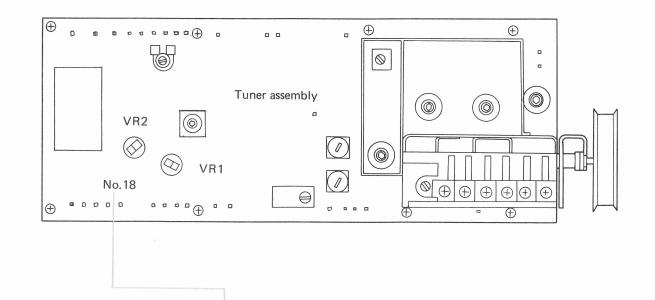
 Oscilloscope Distortion meter

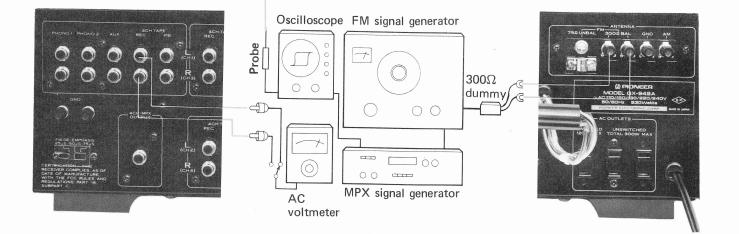
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8.3 FM MPX SECTION

- 1. Set FM signal generator at external modulation. Connect to unit's FM antenna terminals via 300-ohm balanced dummy antenna. Set FM SG output to 60dB.
- 2. Adjust MPX signal generator to obtain main signal modulation of 1kHz, 67.5kHz frequency deviation. Connect to FM SG's external modulator terminals.
- 3. Connect the oscilloscope horizontal inputs to MPX SG's PILOT OUT terminals and Vertical inputs to No. 18 terminal of tuner assembly.
- 4. Tune unit and FM SG to 98MHz.
- 5. Produce a Lissajous pattern on oscilloscope and adjust VR1 to make the pattern still.
- 6. Then set signal generator for modulation of L (later R) and pilot. Adjust VR2 to obtain maximum channel separation.





8.4 POWER AMPLIFIER SECTION

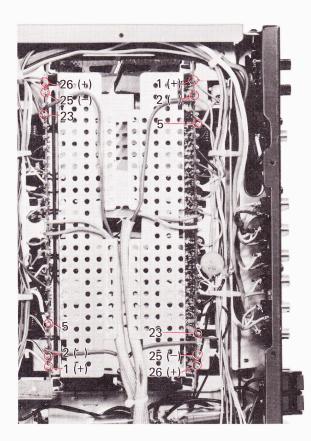
- 1. Do not connect load to speaker terminals. VOLUME Control set at minimum.
- 2. Set power boosting switch to 4CH position. Then energize unit.
- 3. For first approximately six seconds, the relay remains open, keeping the unit muted. Confirm that all voltages are as indicated in the circuit diagram on page 98.
- 4. If voltages are greatly different from rated values, shut off power immediately. Check suspicious areas, especially power supply unit.
- 5. If the relay opens immediately after the power

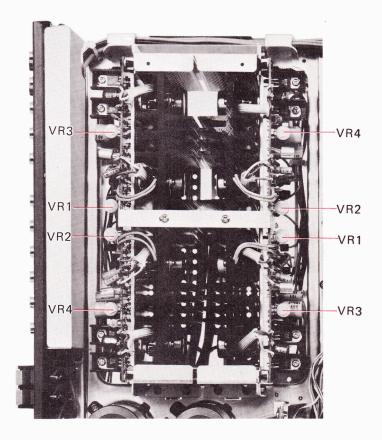
amplifier has been come into operation, a defect in the output transistors can be suspected. Check the output stage.

- 6. After approx. $10 \sim 20$ minutes of warming-up time, adjust VR3 so that the voltage across terminals 1 and 2 of the power amplifier assembly becomes 20mV.
- 7. In the same way, adjust VR4 to obtain 20mV voltage readings across the terminals 25 and 26.
- 8. Next, connect voltmeter between terminal 5 and ground. Adjust VR1 to obtain 0V reading.
- 9. In the same way, adjust VR2 to obtain zero readings between terminal 23 and ground.

Bottom View

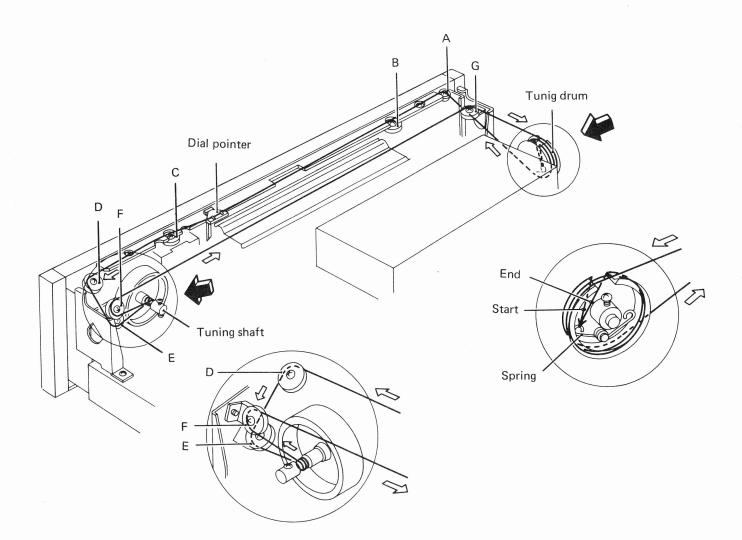
Top View





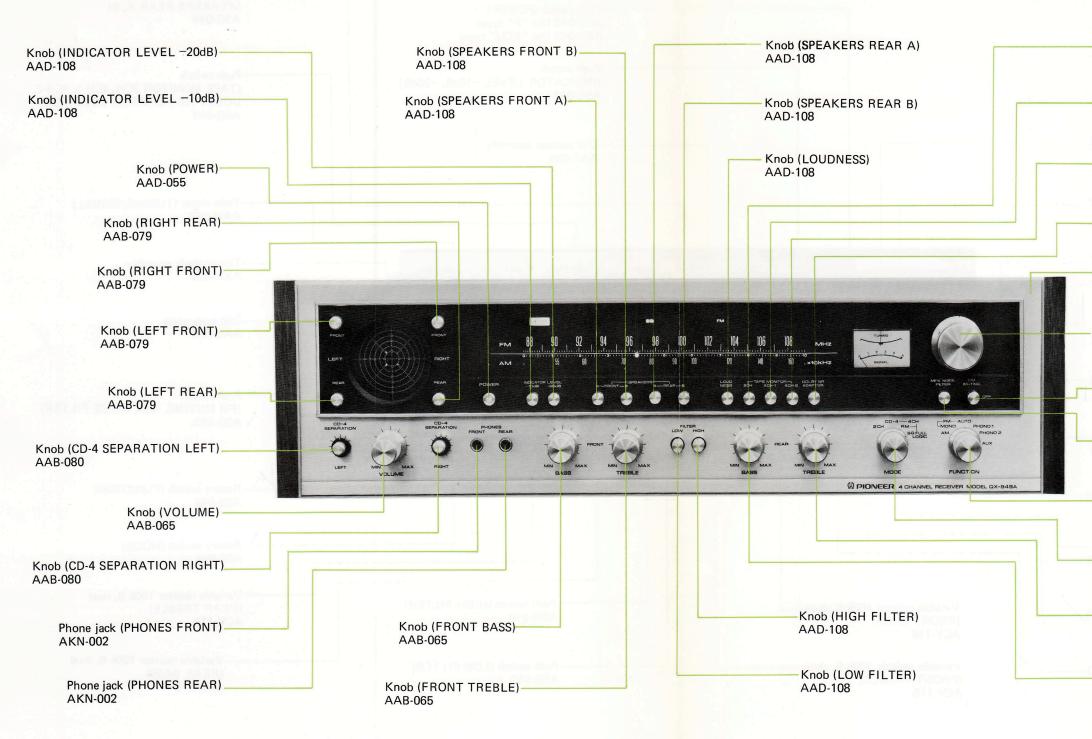
9. DIAL CORD STRINGING

- 1. Turn the tuning capacitor so that its plates protrude as much as possible.
- 2. Tie one end of the string to the spring on the Tuning drum (attached to the tuning capacitor).
- 3. Lead the string around pulleys A, B, C, D and E, then wind it 3 turns around the tuning shaft.
- 4. Lead the string around pulleys F and G, then wind it 2 turns around the Tuning drum.
- 5. Now tie the other end of the string to the spring on the Tuning drum. Turn the tuning shaft and check for proper function. Then trim the ends of the string.
- 6. Turn the tuning shaft until the plates of the variable are all the way in. Move the pointer to the left-end starting point on the dial and fasten it to the string in that position.



10. PARTS LOCATIONS

10.1 FRONT VIEW 1



QX-949A

Knob (TAPE MONITOR 2CH) AAD-108

Knob (TAPE MONITOR 4CH-1) AAD-108

Knob (TAPE MONITOR 4CH-2) AAD-108

-Knob (DOLBY NR ADAPTOR) AAD-108

Front panel assembly ANB-318

Knob (TUNING) AAA-023

Knob (FM MUTING) AAD-108

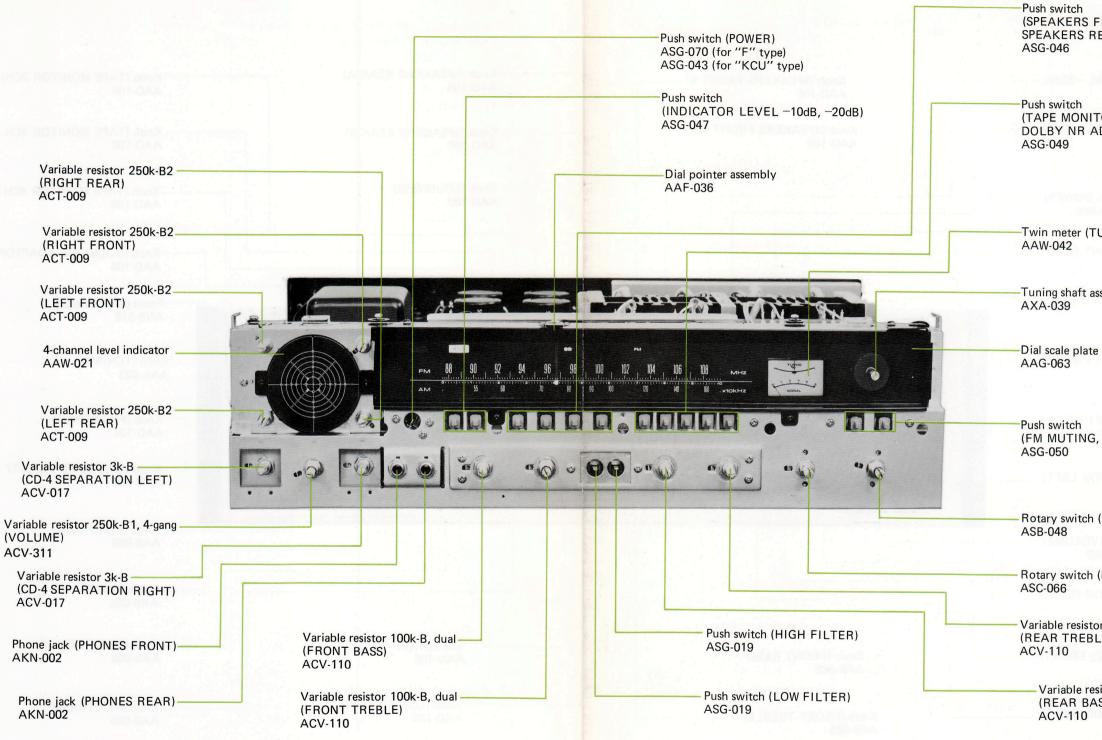
-Knob (MPX NOISE FILTER) AAD-108

- Knob (FUNCTION) AAB-065

Knob (MODE) AAB-065

Knob (REAR TREBLE) AAB-065

Knob (REAR BASS) AAB-065



(SPEAKERS FRONT A, B, SPEAKERS REAR A, B)

(TAPE MONITOR 2CH, 4CH-1, 4CH-2, DOLBY NR ADAPTOR, LOUDNESS)

Twin meter (TUNING/SIGNAL)

Tuning shaft assembly

(FM MUTING, MPX NOISE FILTER)

Rotary switch (FUNCTION)

Rotary switch (MODE)

Variable resistor 100k-B, dual (REAR TREBLE)

> Variable resistor 100k-B, dual (REAR BASS) ACV-110

10.3 TOP VIEW

Electrolytic capacitor 10,000µF 50V (C8) ACH-029

Electrolytic capacitor 10,000µF 50V (C6)— ACH-029

Electrolytic capacitor 10,000µF 50V (C7) ACH-029

Electrolytic capacitor 10,000µF 50V (C9)____ ACH-029

> Ferrite balun T22-025

Micro switch (S7) – ASF-001

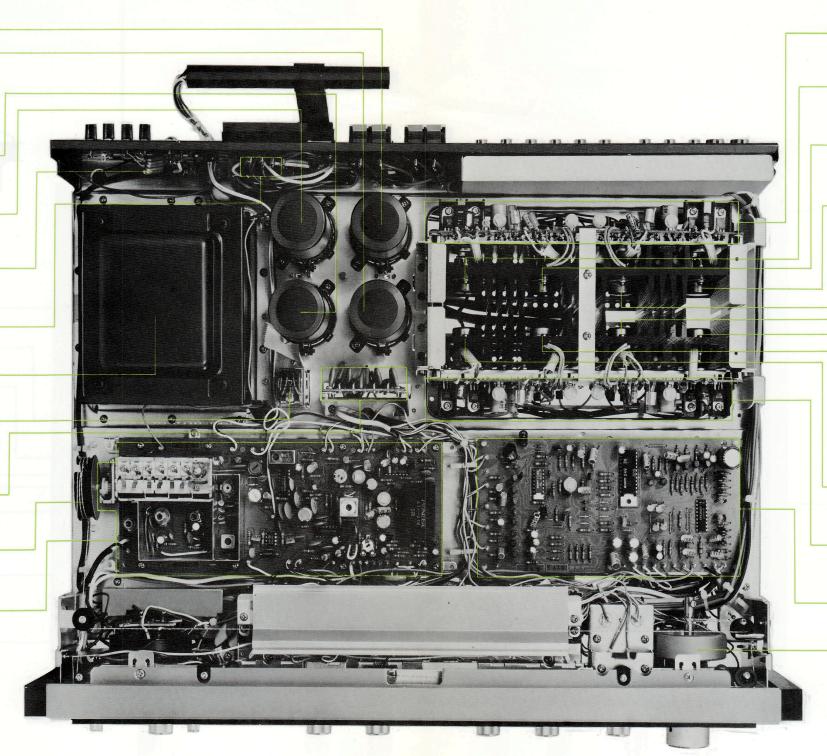
Power transformer ATT-222 (for "F" type) ATT-221 (for "KCU" type)

> Relay ASR-007

Power supply circuit B assembly AWR-039

Tuning drum assembly – AXA-015

> Tuner assembly -AWE-041



QX-949A

Power amplifier assembly (for CH1, CH4) AWH-027

–Transistor (Q16) 2SA679-R or Y (2SA747-R, O or Y)

- Transistor (Q14) 2SC1079-R or Y (2SC1116-R, O or Y)

– Transistor (Q15) 2SB530-R or O (2SA745-R, O or Y)

-Transistor (Q13) 2SD370-R or O (2SC1403-R, O or Y)

-Transistor (Q14) 2SC1079-R or Y (2SC1116-R, O or Y)

Transistor (Q16) 2SA679-R or Y (2SC1116-R, O or Y)

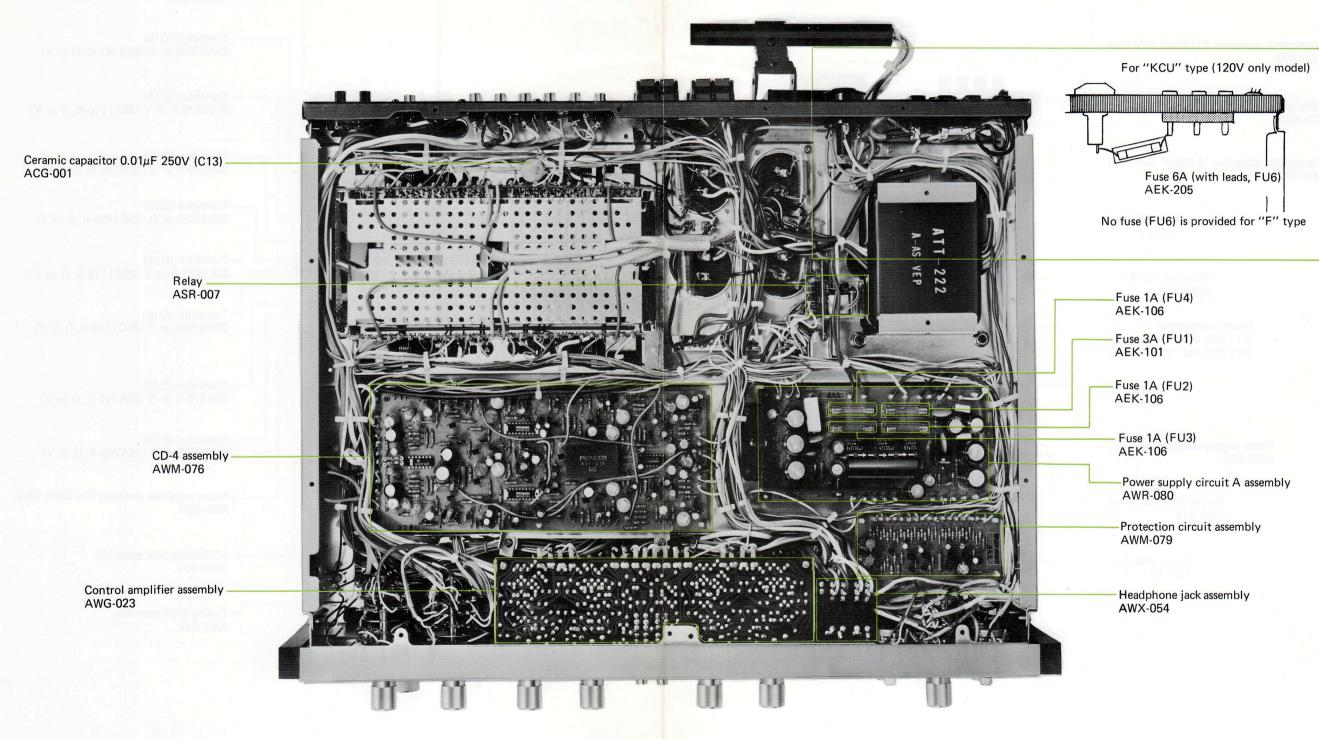
-Transistor (Q13) 2SD370-R or O (2SA747-R, O or Y)

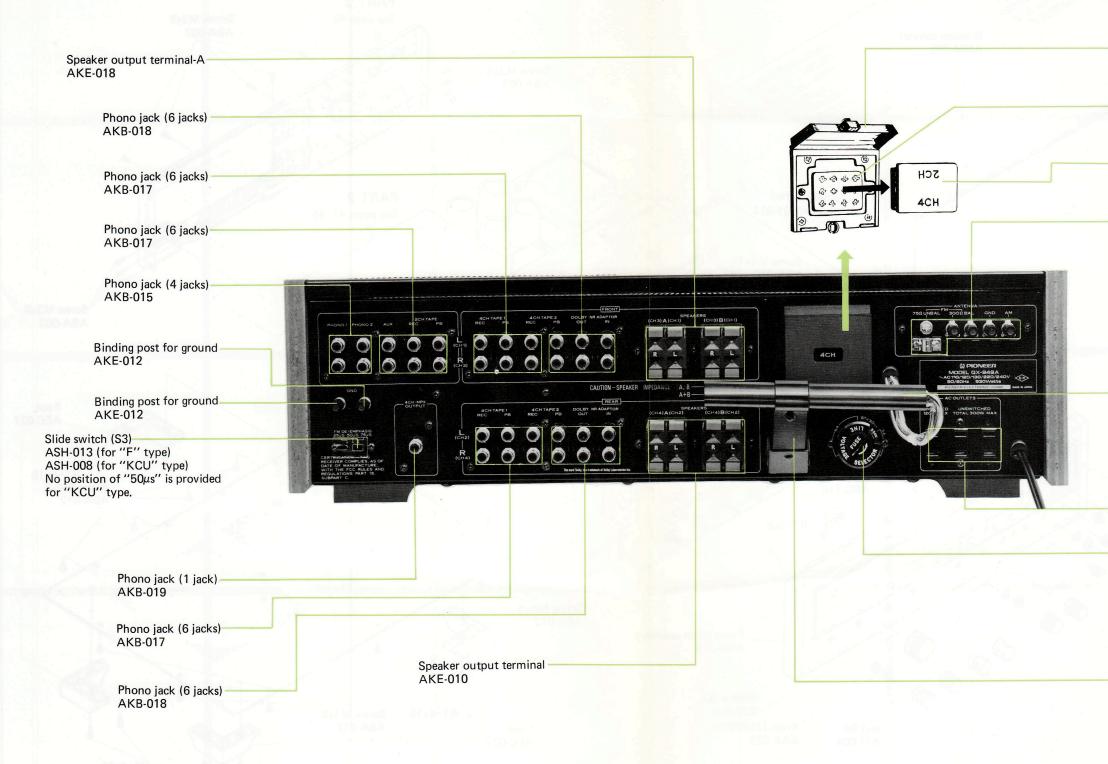
-Transistor (Q15) 2SB530-R or O (2SA745-R, O or Y)

- Power amplifier assembly (for CH2, CH3) AWH-027

-SQ/RM decoder assembly AWM-077

Tuning shaft assembly AXA-039





QX-949A

Switch cover assembly AEC-110

Multi-socket (power boosting switch) AKP-006

Multi-plug (power boosting switch) AKM-006

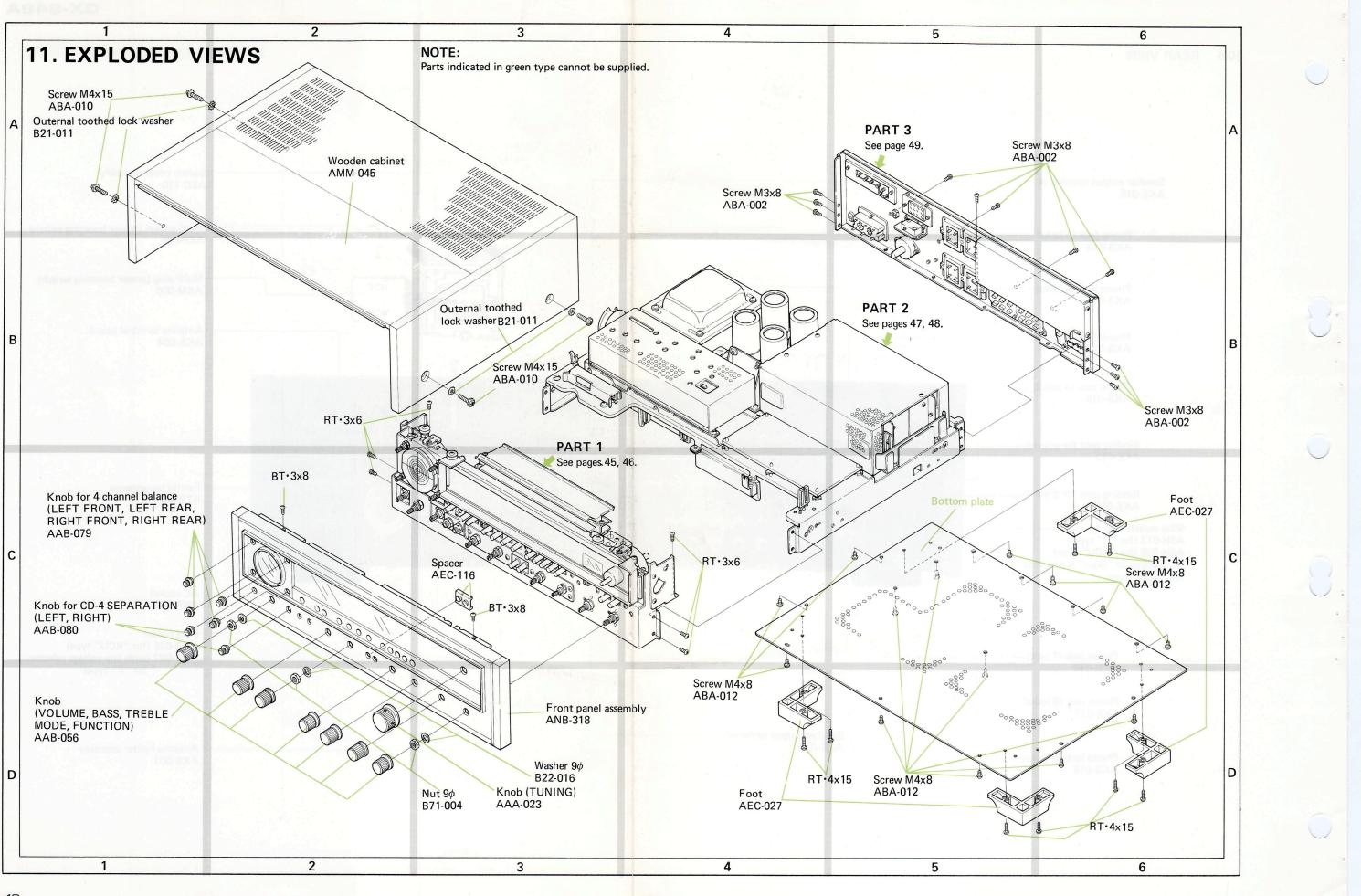
Antenna terminal board AKA-004

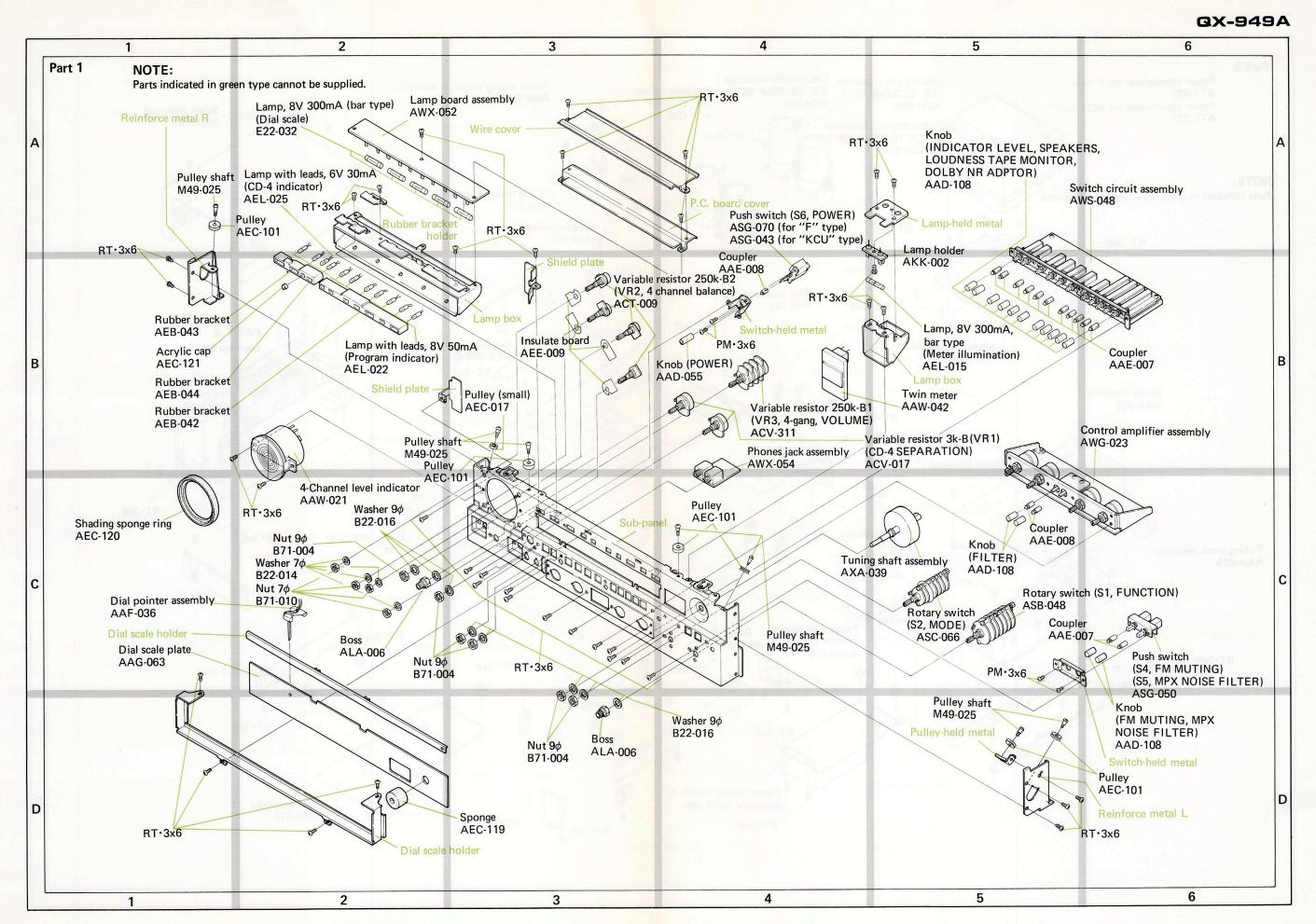
Ferrite bar-antenna ATB-042

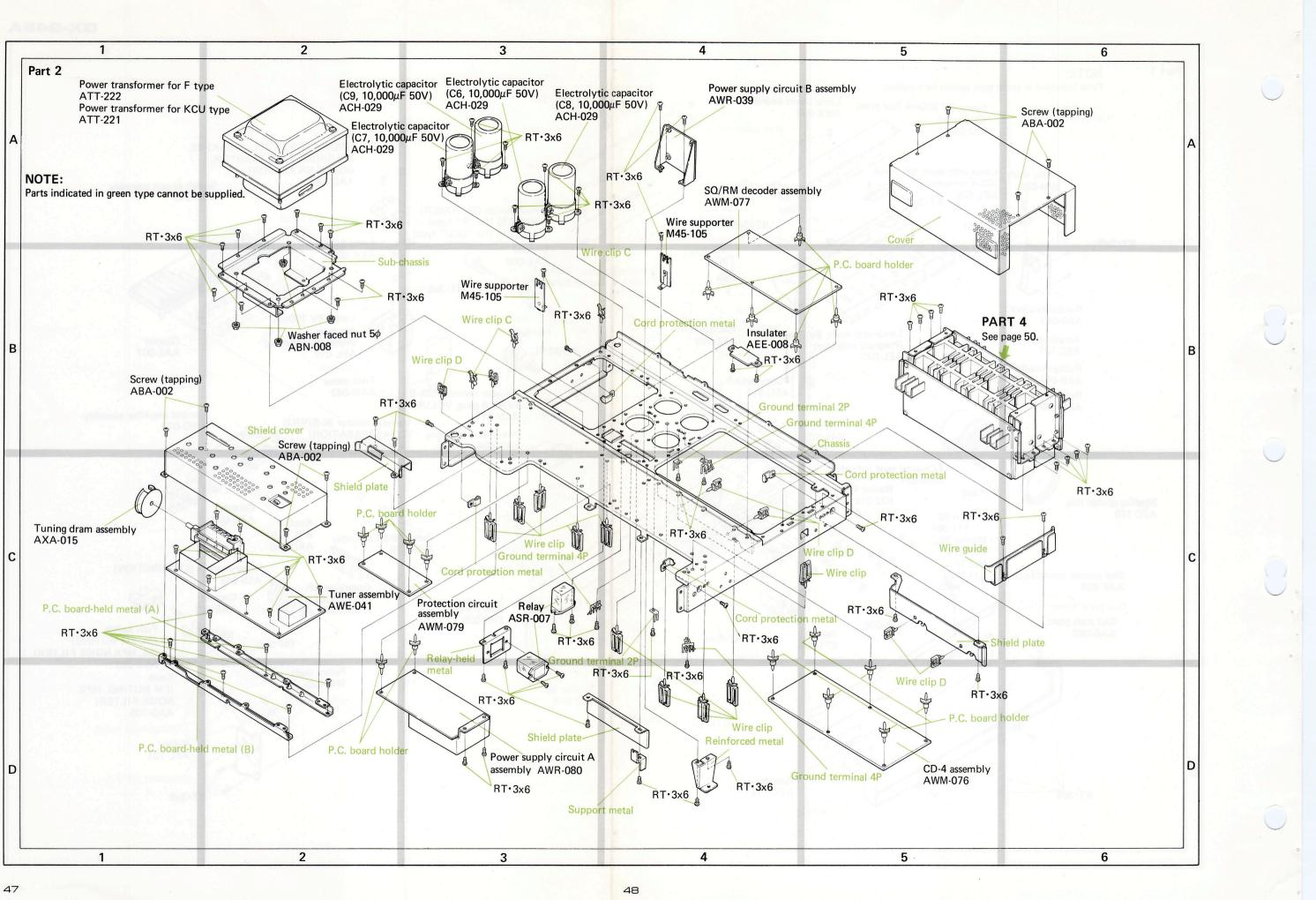
AC socket AKP-005

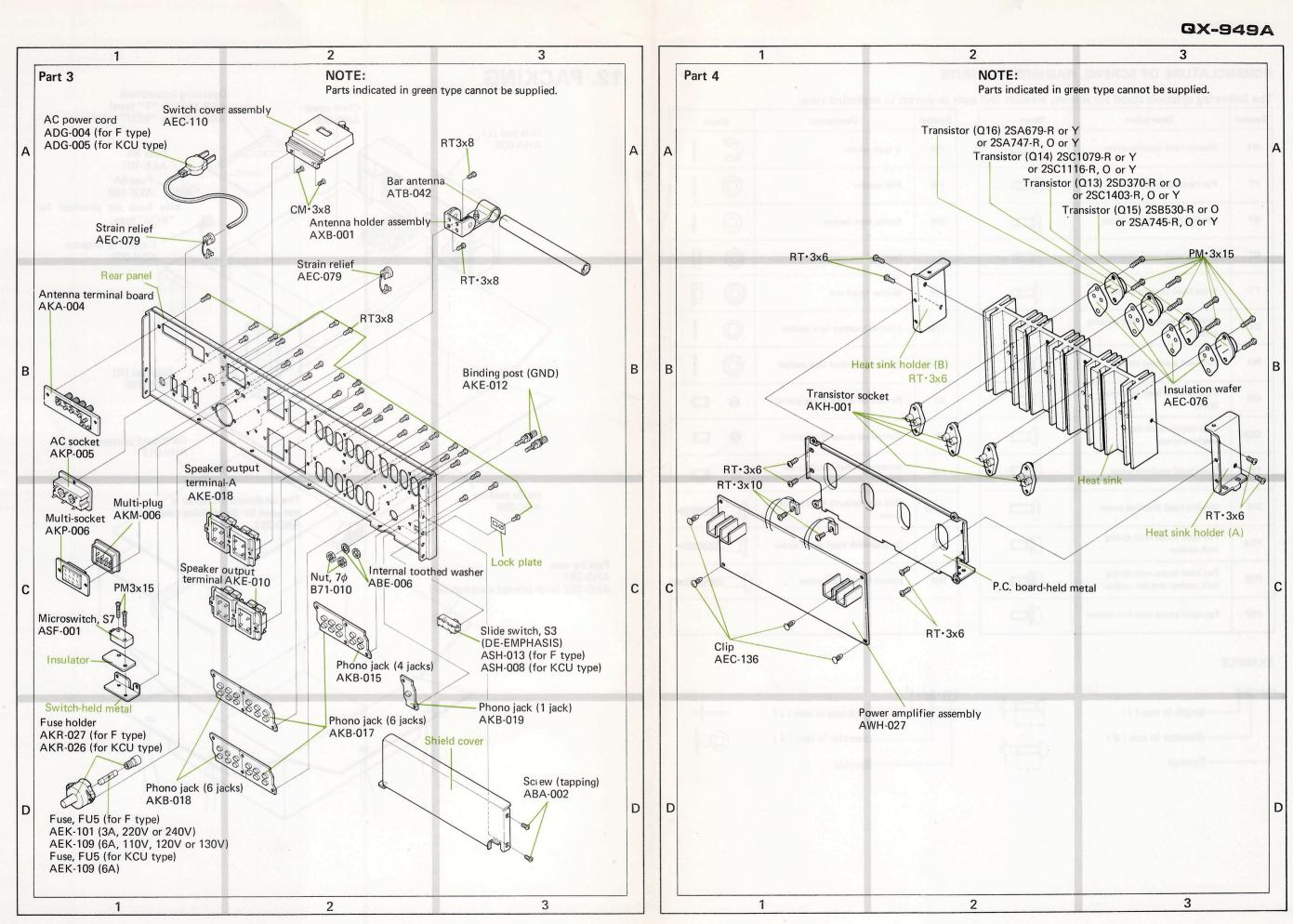
Fuse holder AKR-026 (for "KCU" type) AKR-027 (with line voltage selector, for "F" type)

Antenna holder assembly AXB-001





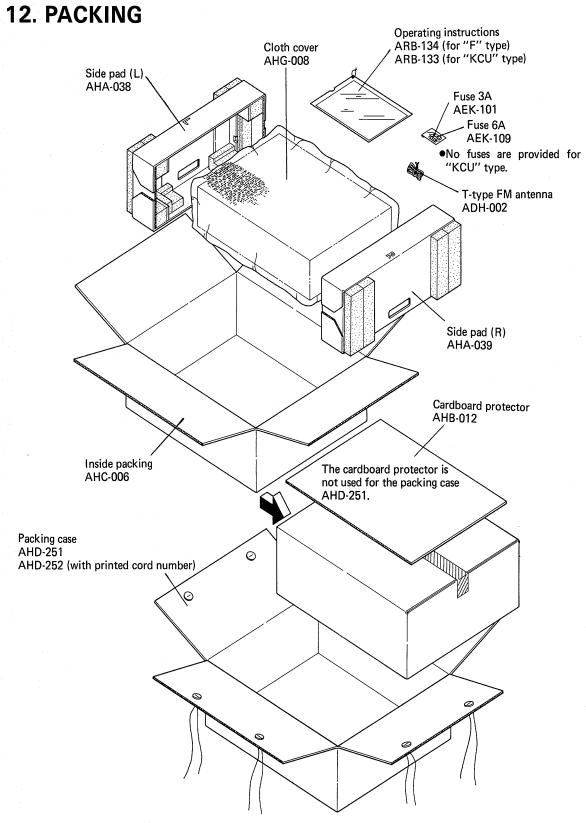




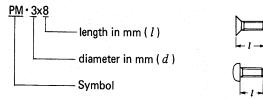
NOMENCLATURE OF SCREWS, WASHERS AND NUTS

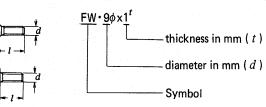
The following symbols stand for screws, washers and nuts as shown in exploded view.

Symbol	Description	Shape	Symbol	Description	Shape
RT	Brazier head tapping screw	(III)	EW	E type washer	C
РТ	Pan head tapping screw		FW	Flat washer	
вт	Binding head tapping screw		sw	Spring lock washer	C I
СТ	Countersunk head tapping screw		N	Nut	Ô
тт	Truss head tapping screw		WN	Washer faced nut	
ост	Oval countersunk head tapping screw		ITW	Internal toothed lock washer	0
РМ	Pan head machine screw		ОТЖ	Outernal toothed lock washer	
СМ	Countersunk head machine screw		SC	Slotted set screw (Cone point)	0
осм	Oval countersunk head machine screw		SF	Slotted set screw (Flat point)	8 2
тм	Truss head machine screw		HS	Hexagon socket headless set screw	0 D
BM	Binding head machine screw		OCW	Oval countersunk head wood screw	
PSA	Pan head screw with spring lock washer		CW	Countersunk head wood screw	
PSB	Pan head screw with spring lock washer and flat washer		RW	Round head wood screw	
PSF	Pan head screw with flat washer				



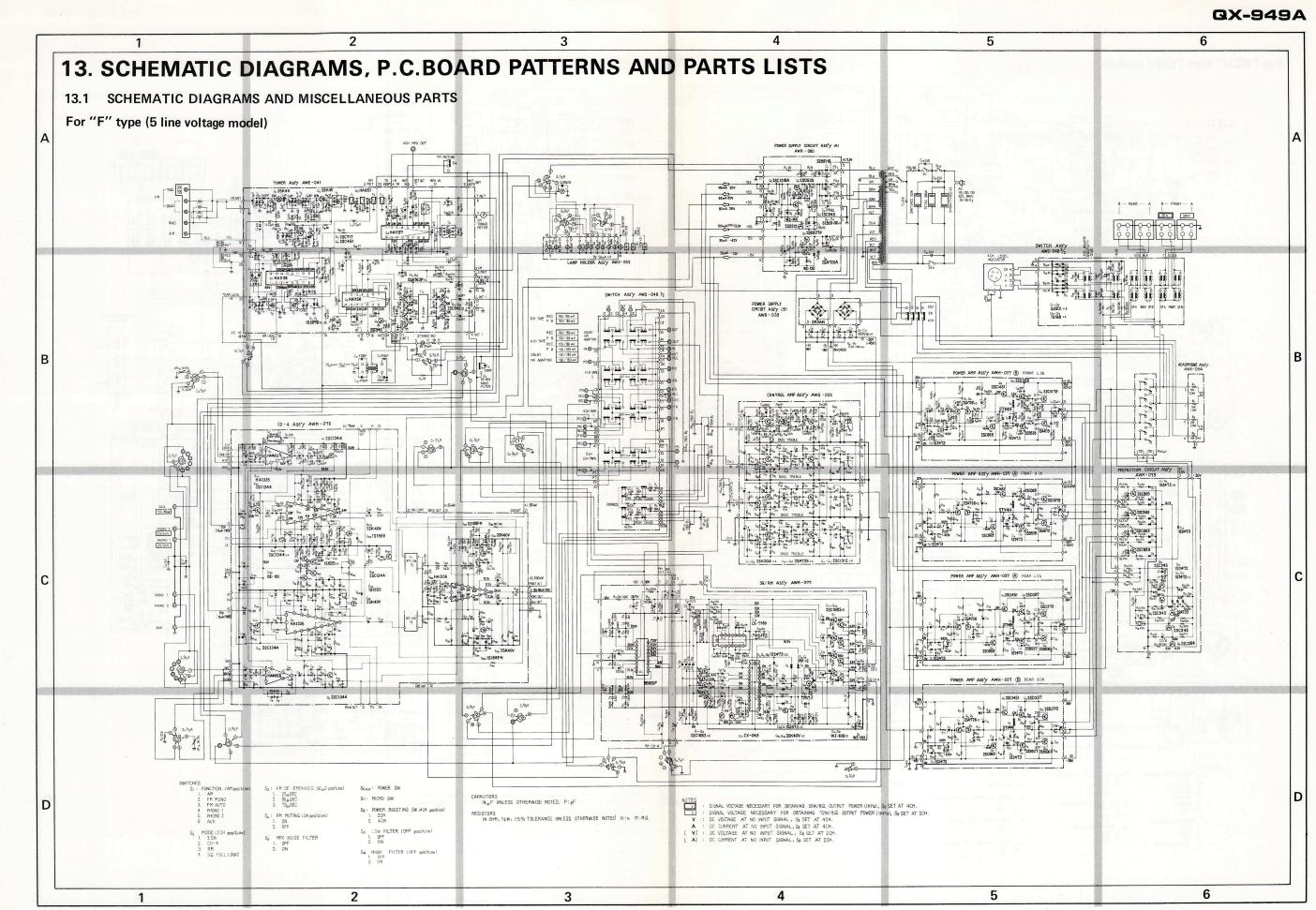
EXAMPLE

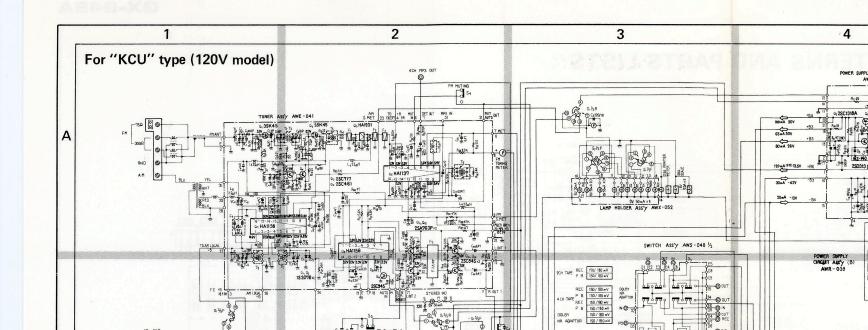


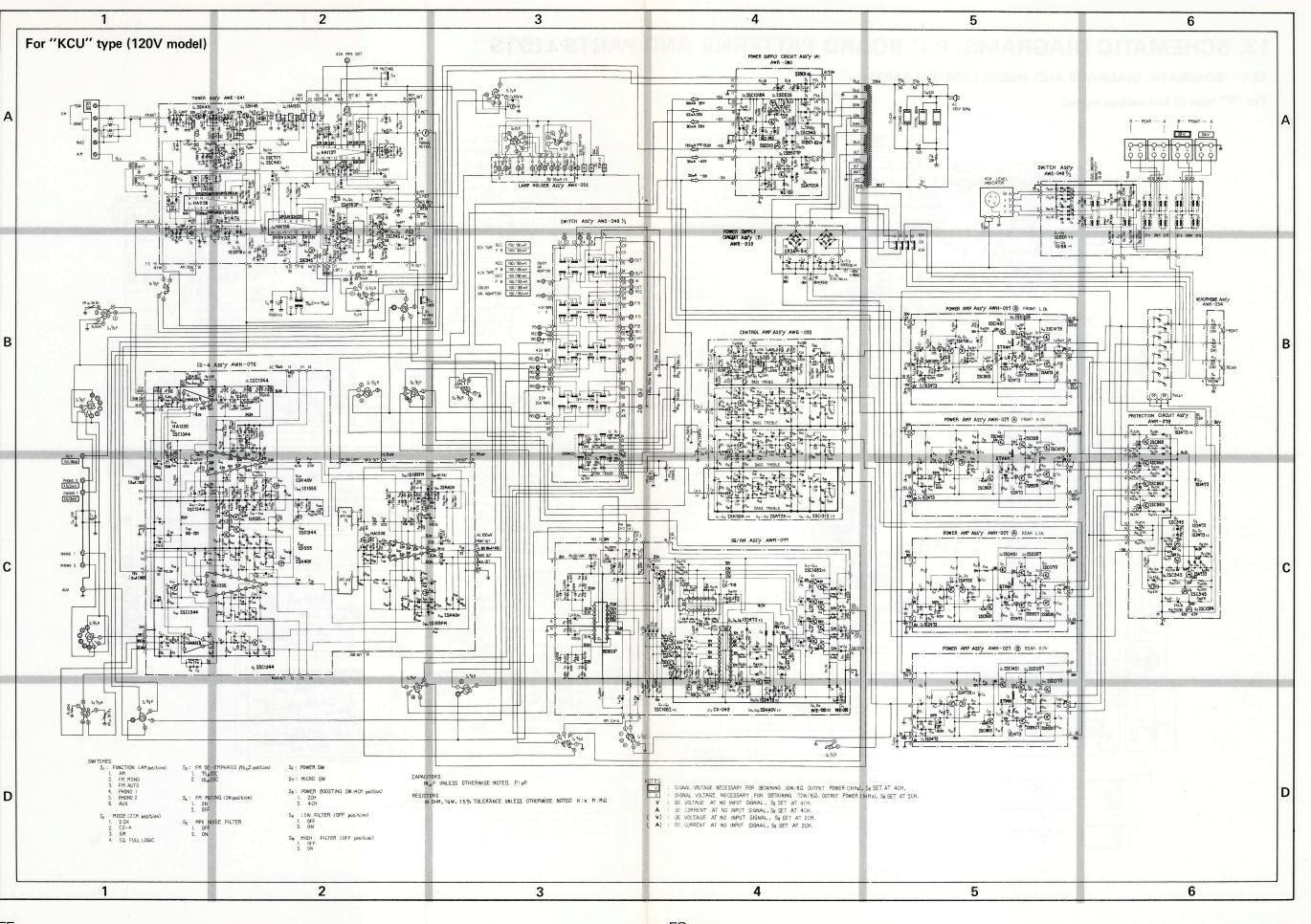




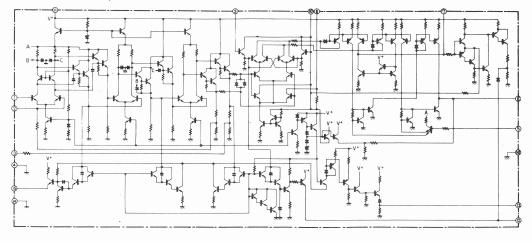
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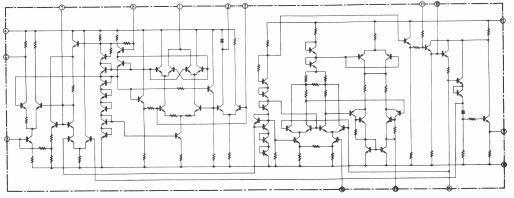


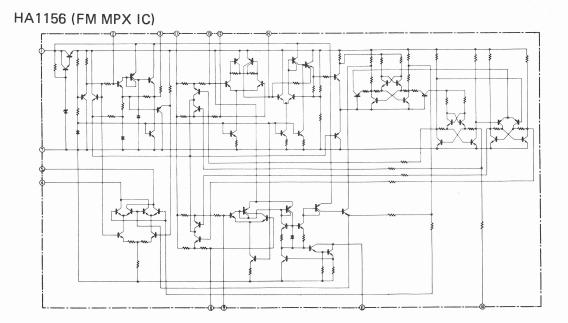


HA1137 (FM IF IC)

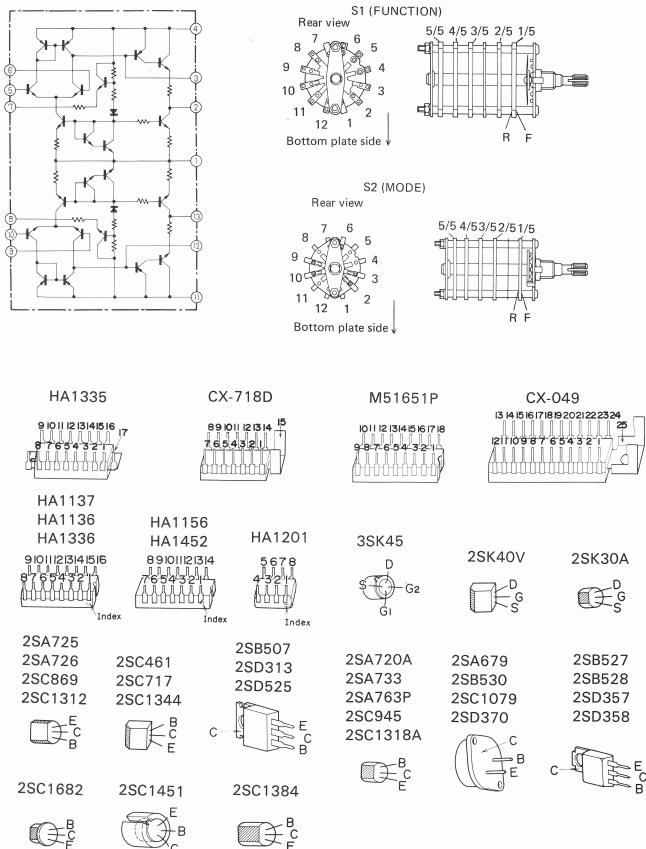


HA1138 (AM IC)





HA1452(EQ AMP IC)



Miscellaneous Parts for "F" type

NOTE:

• Capacitors: in μF unless otherwise noted p:pF

CAPACITORS

Symbol	Des	cription		Part No.
C1	Ceramic	0.01	50V	CKDYF 103Z 50
C2	Mylar	0.0091	50V	CQMA 912J 50
C3	Mylar	0.0091	50V	CQMA 912J 50
C4	Ceramic	0.0056	50V	CKDYB 562K 50
C5	Electrolytic	220	16V	CEA 221P 16
C6	Electrolytic	10,000	50V	ACH-029
C7	Electrolytic	10,000	50V	ACH-029
C8	Electrolytic	10,000	50V	ACH-029
C9	Electrolytic	10,000	50V	ACH-029
C10	Ceramic	0.01	250V	ACG-001
C11	Ceramic	0.01	250V	ACG-001
C12	Ceramic	0.01	250V	ACG-001
C13	Ceramic	0.01	250V	ACG-001
C14	Mylar	0.0047	50V	CQMA 472J 50
C15	Mylar	0.0047	50V	CQMA 472J 50
C16	Ceramic	0.01	50V	CKDYF 103Z 50
C17	Ceramic	0.01	250V	ACG-001

RESI	STO	RS
------	-----	----

and the

Symbol	Description		Part No.	
R1	Carbon film	100k		RD%PS 104J
R2	Carbon film	100k		RD%PS 104J
R3	Carbon film	1M		RD%PS 105J
R4	Metal oxide	3.3k	ЗW	RS3P 332K
R5	Metal oxide	3.3k	3W	RS3P 332K
R6	Metal oxide	3.3k	3W	RS3P 332K
R7	Metal oxide	3.3k	3W	RS3P 332K
VR1a	Variable resist		· · · ·	ACV-017
	(CD-4 SEPAR		EFT)	
VR1b	Variable resist (CD-4 SEPAR		GHT)	ACV-017
VR2a	Variable resistor 250k-B2 (FRONT L level)			ACT-009
VR2b	(FRORT Liever) Variable resistor 250k-B2 (REAR R level)		ACT-009	
VR2c	Variable resistor 250k-B2 (FRONT L level)		ACT-009	
VR2d	Variable resist (REAR R leve		2	ACT-009
VR3	Variable resist 4-gang (VOLU		1,	ACV-311
· · · · · · · · · · · · · · · · · · ·				

		/er amplifier)
Symbol	Description	Part No.
Q13		2SD370-R
		(2SC1403-R
Q14		2SC1079-R
		(2SC1116-R
15		2SB530-R
		(2SA745-R
216		2SA679-R
		(2SA747-R

Symbol	Description	Part No.
	Lamp 8V, 300mA, bar type (Dial illumination)	E22-032
	Lamp 8V, 300mA, bar type (Meter illumination)	AEL-015
	Lamp 6V, 30mA, with leads (CD-4 indicator)	AEL-025
	Lamp 8V 50mA, with leads (Program indicator)	AEL-022

Sumbal	Description	Part No.
Symbol	Description	Tarcivo.
FU1	Fuse 3A (lamp circuit)	AEK-101
FU2	Fuse 1A (secondary)	AEK-106
FU3	Fuse 1A (secondary)	AEK-106
FU4	Fuse 1A (secondary)	AEK-106
FU5	Fuse 3A (220V, 240V, primary)	AEK-101
	or 6A (110V, 120V, 130V, primary)	AEK-109

SWITCHES

Symbol	Description	Part No.
S1	Rotary switch (FUNCTION)	ASB-048
S2	Rotary switch (MODE)	ASC-066
S3	Slide switch (DE-EMPHASIS)	ASH-013
S4, S5	Push switch (FM MUTING,	1. 1. 1. 1. 1. 1. 1. 1. 1. 1. 1. 1. 1. 1
	MPX NOISE FILTER)	ASG-050
S6	Push switch (POWER)	ASG-070
S7	Micro switch (Switch cover)	ASF-001

Miscellaneous Parts for "KCU" type

CAPACITORS Part No. Symbol Description CKDYF103Z 50 C1 Ceramic 0.01 50V 0.0091 50V CQMA 912J 50 Mylar C2 C3 Mylar 0.0091 50V CQMA 912J 50 CKDYB 562K 50 C4 Ceramic 0.0056 50V CEA 221P 16 C5 Electrolytic 220 16V ACH-029 C6 Electrolytic 10,000 50V Electrolytic 10,000 50V ACH-029 C7 C8 Electrolytic 10,000 50V ACH-029 C9 10,000 50V ACH-029 Electrolytic ACG-003 150V C10 Ceramic 0.01 C11 Ceramic 0.01 150V ACG-003 150V ACG-003 C12 Ceramic 0.01 250V ACG-001 C13 Ceramic 0.01 50V CKDYF 103Z 50 C14 Ceramic 0.01

RESISTORS

Symbol	Description		Part No.	
R1	Carbon film	100k		RD1/4PS 104J
R2	Carbon film	100k		RD%PS 104J
R3	Carbon film	1M		RD¼PS 105J
R4	Metal oxide	3.3k	ЗW	RS3P 332K
R5	Metal oxide	3.3k	3W	RS3P 332K
R6	Metal oxide	3.3k	3W	RS3P 332K
. R7	Metal oxide	3.3k	ЗW	RS3P 332K
R8	Carbon film	2.2M	1⁄2W	RD½PS 225J
VR1a	Variable resistor 3k-B (CD-4 SEPARATION LEFT)			ACV-017
VR1b	Variable resistor 3k-B (CD-4 SEPARATION RIGHT)		ACV-017	
VR2a	Variable resistor 250k-B2 (FRONT L level)			ACT-009
VR2b	Variable resistor 250k-B2 (REAR R level)		ACT-009	
VR2c	Variable resistor 250k-B2 (FRONT L level)		ACT-009	
VR2d	Variable resistor 250k-B2 (REAR R level)			ACT-009
VR3	Variable resistor 250k-B1 4-gang (VOLUME)			ACV-311

Q14 Q15 Q16 LAMPS Symbol Description Lamp 8V, 300mA, bar typ (Dial illumination) Lamp 8V, 300mA, bar typ (Meter illumination) Lamp 6V, 30mA, with lead (CD-4 indicator) Lamp 8V, 50mA, with leave (Program indicator) FUSES

Symbol	Description	Part No.
FU1	Fuse 3A (lamp circuit)	AEK-101
FU2	Fuse 1A (secondary)	AEK-106
FU3	Fuse 1A (secondary)	AEK-106
FU4	Fuse 1A (secondary)	AEK-106
FU5	Fuse 6A (primary)	AEK-109
FU6	Fuse 6A (primary, with leads)	AEK-205

SWITCHES

Symbol	Description	Part No
S1	Rotary switch (FUNCTION)	ASB-048
S2	Rotary switch (MODE)	ASC-066
S3	Slide switch (DE-EMPHASIS)	ASH-008
S4,S5	Push switch (FM MUTING,	
	MPX NOISE FILTER)	ASG-050
S6	Push switch (POWER)	ASG-043
S7	Micro switch (Switch cover)	ASF-001

POWER TRANSISTORS (for Power amplifier)

Description

Symbol

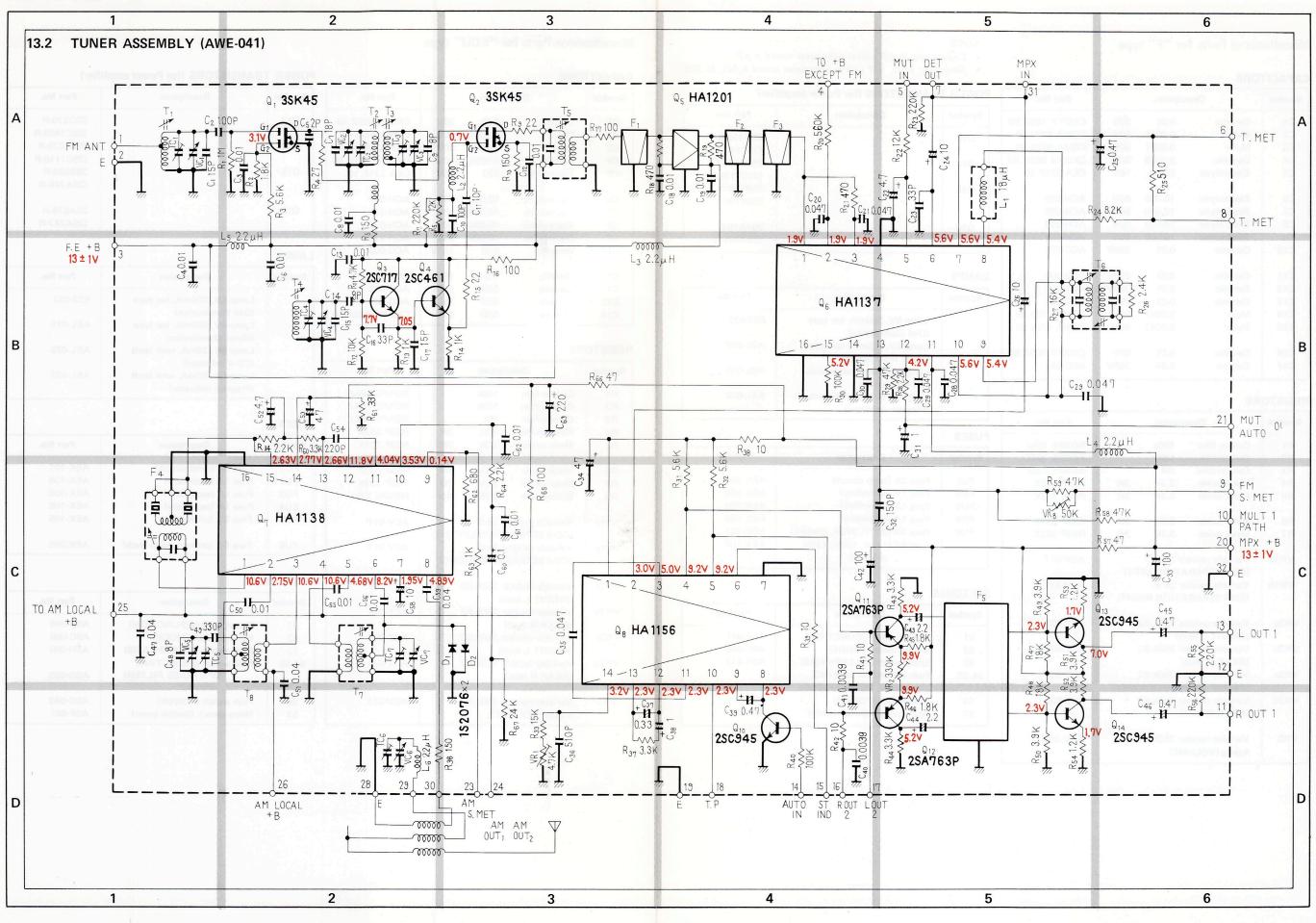
Q13

QX-949A

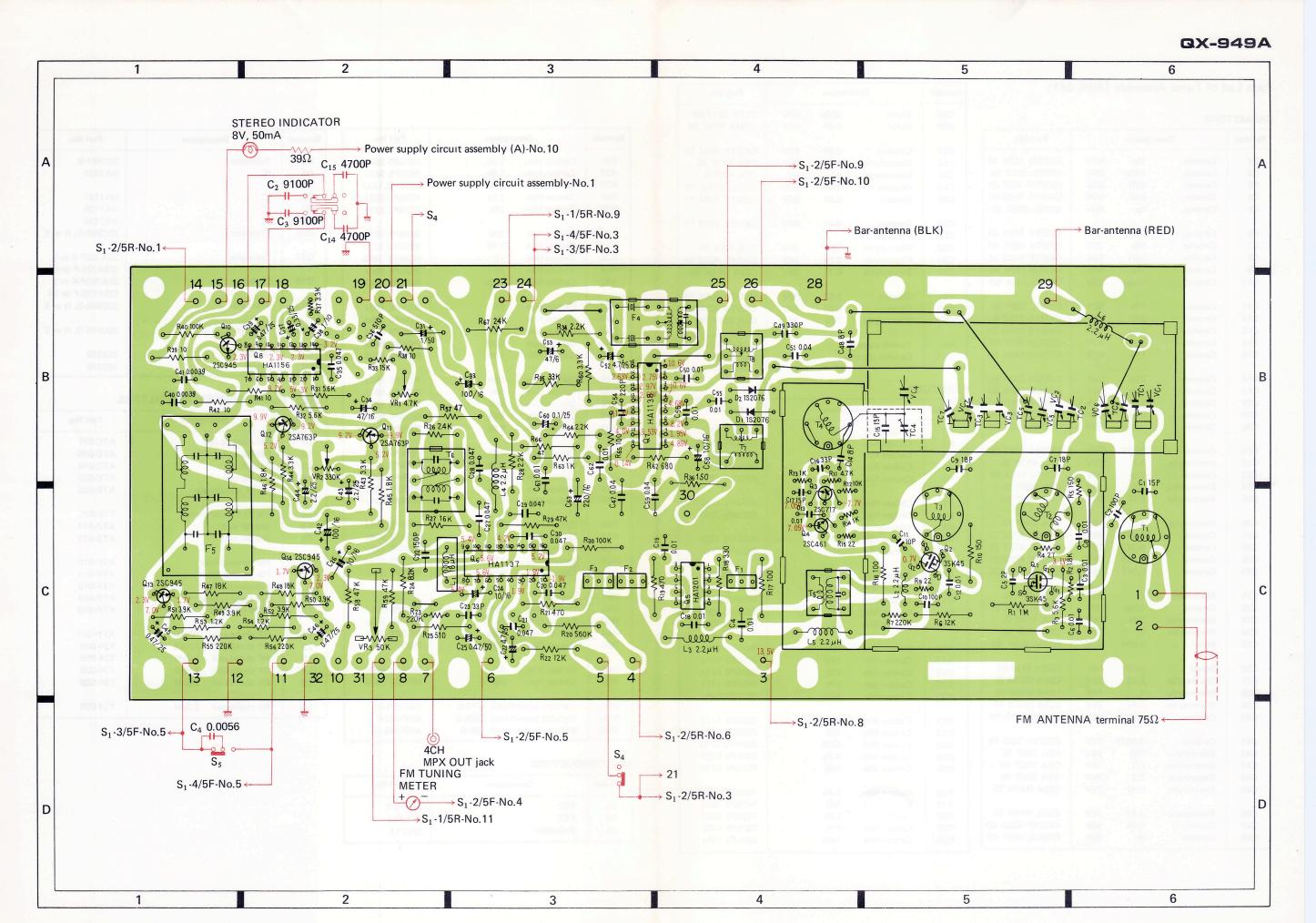
Part No.	
2SD370-R	
(2SC1403-R	
2SC1079-R	
(2SC1116-R	
2SB530-R	
(2SA745-R	
2SA679-R	
(2SA747-R	

	Part No.
pe	E22-032
pe	AEL-015
ads	AEL-025
ads	AEL-022

AGNG-XO







Parts List of Tuner Assembly (AWE-041)

APACIT	ORS				C50	Mylar	0.01	50
Symbol	Descr	ription		Part No.				
		4.5	501/	000011 45014 50	C51	Ceramic	0.04	50
C1	Ceramic	15p	50V	CCDSH 150K 50	C52	Electrolytic	4.7	25
C2	Ceramic	100p	50V	CCDSL 101K 50	C53	Electrolytic	47	6V
C3	Ceramic	0.01	50V	CKDYF 103Z 50	C54	Ceramic	220p	50
C4	Ceramic	0.01	50V	CKDYF 103Z 50	C55	Ceramic	0.01	50
C5	Ceramic	2p	50V	CCDSL 020C 50				
C6	Ceramic	0.01	50V	CKDYF 103Z 50	C56 C57	Ceramic Vacancy	0.01	50
C7	Ceramic	18p	50V	CCDSH 180K 50	C58	Electrolytic	10	16
C8	Ceramic	0.01	50V	CKDYF 103Z 50	C50	Electrolytic	0.04	50
C9	Ceramic	18p	50V	CCDSH 180K 50	the second se	 A second sec second second sec		
C10	Ceramic	100 100p	50V	CCDSL 101K 50	C60	Electrolytic	0.1	25
					C61	Ceramic	0.01	50
C11	Ceramic	10p	50V	CCDSL 100F 50	C62	Ceramic	0.01	50
C12	Ceramic	0.01	50V	CKDYF 103Z 50	C63	Electrolytic	220	16
C13	Ceramic	0.01	50V	CKDYB 103K 50				
C14	Ceramic	8p	50V	CCDLH 080F 50	VC	Tuning capacit	tor	
C15	Ceramic	15p	50V	CCDLH 150K 50	TC4	Ceramic trimm		
C16	Ceramic	33p	50V	CCDCH 330K 50	<u>له الم</u>			
C17	Ceramic	15p	50V	CCDCH 150K 50	RESISTO	RS		
C17	Ceramic	0.01	50V	CKDYF 103Z 50				
C18	Ceramic	0.01	50V	CKDYF 103Z 50	Symbol	Desc	ription	
C19 C20	Ceramic	0.01	25V	CKDBC 473Z 25				
620	Gerannic	0.047	23,0		R1 R2	Carbon film Carbon film	1M 1.8k	
C21	Ceramic	0.047	25V	CKDBC 473Z 25	R2 R3	Carbon film	5.6k	
C22	Electrolytic	4.7	25V	CEA 4R7P 25				
C23	Ceramic	33p	50V	CCDSL 330K 50	R4	Carbon film	27	
C23	Electrolytic	10	16V	CEA 100P 16	R5	Carbon film	150	
C24	Electrolytic	0.47	50V	CEA R47P 50	R6	Carbon film	12k	
	••••				R7	Carbon film	220k	
C26	Electrolytic	10	16V	CEA 100P 16	R8	Vacancy	2200	
C27	Ceramic	0.047	25V	CKDBC 473Z 25	1 1		22	
C28	Ceramic	0.047	25V	CKDBC 473Z 25	R9	Carbon film	22	
C28	Ceramic	0.047	25V	CKDBC 473Z 25	R10	Carbon film	150	
C29	Ceramic	0.047	25V 25V	CKDBC 473Z 25				
030	Gerannic	0.047	201	01000 7102 20	R11	Carbon film	4.7k	
021	Electrolytic	1	50V	CEA 010P 50	R12	Carbon film	10k	
C31	Ceramic		50V 50V	CCDSL 151K 50	R13	Carbon film	1k	
C32		150p			R14	Carbon film	1k	
C33	Electrolytic	100	16V	CEA 101P 16	R15	Carbon film	22	
C34	Electrolytic	47	16V	CEA 470P 16				
C35	Mylar	0.047	50V	COMA 473K 50	R16	Carbon film	100	
					R17	Carbon film	100	
C36	Styrol	510P	50V	COSH 511J 50	R18	Carbon film	470	
C37	Electrolytic	0.33	25V	CSSA R33M 25	R19	Carbon film	470	
C38	Electrolytic	1	10V	CSSA 010M 10	R20	Carbon film	560k	
C39	Electrolytic	0.47	25V	CSSA R47M 25				
C40	Ceramic	0.0039	50V	CKDYA 392J 50	R21	Carbon film	470	
					R22	Carbon film	12k	
C41	Ceramic	0.0039	50V	CKDYA 392J 50	R23	Carbon film	220k	
C42	Electrolytic	100	16V	CEA 101P 16	R24	Carbon film	8.2k	
C43	Electrolytic	2.2	25V	CEA 2R2P 25	R25	Carbon film	510	
C44	Electrolytic	2.2	25V	CEA 2R2P 25		Carbon min		
C45	Electrolytic	0.47	25V	CSSA R47M 25	R26	Carbon film	2.4k	
					R20	Carbon film	2.4k 16k	
C46	Electrolytic	0.47	25V	CSSA R47M 25	R27 R28	Carbon film	2.2k	
C40 C47	Ceramic	0.04	50V	CKDYF 403Z 50	R20	Carbon film	2.2k 47k	
	Ceramic		50V	CCDXL 080F 50	R29 R30			
C48		8p				Carbon film	100k	

Symbol

Description

Part No.

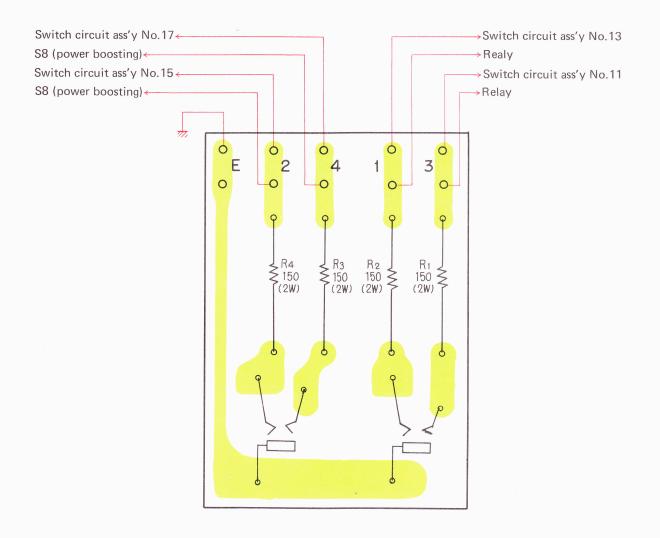
RD%VS 103J RD¼VS 102J RD%VS 102J RD¼VS 220J RD%PS 101J RD%PS 101J RD%PS 471J RD¼PS 471J RD%PS 564J RD%PS 471J RD%PS 123J RD¼VS 224J RD%PS 822J RD%PS 511J RD¼VS 242J RD%PS 163J RD%PS 222J RD%PS 473J RD¼PS 104J

CQSA 331J 50						
CQMA 103K 50		Symbol	Des	cription	Part No.	Sym
CKDYF 403Z 50						-
CEA 4R7P 25		R31	Carbon film	5.6k	RD%PS 562J	04
CEA 470P 6		R32	Carbon film	5.6k	RD%PS 562J	Q5
CCDSL 221K 50		R33	Carbon film	15k	RD%VS 153J	
CKDYF 103Z 50		R34	Carbon film	2.2k	RD%PS 222J	06
		R35	Carbon film	33k	RD%PS 333J	07
CKDYF 103Z 50						08
•••••	1 - R	R36	Carbon film	150	RD%PS 151J	Q1
CEA 100P 16		R37	Carbon film	3.3k	RD¼VS 332J	
CKDYF 403Z 50		R38	Carbon film	10	RD¼VS 100J	01
CSSA 0R1M 25		R39	Carbon film	10	RD%PS 100J	
		R40	Carbon film	100k	RD%PS 104J	Q1
CKDYB 103K 50						
CKDYB 103K 50		R41	Carbon film	10	RD%PS 100J	01
CEA 221P 16		R42	Carbon film	10	RD%PS 100J	
		R43	Carbon film	-3.3k	RD%PS 332J	Q1
ACK-006-A		R44	Carbon film	3.3k	RD%PS 332J	
C43-007-A		R45	Carbon film	1.8k	RD%PS 182J	D1
L.,	1					D2
		R46	Carbon film	1.8k	RD%PS 182J	
		R47	Carbon film	18k	RD%PS 183J	COIL
Part No.		R48	Carbon film	18k	RD%PS 183J	
		R49	Carbon film	3.9k	RD%PS 392J	Sym
RD%PS 105J		R50	Carbon film	3.9k	RD%PS 392J	
RD¼VS 182J			-			T1
RD¼PS 562J		R51	Carbon film	3.9k	RD%PS 392J	T2
RD¼VS 270J		R52	Carbon film	3.9k	RD%PS 392J	Т3
RD¼VS 151J		R53	Carbon film	1.2k	RD%PS 122J	T4
		R54	Carbon film	1.2k	RD%PS 122J	T5
RD%PS 123J		R55	Carbon film	220k	RD%PS 224J	
RD¼VS 224J						Т6
		R56	Carbon film	220k	RD%PS 224J	T7
RD¼VS 220J		R57	Carbon film	47	RD%PS 470J	T8
RD%PS 151J		R58	Carbon film	47k	RD%PS 473J	
		R59	Carbon film	47k	RD%PS 473J	F1
RD¼VS 472J		R60	Carbon film	3.3k	RD%PS 332J	F2
RD¼VS 103J		· · · ·				F3
RD¼VS 102J		R61	Vacancy			F4
RD¼VS 102J		R62	Carbon film	680	RD%PS 681J	F5
RD¼VS 220J		R63	Carbon film	1k	RD%PS 102J	
		R64	Carbon film	2.2k	RD%PS 222J	L1
RD1/4PS 101J		R65	Carbon film	100	RD%PS 101J	L2
RD%PS 101J						L3
RD%PS 471J		R66	Carbon film	47	RD%PS 470J	L4
RD%PS 471J		R67	Carbon film	24k	RD%PS 243J	L5
RD%PS 564J						
	1. J	VR1		-fixed) 4.7k-B	C92-051-0	L6
RD%PS 471J		VR2		-fixed) 330k-B	ACP-042-0	
RD%PS 123J		VR3	Variable (semi	-fixed) 50k-B	ACP-043-0	
RD¼VS 224J		······				-
RD%PS 822J		CENILCO	IDUCTORS			
RD%PS 511J		SEIVITUU	NDUCTORS			_

			-	
Symbol	Description	Part No.]	
Q4	Transistor	2SC461-B		
Q5	IC	HA1201		
Q6	IC	HA1137		
Q7	IC	HA1138		
Q8 Q10	IC Transistor	HA1156 2SC945-Q, R or S]	
Q11	Transistor	2SA763P-6 or 5 (2SA725-F or G)		
Q12	Transistor	2SA763P-6 or 5		
Q13	Transistor	(2SA725-F or G) 2SC945-Q, R or S	1	
Q14	Transistor	2SC945-Q, R or S	\cap	
D1	Diode	1S2076		
D2	Diode	1S2076	J North	
		c	•	
	RANSFORMERS, AND FILTER	r	1	
Symbol	Description	Part No.	-	
T1	FM antenna coil	ATC-021		
T2 T3	FM RF coil FM RF coil	ATC-015 ATC-016		
13 T4	FM RF coll FM osc coll	ATC-022		
т5	FM IF transformer	ATE-008	time	
Т6	FM DET transformer	т73-035		
Т7	AM RF coil	ATB-014		
Т8	AM osc coil	ATB-013		
F1	FM ceramic filter	ATF-013		
F2	FM ceramic filter	ATF-013		
F3 F4	FM ceramic filter AM ceramic filter	ATF-013 ATF-009		
F4 F5	LOW Pass filter	ATF-019		
L1	RF choke coil 18µH	ATH-007	1 S.S.	
L2	RF choke coil 2.2µH	T24-028		
L3	RF choke coil 2.2µH	T24-028		
L4 L5	RF choke coil 2.2μH RF choke coil 2.2μH	T24-028 T24-028		
1997 - 1997 - 1997 - 1997 - 1997 - 1997 - 1997 - 1997 - 1997 - 1997 - 1997 - 1997 - 1997 - 1997 - 1997 - 1997 -				
L6	RF choke coil 2.2µH	T24-028	J	
			\frown	

			\square	
<u> </u>		B	7	
nbol	Description	Part No.		
4 5	Transistor IC	2SC461-B HA1201		
6	IC	HA1137		
7	IC	HA1138		
8 10	IC Transistor	HA1156 2SC945-Q, R or S		
11	Transistor	2SA763P-6 or 5		
	_ .	(2SA725-F or G)		
12	Transistor	2SA763P-6 or 5 (2SA725-F or G)		
13	Transistor	2SC945-Q, R or S		
214	Transistor	2SC945-Q, R or S	\square	
		400070		
1 2	Diode	1S2076 1S2076		
l	······································	1		
LS, TI	RANSFORMERS, AND FILTER	s.		
mbol	Description	Part No.	7	
1	FM antenna coil	ATC-021	1	
2	FM RF coil	ATC-015		
3	FM RF coil	ATC-016	\square	
.4 5	FM osc coil FM IF transformer	ATC-022 ATE-008	(see f	
6	FM DET transformer AM RF coil	T73-035 ATB-014		
7 8	AM osc coil	ATB-014		
		475 010		
1 2	FM ceramic filter FM ceramic filter	ATF-013 ATF-013		
3	FM ceramic filter	ATF-013		
4	AM ceramic filter	ATF-009		
5	LOW Pass filter	ATF-019		
.1	RF choke coil 18µH	ATH-007		
.2	RF choke coil 2.2µH	T24-028		
.3 .4	RF choke coil 2.2μΗ RF choke coil 2.2μΗ	T24-028 T24-028		
.5	RF choke coil 2.2µH	T24-028		
		T24-028		
.6	RF choke coil 2.2µH	127-020		
			\bigcirc	
			1. A. A.	

Symbol	Description	Part No.		
Q1	FET	3SK45-B		
Q2	FET	3SK45-B		
Q3	Transistor	2SC717		



Parts List of Headphone Jack Assembly (AWX-054)

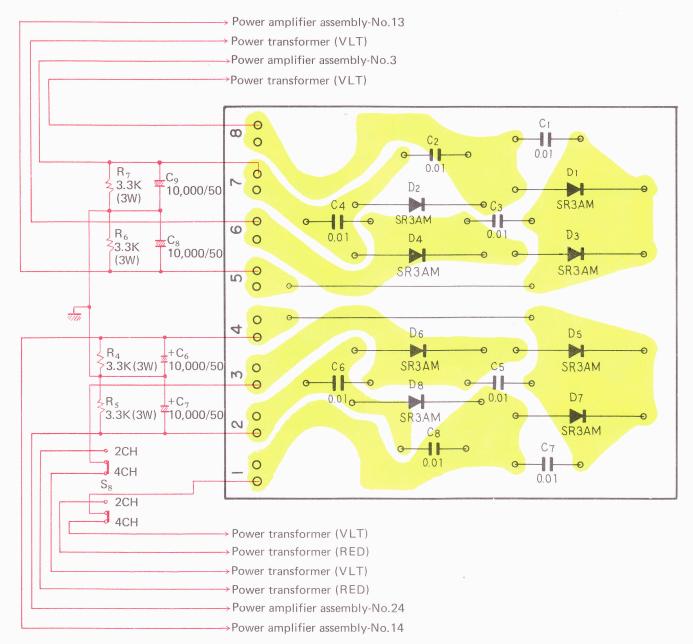
RESISTORS

Symbol	Des	Part No.		
R1	Metal oxide	150	2W	RS2P 151K
R2	Metal oxide	150	2W	RS2P 151K
R3	Metal oxide	150	2W	RS2P 151K
R4	Metal oxide	150	2W	RS2P 151K

OTHERS

Symbol	Description	Part No.		
	Phone jack (FRONT) Phone jack (REAR)	AKN-002 AKN-002		

13.4 POWER SUPPLY CIRCUIT B ASSEMBLY (AWR-039)



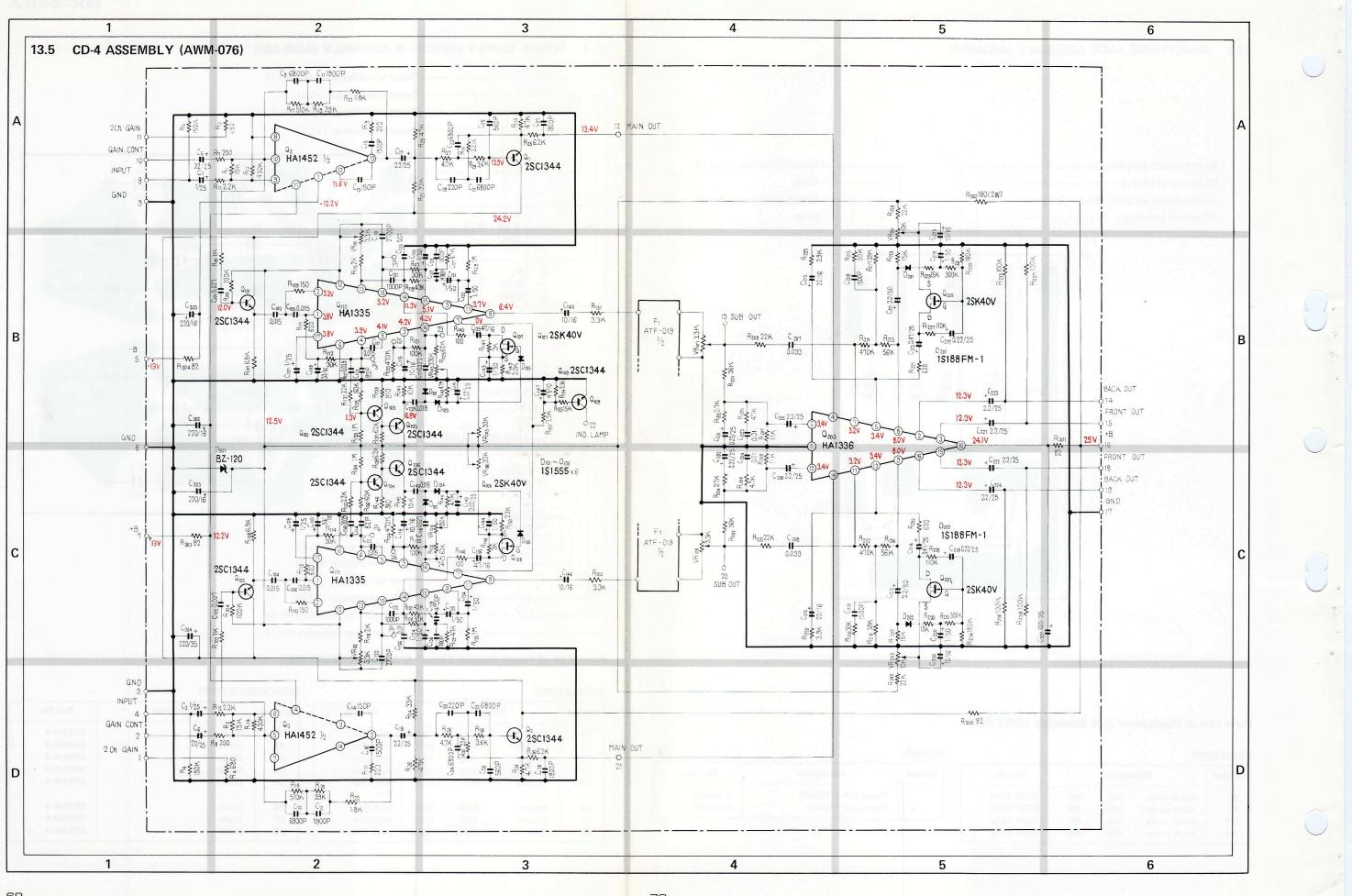
Parts List of Power Supply Circuit B Assembly (AWR-039)

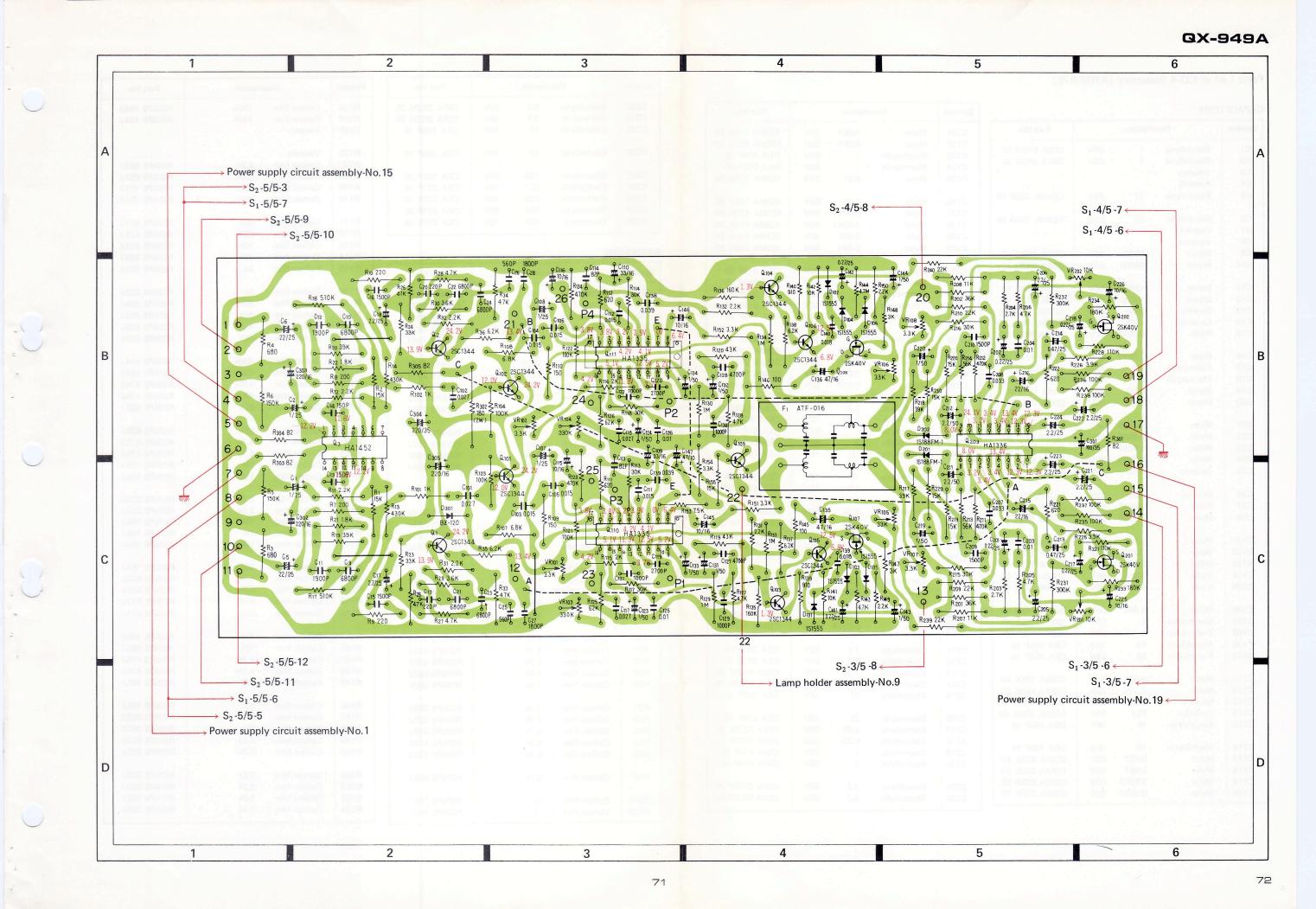
CAPACITORS

Symbol	De	escription	Part No.		
C1	Ceramic	0.01	150V	ACG-004	
C2	Ceramic	0.01	150V	ACG-004	
C3	Ceramic	0.01	150V	ACG-004	
C4	Ceramic	0.01	150V	ACG-004	
C5	Ceramic	0.01	150V	ACG-004	
C6	Ceramic	0.01	150V	ACG-004	
C7	Ceramic	0.01	150V	ACG-004	
C8	Ceramic	0.01	150V	ACG-004	

SEMICONDUCTORS

Symbol	Description	Part No.
D1	Diode	SR3AM-4
D2	Diode	SR3AM-4
D3	Diode	SR3AM-4
D4	Diode	SR3AM-4
D5	Diode	SR3AM-4
D6	Diode	SR3AM-4
D7	Diode	SR3AM-4
D8	Diode	SR3AM-4





Parts List of CD-4 Assembly (AWM-076)

• • * *

APACITORS		5		Symbol	Desi	ription		Part No.	
Symbol	Des	cription	- ¹	Part No.	C121	Mylar	0.001	50V	CQMA 102K 50
	—		0514		C122	Mylar	0.001	50V	COMA 102K 50
C1	Electrolytic	1	25V	CSSA 010M 25	C123	Electrolytic	1	50V	CEA 010P 50
C2	Electrolytic	1	25V	CSSA 010M 25	C124	Electrolytic	1	50V	CEA 010P 50
C3	Vacancy				C125	Mylar	0.01	50V	CQMA 103K 5
C4	Vacancy				0125	iviyiai	0.01	500	COMA TOSK S
C5	Electrolytic	22	25V	CEANL 220P 25				-01/	
					C126	Mylar	0.01	50V	CQMA 103K 5
C6	Electrolytic	22	25V	CEANL 220P 25	C127	Mylar	0.0047	50V	COMA 472K 5
	•	22	250		C128	Mylar	0.0047	50V	CQMA 472K 5
C7	Vacancy			•••••	C129	Mylar	0.001	50V	CQMA 102K 5
C8	Vacancy			· · · · · · · · · · · · · · · · · · ·	C130	Mylar	0.001	50V	CQMA 102K 5
C9	Styrol	6800p	50V	CQSA 682G 50					
C10	Styrol	6800p	50V	CQSA 682G 50	C131	Electrolytic	1	50V	CEA 010P 50
								-	
C11	Styrol	1900p	50V	CQSA 192G 50	C132	Electrolytic	1	50V	CEA 010P 50
C12	Styrol	1900p	50V	CQSA 192G 50	C133	Electrolytic	1	50V	CEA 010P 50
C13	Ceramic	150p	50V	CCDSL 151K 50	C134	Electrolytic	1	50V	CEA 010P 50
C13	Ceramic				C135	Electrolytic	47	16V	CEA 470P 16
		150p	50V	CCDSL 151K 50					
C15	Mylar	0.0015	50V	COMA 152K 50	C136	Electrolytic	47	16V	CEA 470P 16
					C137	Mylar	0.039	50V	COMA 393K 5
C16	Mylar	0.0015	50V	CQMA 152K 50	C138	Mylar	0.039	50V	CQMA 393K 5
C17	Electrolytic	2.2	25V	CSSA 2R2M 25					COMA 183K 5
C18	Electrolytic	2.2	25V	CSSA 2R2M 25	C139	Mylar	0.018	50V	
C19	Styrol	220p	50V	CQSA 221J 50	C140	Mylar	0.018	50V	COMA 183K 5
C20	Styrol	220p	50V	CQSA 2213 50	125 14 1				
020	Styroi	220p	500	CU3A 2213 50	C141	Electrolytic	0.22	25V	CSSA R22M 2
					C142	Electrolytic	0.22	25V	CSSA R22M 2
C21	Mylar	0.0068	50V	CQMA 682J 50	C143	Electrolytic	1	50V	CEA 010 50
C22	Mylar	0.0068	50V	CQMA 682J 50	C144	Electrolytic	1	50V	CEA 010 50
C23	Mylar	0.0068	50V	CQMA 682J 50	C145	Electrolytic	10	16V	CEA 100P 16
C24	Mylar	0.0068	50V	CQMA 682J 50	0145	LIECTIONYTIC	10	10 0	CLA IOU IO
C25	Ceramic	560p	50V	CKDYB 561K 50					
					C146	Electrolytic	10	16V	CEA 100P 16
C26	Ceramic	560p	50V	CKDYB 561K 50	C147	Electrolytic	47	10V	CEA 470P 10
								100 C	
C27	Mylar	0.0018	50V	CQMA 182K 50	C201	Electrolytic	0.22	25V	CSSA R22M 2
C28	Mylar	0.0018	50V	COMA 182K 50	C202	Electrolytic	0.22	25V	CSSA R22M 2
					C203	Mylar	0.01	50V	COMA 103K 5
C101	Mylar	0.027	50V	CQMA 273K 50	C204	Mylar	0.01	50V	COMA 103K 5
C102	Mylar	0.027	50V	CQMA 273K 50				·	
C103	Mylar	0.015	50V	CQMA 153K 50	C205	Electrolytic	2.2	25V	CSSA 2R2M 2
C104	Mylar	0.015	50V	CQMA 153K 50				1000	
1					C206	Electrolytic	2.2	25V	CSSA 2R2M 2
C105	Mylar	0.015	50V	CQMA 153K 50	C207	Mylar	0.033	50V	COMA 333K 5
	•• •				C208	Mylar	0.033	50V	COMA 333K 5
C106	Mylar	0.015	50V	CQMA 153K 50	C209	Mylar	0.0015	50V	COMA 152K 5
C107	Electrolytic	1	25V	CSSA 010M 25	C210	Mylar	0.0015	50V	CQMA 152K 5
C108	Electrolytic	1	25V	CSSA 010M 25	0210	141 9 101	0.0010		
C109	Electrolytic	33	16V	CEA 330P 16	0011	Electrolist	^ ^	F01/	
C110	Electrolytic	33	16V	CEA 330P 16	C211	Electrolytic	2.2	50V	CEA 2R2P 50
			•••		C212	Electrolytic	2.2	50V	CEA 2R2P 50
C111	Mylar	0.015	50V	COMA 153K 50	C213	Electrolytic	0.47	25V	CSSA R47M 2
		0.015			C214	Electrolytic	0.47	25V	CSSA R47M 2
C112	Mylar	0.015	50V	CQMA 153K 50	C215	Electrolytic	22	16V	CEA 220P 16
C113	Ceramic	82p	50V	CCDSL 820K 50					
C114	Ceramic	82p	50V	CCDSL 820K 50	C216	Electrolytic	22	16V	CEA 220P 16
C115	Electrolytic	10	16V	CEA 100P 16	C210	Electrolytic	0.22	25V	CSSA R22M 2
			1.1					1.1	CSSA R22M 2
C116	Electrolytic	10	16V	CEA 100P 16	C218	Electrolytic	0.22	25V	
C117	Mylar	0.027	50V	CQMA 273K 50	C219	Electrolytic	1	50V	CSSA 010P 50
	•				C220	Electrolytic	1	50V	CSSA 010P 50
C118	Mylar	0.027	50V	COMA 273K 50					
C119	Mylar	0.0027	50V	COMA 272K 50	C221	Electrolytic	2.2	25V	CSSA 2R2M 2
C120	Mylar	0.0027	50V	CQMA 272K 50	C222	Electrolytic	2.2	25V	CSSA 2R2M 2

				······································	[
Symbol	Des	cription		Part No.	Symbol	Des	cription
C223	Electrolytic	2.2	25V	CSSA 2R2M 25	R103	Carbon film	100k
C224	Electrolytic	2.2	25V	CSSA 2R2M 25	R104	Carbon film	100k
C225	Electrolytic	10	16V	CEA 100P 16	R105	Vacancy	
C226	Electrolytic	10	16V	CEA 100P 16	R106	Vacancy	
10					R107	Carbon film	6.8k
C301	Electrolytic	100	35V	CEA 101P 35	R108	Carbon film	6.8k
C302	Electrolytic	220	16V	CEA 221P 16	R109	Carbon film	150
C303	Electrolytic	220	16V	CEA 221P 16	R110	Carbon film	150
C304	Electrolytic	220	35V	CEA 221P 35			
C305	Electrolytic	220	16V	CEA 221P 16	R111	Carbon film	620
L					R112	Carbon film	620
DECIOTO	NDO				R113	Carbon film	30k
RESISTO	JRS				R114	Carbon film	30k
Symbol	Des	cription		Part No.	R115	Carbon film	2k
R1	Carbon film	15k		RD%PS 153J	R116	Carbon film	2k
R2	Carbon film	15k		RD%PS 153J	R117	Carbon film	30k
R3	Carbon film	680		RD%PS 681J	R118	Carbon film	30k
R4	Carbon film	680		RD%PS 681J	R119	Carbon film	43k
R5	Carbon film	150k		RD%PS 154J	R120	Carbon film	43k
R6	Carbon film	150k		RD%PS 154J	R121	Carbon film	100k
R7	Carbon film	200		RD%PS 201J	R122	Carbon film	100k
R8	Carbon film	200		RD%PS 201J	R123	Carbon film	470k
R9	Carbon film	220		RD¼PS 221J	R124	Carbon film	470k
R10	Carbon film	220		RD¼PS 221J	R125	Carbon film	62k
R11	Carbon film	2.2k		RD%PS 222J	R126	Carbon film	62k
R12	Carbon film	2.2k		RD%PS 222J	R127	Carbon film	4.7k
R13	Carbon film	430k		RD%PS 434J	R128	Carbon film	4.7k
R14	Carbon film	430k		RD%PS 434J	R129	Carbon film	1M
R15	Vacancy				R130	Carbon film	1M
R16	Vacancy				R131	Carbon film	2.2k
R17	Carbon film	510k		RD%PS 514J	R132	Carbon film	2.2k
R18	Carbon film	510k		RD%PS 514J	R133	Carbon film	1M
R19	Carbon film	39k		RD%PS 393J	R134	Carbon film	1M
R20	Carbon film	39k		RD%PS 393J	R135	Carbon film	160k
B21	Carbon film	1.8k		RD%PS 182J	R136	Carbon film	160k
R22	Carbon film	1.8k		RD1/4PS 182J	R137	Carbon film	6.2k
R23	Carbon film	33k		RD%PS 333J	R138	Carbon film	6.2k
R24	Carbon film	33k		RD%PS 333J	R139	Carbon film	910
R25	Carbon film	47k		RD14PS 473J	R140	Carbon film	910
, R26	Carbon film	47k		RD%PS 473J	R141	Carbon film	10k
R27	Carbon film	4.7k		RD%PS 472J	R142	Carbon film	10k
R28	Carbon film	4.7k		RD%PS 472J	R143	Carbon film	4.7M
R29	Carbon film	3.6k		RD%PS 362J	R144	Carbon film	4.7M
R30	Carbon film	3.6k		RD%PS 362J	R145	Carbon film	100
R31	Carbon film	2.2k		RD¼PS 222J	R146	Carbon film	100
R32	Carbon film	2.2k		RD%PS 222J	R147	Carbon film	3k
R33	Carbon film	4.7k		RD%PS 472J	R148	Carbon film	3k
R34	Carbon film	4.7k		RD%PS 472J	R149	Carbon film	2.2k
R35	Carbon film	6.2k		RD14PS 622J	R150	Carbon film	2.2k
R36	Carbon film	6.2k		RD%PS 622J	R151	Carbon film	3.3k
					R152	Carbon film	3.3k
R101	Carbon film	1k		RD%PS 102J	R153	Carbon film	7.5k
R102	Carbon film	1k		RD%PS 102J	R154	Carbon film	3.3k
L							

Part No.]		
RD%PS 104J RD%PS 104J			
RD%PS 682J			
RD14PS 682J			
RD%PS 151J RD%PS 151J			
RD%PS 621J RD%PS 621J			
RD%PS 303J			
RD%PS 303J			
RD%PS 202J			
RD%PS 202J			
RD%PS 303J			
RD¼PS 303J RD¼PS 433J	1		
RD%PS 433J	ľ	1	
RD14PS 104J	\		
RD%PS 104J RD%PS 104J			
RD%PS 474J			
RD%PS 474J RD%PS 623J			
RD%PS 623J RD%PS 472J			
RD%PS 472J			
RD%PS 105J			
RD%PS 105J			
RD14PS 222J			
RD%PS 222J RD%PS 105J			
RD%PS 105J			
RD%PS 164J			
RD%PS 164J	(\frown	
RD%PS 622J			
RD%PS 622J RD%PS 911J			
RD%PS 911J			
RD%PS 103J			
RD%PS 103J			
RD¼PS 475J RD¼PS 475J			
RD%PS 475J RD%PS 101J			
RD%PS 101J RD%PS 302J			
RD%PS 302J			
RD%PS 222J RD%PS 222J			
110/4F0 222J			
RD%PS 332J			
RD%PS 332J RD%PS 752J			
RD%PS 332J	(
· · · ·	7		

Symbol	Des	cription		Part	No.	Symbol	
R155	Carbon film	15k		RD%PS	153J	VR106	Varia
						VR107	Varia
R201	Carbon film	36k		RD14PS	363J	VR108	Varia
R202	Carbon film	36k		RD14PS	363J	VR201	Varia
R203	Carbon film	2.7k		RD ¹ / ₄ PS	272J	VR202	Varia
R204	Carbon film	2.7k		RD%PS			
R204	Carbon film	4.7k		RD%PS			
R205	Carbon min	4.75		110/410	7720	SEMICON	IDUC.
R206	Carbon film	4.7k		RD%PS	472J		
R207	Carbon film	11k		RD14PS	113J	Symbol	
R208	Carbon film	11k		RD14PS	113J	0.1	-
R209	Carbon film	22k		RD%PS	223J	Q1	Tran
R210	Carbon film	22k		RD%PS	223J	02	Tran
						<u>u</u> z	IIdi
R211	Carbon film	470k		RD14PS		03	IC
R212	Carbon film	470k		RD%PS	474J		
R213	Carbon film	56k		RD%PS	563J	Q101	Tran
R214	Carbon film	56k		RD%PS	563J	0.01	1141
R215	Carbon film	30k		RD%PS	303J	0400	· . -
						Q102	Tran
R216	Carbon film	30k		RD14PS	303J	Q103	Tran
R217	Carbon film	39k		RD%PS	393J	0103	1141
R218	Carbon film	39k		RD%PS	393J	a service a	$(k_{i}) \in \mathbb{N}$
R219	Carbon film	15k		RD%PS	153J		
R220	Carbon film	15k		RD%PS		Q104	Trar
						Q105	Trar
R221	Carbon film	620		RD%PS			
R222	Carbon film	620		RD%PS	621J	Q106	Trar
R223	Vacancy			· · · · · · ·	••		
R224	Vacancy				••		
R225	Carbon film	3.9k		RD%PS	392J	Q107	FET
		0.01		RD%PS	2021		
R226	Carbon film	3.9k		1.1		Q108	FET
R227	Carbon film	110k		RD%PS			
R228	Carbon film	110k		RD14PS		Q109	Trar
R229	Carbon film	15k		RD1/4PS	5 153J		
R230	Carbon film	15k		RD%PS	5 153J		
						Q110	IC
R231	Carbon film	300k		RD%PS		Q111	IC
R232	Carbon film	300k		RD%PS			
R233	Carbon film	180k		RD%PS	5 184J	0201	FET
R234	Carbon film	180k		RD%PS	5 184J		
R235	Carbon film	100k		RD%PS	5 104J	0202	FET
		400'			1041		
R236	Carbon film	100k		RD%PS		Q203	IC
R237	Carbon film	100k					
R238	Carbon film	100k		RD%PS		D101	Dio
R239	Carbon film	22k		RD%PS	-		
R240	Carbon film	22k		RD%PS	5 223J	D102	Dio
R301	Carbon film	82		RD%PS	; 820J		
	Metal oxide	82 180	2W	RS2P		D103	Dio
R302			2 V V	RD%PS		H Star	
R303	Carbon film	82		1.	5 820J 5 820J		
R304	Carbon film	82 82		1	5 820J 5 820J	D104	Dio
R305	Carbon film	ō2		nu/4PS	. 0203	DIO	
VR101	Variable (sen	ni-fixed)	3.3k-B	ACP-04	47	D105	Dio
VR102	Variable (sen		3.3k-B	ACP-0	47	D100	n:-
VR103	Variable (sen		330k-B	ACP-0	42	D106	Dio
VR104			330k-B	ACP-0		h i han a tur	1
	1		33k-B	ACP-0			•
VR105		m-nxeu/		1.01.0]	

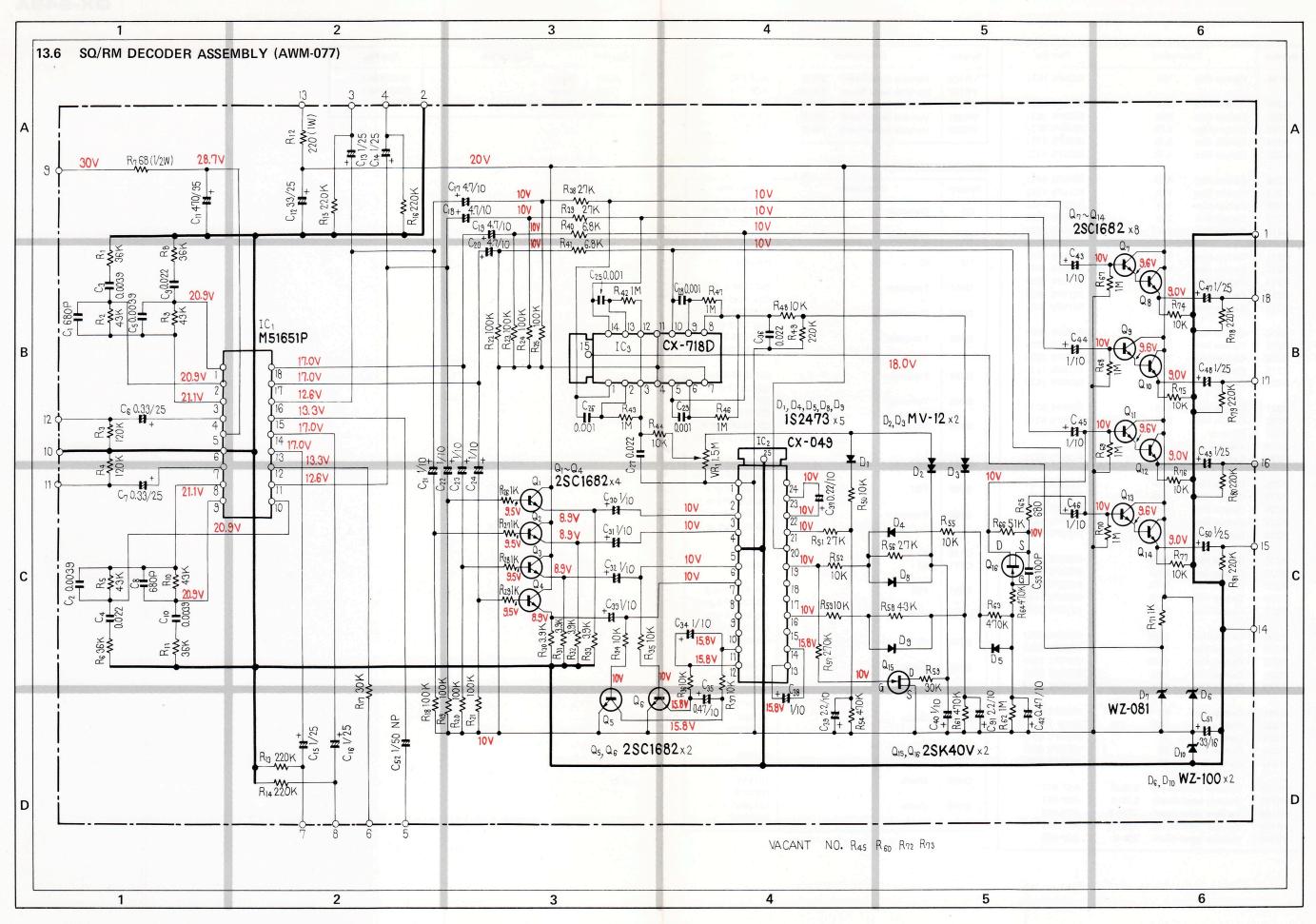
Symbol	Description	Part No.	
VR106	Variable (semi-fixed)	33k-B	ACP-025
VR107	Variable (semi-fixed)	3.3k-B	ACP-028
VR108	Variable (semi-fixed)	3.3k-B	ACP-028
VR201	Variable (semi-fixed)	10k-B	C92-049
VR202	Variable (semi-fixed)	10k-B	C92-049

CTORS

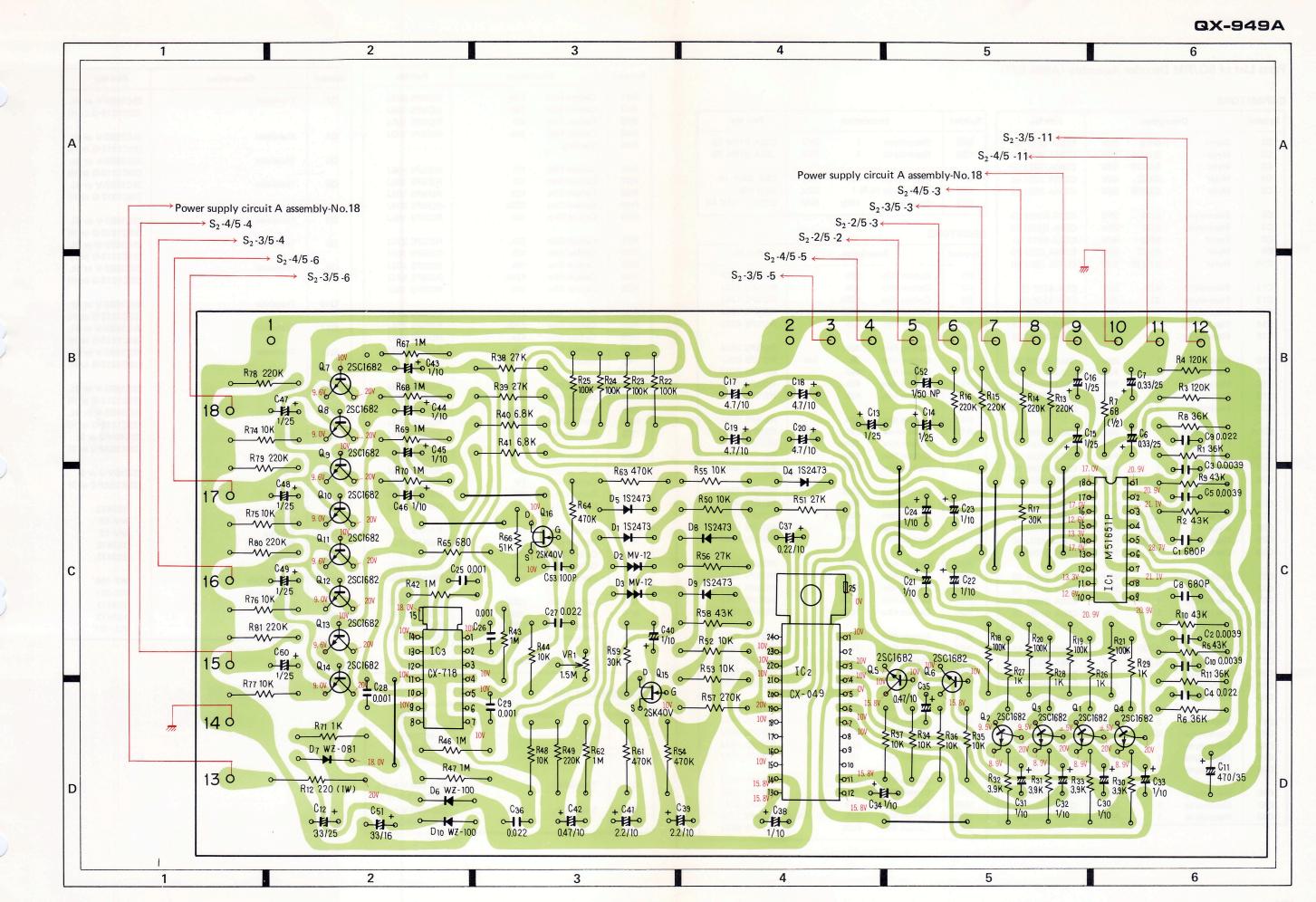
nbol	Description	Part No.
1	Transistor	2SC1344-E or F
		(2SC1312-G or H)
2	Transistor	2SC1344-E or F
		(2SC1312-G or H)
3	IC	HA1452
101	Transistor	2SC1344-E or F
e de la c		(2SC1312-G or H)
102	Transistor	2SC1344-G or F
	-	(2SC1312-G or H)
103	Transistor	2SC1344-E or F
		(2SC1312-G or H)
104	Transistor	2SC1344-E or F
104	11411919101	(2SC1312-G or H)
105	Transistor	2SC1344-E or F
		(2SC1312-G or H)
106	Transistor	2SC1344-E or F
		(2SC1312-G or H)
107	FET	2SK40V-2 or 3
		(2SK30AP-2 or 3)
108	FET	2SK40V-2 or 3
		(2SK30AP-2 or 3)
109	Transistor	2SC1344-E or F
		(2SC1312-G or H)
110	IC	HA1335
111		HA1335
201	FET	2SK40V-2 or 3
201	rei	(2SK30AP-2 or 3)
202	FET	2SK40V-2 or 3
202		(2SK30AP-2 or 3)
203	IC	HA1336
200		
101	Diode	1S1555
		(1S2473)
102	Diode	1S1555
		(1\$2473)
103	Diode	1S1555
		(1S2473)
0104	Diode	1\$1555
104		(1\$2473)
0105	Diode	1\$1555
		(1\$2473)
0106	Diode	1S1555
		(1S2473)
		L

Symbol	Description	Part No.
D201	Diode	1S188FM-1
D202	Diode	1S188FM-1
D301	Zener diode	BZ-120

QX-949A







Parts List of SQ/RM Decoder Assembly (AWM-077)

CAPACITORS

Symbol	Des	cription		Part No.	Symbol	Des	cription		Part No.
C1	Styrol	680p	50V	CQSA 681J 50	C49	Electrolytic	1	25V	CSSA 010M 25
C2	Mylar	0.0039	50V	CQMA 392J 50	C50	Electrolytic	1	25V	CSSA 010M 25
C3	Mylar	0.0039	50V	CQMA 392J 50			•		
	•	0.0039	50V		C51	Electrolytic	33	16V	CEA 330P 16
C4	Mylar			CQMA 223J 50	C51	Electrolytic (N		50V	ACH-305
C5	Mylar	0.0039	50V	COMA 392J 50	C52	Ceramic	100p	50V	CCDSL 101K 5
C6	Electrolytic	0.33	25V	CSSA R33M 25		ocrame	1000		
C7	Electrolytic	0.33	25V	CSSA R33M 25					
C8	Styrol	680p	50V	CQSA 681J 50	RESISTO	RS			
C9	Mylar	0.022	50V	CQMA 223J 50					Part No.
C10	Mylar	0.022	50V	COMA 392J 50	Symbol	Desi	cription		Part No.
					R1	Carbon film	36k		RD1/2PS 363J
C11	Electrolytic	470	35V	CEA 471P 35	R2	Carbon film	43k		RD1/4PS 433J
C12	Electrolytic	33	25V	CEA 330P 25	R3	Carbon film	120k		RD¼PS 124J
C13	Electrolytic	1	25V	CSSA 010M 25	R4	Carbon film	120k		RD%PS 124J
1					R5	Carbon film	43k		RD1/4PS 433J
C14	Electrolytic	1	25V	CSSA 010M 25		Carbon nim			112741 0 4000
C15	Electrolytic	1	25V	CSSA 010M 25		Carbon film	261		RD%PS 363J
010			0-11	0000 01000 0-	R6	Carbon film	36k	1/14/	RD%PS 363J RD%PS 680J
C16	Electrolytic	1	25V	CSSA 010M 25	R7	Carbon film	68	1⁄2W	1 State of the
C17	Electrolytic	4.7	10V	CSSA 4R7M 10	R8	Carbon film	36k		RD%PS 363J
C18	Electrolytic	4.7	10V	CSSA 4R7M 10	R9	Carbon film	43k		RD1/4PS 433J
C19	Electrolytic	4.7	10V	CSSA 4R7M 10	R10	Carbon film	43k		RD1/4PS 433J
C20	Electrolytic	4.7	10V	CSSA 4R7M 10					
					R11	Carbon film	36k		RD14PS 363J
C21	Electrolytic	1	10V	CSSA 010M 10	R12	Metal oxide	220	1W	RS1P 221J
C22	Electrolytic	1	10V	CSSA 010M 10	R13	Carbon film	220k		RD¼PS 224J
C23	Electrolytic	1	10V	CSSA 010M 10	R14	Carbon film	220k		RD%PS 224J
C24	Electorlytic	1	10V	CSSA 010M 10	R15	Carbon film	220k		RD%PS 224J
C25	Mylar	0.001	50V	CQMA 102J 50					
	,	01001			R16	Carbon film	220k		RD%PS 224J
C26	Mylar	0.001	50V	COMA 102J 50	R17	Carbon film	30k		RD%PS 303J
C27	Mylar	0.022	50V	CQMA 1023 50	R18	Carbon film	100k		RD%PS 104J
					R19	Carbon film	100k		RD%PS 104J
C28	Mylar	0.001	50V	CQMA 102J 50	R20		100k		RD%PS 104J
C29	Mylar	0.001	50V	CQMA 102J 50	R20	Carbon film	TUUK		ND/4F3 1043
C30	Electrolytic	1	10V	CSSA 010M 10		0.1	1001		RD%PS 104J
					R21	Carbon film	100k		
C31	Electrolytic	1	10V	CSSA 010M 10	R22	Carbon film	100k		RD%PS 104J
C32	Electrolytic	1	10V	CSSA 010M 10	R23	Carbon film	100k		RD%PS 104J
C33	Electrolytic	1	10V	CSSA 010M 10	R24	Carbon film	100k		RD%PS 104J
C34	Electrolytic	1	10V	CSSA 010M 10	R25	Carbon film	100k		RD%PS 104J
C35	Electrolytic	0.47	10V	CSSA R47M 10					
· · ·					R26	Carbon film	1k		RD%PS 102J
C36	Mylar	0.022	50V	COMA 223J 50	R27	Carbon film	1k		RD¼PS 102J
C37	Electrolytic	0.22	10V	CSSA R22M 10	R28	Carbon film	1k		RD1/4PS 102J
C38	Electrolytic	1	10V	CSSA 010M 10	R29	Carbon film	1k		RD%PS 102J
C39	Electrolytic	2.2	10V	CSSA 2R2M 10	R30	Carbon film	3.9k		RD%PS 392J
C40	Electrolytic	1	10V	CSSA 2112M 10					
U-10	LICCLOTYLIC		100		R31	Carbon film	3.9k		RD%PS 392J
044	Electrol	2.2	1017	0000 00014 40	R32	Carbon film	3.9k		RD%PS 392J
C41	Electrolytic	2.2	10V	CSSA 2R2M 10					RD%PS 392J
C42	Electrolytic	0.47	10V	CSSA R47M 10	R33	Carbon film	3.9k		
C43	Electrolytic	1	10V	CSSA 010M 10	R34	Carbon film	10k		RD%PS 103J
C44	Electrolytic	1	10V	CSSA 010M 10	R35	Carbon film	10k		RD%PS 103J
C45	Electrolytic	1	10V	CSSA 010M 10					
· · · · · ·				. Presidente de la Color	R36	Carbon film	10k		RD%PS 103J
C46	Electrolytic	1	10V	CSSA 010M 10	R37	Carbon film	10k		RD%PS 103J
C47	Electrolytic	1	25V	CSSA 010M 25	R38	Carbon film	27k		RD1/2PS 273J
C48	Electrolytic	1	25V	CSSA 010M 25	R39	Carbon film	27k		RD%PS 273J
			1		R40	Carbon film	6.8k		RD1/4PS 682J

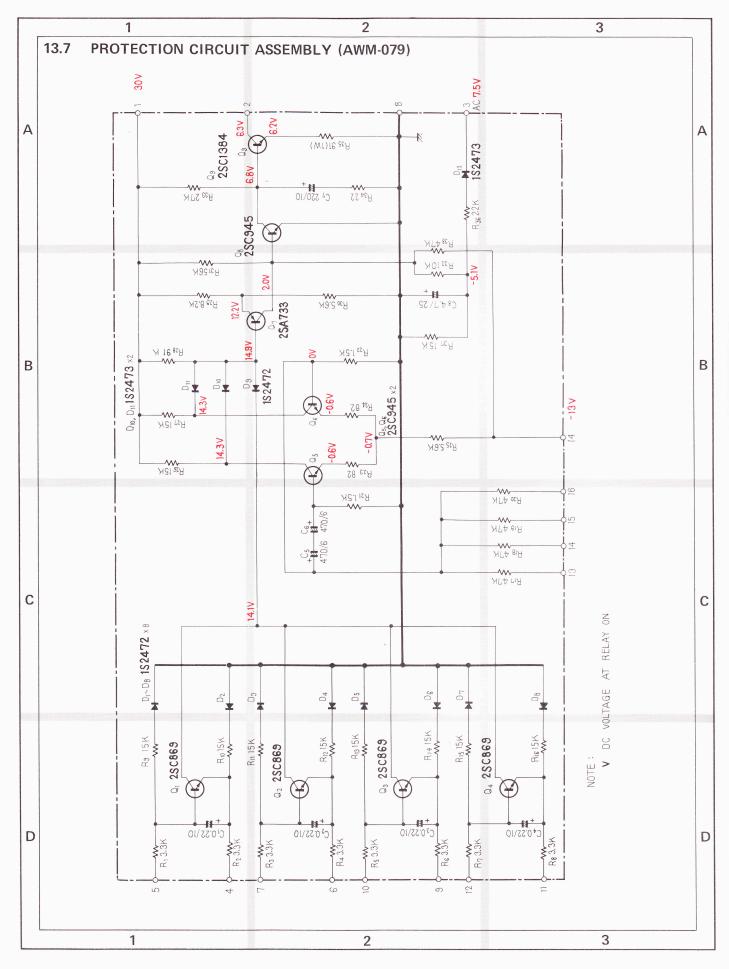
Symbol	Des	cription		Part No.	Symbol	Description	P
R41	Carbon film	6.8k		RD1/4PS 682J	03	Transistor	2SC1
R42	Carbon film	1M		RD1/2PS 105J			(250
R43	Carbon film	1M		RD14PS 105J			(200
R44	Carbon film	10k		RD%PS 103J	Q4	Transistor	2SC1
R45	Vacancy						(250
					Q5	Transistor	2SC1
R46	Carbon film	1M		RD¼PS 105J			(2SC
R47	Carbon film	1M		RD1/4PS 105J	Q6	Transistor	2SC1
R48	Carbon film	10k		RD%PS 103J			(2SC
R49	Carbon film	220k		RD%PS 224J			
R50	Carbon film	10k		RD%PS 103J	Q7	Transistor	2SC1
R51	Carbon film	27k		RD%PS 273J	Q8	Transistor	(2SC) 2SC1
R52	Carbon film	10k	1	RD%PS 103J	00	Tansistor	(25C)
R53	Carbon film	10k	1	RD%PS 103J	Q9	Transistor	250
R54	Carbon film	470k		RD%PS 474J	09	Tansistor	(2SC)
R55	Carbon film	10k		RD%PS 103J			1200
					Q10	Transistor	2SC1
R56	Carbon film	27k		RD%PS 273J		1181813101	(2SC
R57	Carbon film	270k		RD%PS 274J	Q11	Transistor	250
R58	Carbon film	43k		RD%PS 433J		Tanaiator	(2SC)
R59	Carbon film	30k		RD14PS 303J	Q12	Transistor	2SC1
R60	Vacancy						(250
R61	Carbon film	470k		RD%PS 474J	Q13	Transistor	2SC1
R62	Carbon film	1M		RD1/2PS 105J		1 and 10 con	(250
R63	Carbon film	470k		RD%PS 474J	Q14	Transistor	2SC1
R64	Carbon film	470k		RD14PS 474J			(2SC
R65	Carbon film	680		RD%PS 681J	Q15	FET	2SK4
							(2SK
R66	Carbon film	51k		RD%PS 513J			
R67	Carbon film	1M		RD¼PS 105J	Q16	FET	2SK4
R68	Carbon film	1M		RD%PS 105J			(2SK
R69	Carbon film	1M		RD%PS 105J			
R70	Carbon film	1M		RD¼PS 105J	D1	Diode	1
					D2	Varistor	N
R71	Carbon film	1k		RD¼PS 102J	D3	Varistor	N
R74	Carbon film	10k	1	RD%PS 103J	D4	Diode	1:
R75	Carbon film	10k		RD%PS 103J	D5	Diode	1:
R76	Carbon film	10k		RD%PS 103J			
R77	Carbon film	10k	· .	RD%PS 103J	D6	Zener diode	W
					D7	Zener diode	W
R78	Carbon film	220k		RD%PS 224J	D8	Diode	1
R79	Carbon film	220k		RD1/4PS 224J	D9	Diode	.1:
R80	Carbon film	220k		RD%PS 224J	D10	Zener diode	- W
R81	Carbon film	220k		RD¼PS 224J			
VR1	Variable (semi	-fixed) 1	.5M-B	ACP-048			

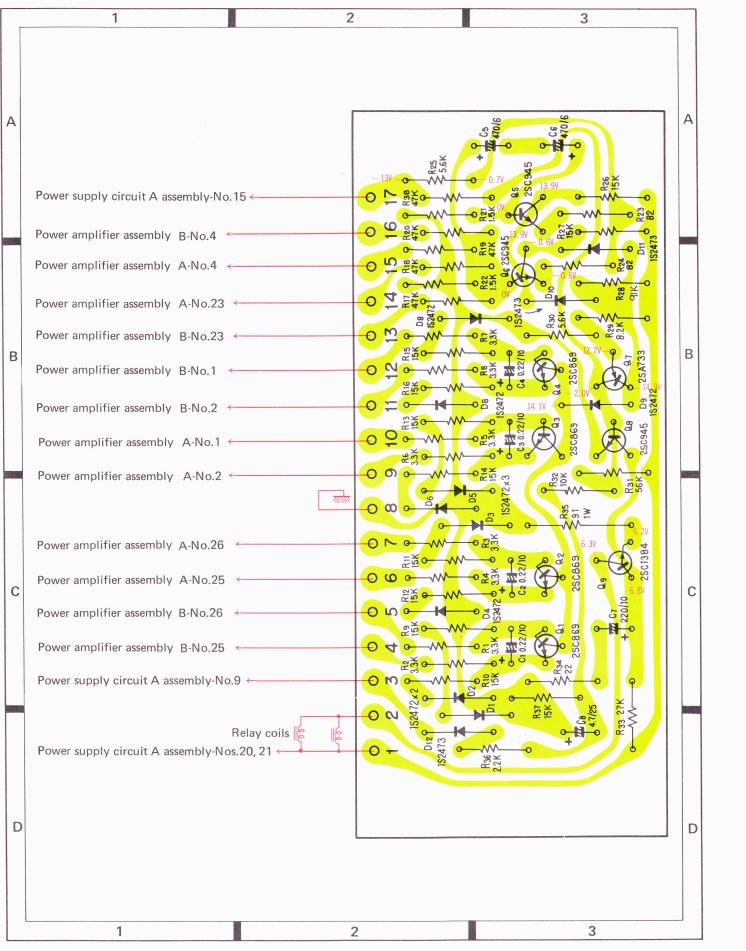
SEMICONDUCTORS

Symbol	Description	Part No.
IC1	IC	M51651P
IC2	IC	CX-049
IC3	IC	CX-718D
Q1	Transistor	2SC1682-V or BL
		(2SC1312-G or H)
02	Transistor	2SC1682-V or BL
		(2SC1312-G or H)

81

	1
Part No.	
2SC1682-V or BL (2SC1312-G or H)	
2SC1682-V or BL (2SC1312-G or H) 2SC1682-V or BL (2SC1312-G or H) 2SC1682-V or BL (2SC1312-G or H)	
2SC1682-V or BL (2SC1312-G or H) 2SC1682-V or BL (2SC1312-G or H) 2SC1682-V or BL (2SC1312-G or H)	
2SC1682-V or BL (2SC1312-G or H) 2SC1682-V or BL (2SC1312-G or H) 2SC1682-V or BL (2SC1312-G or H)	 A second sec second second sec
2SC1682-V or BL (2SC1312-G or H) 2SC1682-V or BL (2SC1312-G or H) 2SK40V-2 or 3 (2SK30AP-2 or 3)	
2SK40V-2 or 3 (2SK30AP-2 or 3)	
1S2473 MV-12 MV-12 1S2473 1S2473	
WZ-100 WZ-081 1S2473 1S2473 WZ-100	





QX-949A

Parts List of Protection Circuit Assembly (AWM-079)

CAPACITORS

Symbol	Des	cription		Part No.
C1	Electrolytic	0.22	10V	CSSA R22M 10
C2	Electrolytic	0.22	10V	CSSA R22M 10
C3	Electrolytic	0.22	10V	CSSA R22M 10
C4	Electrolytic	0.22	10V	CSSA R22M 10
C5	Electrolytic	470	6V	CEA 471P 6
C6	Electrolytic	470	6V	CEA 471P 6
C7	Electrolytic	220	10V	CEA 221P 10
C8	Electrolytic	4.7	25V	CEA 4R7P 25

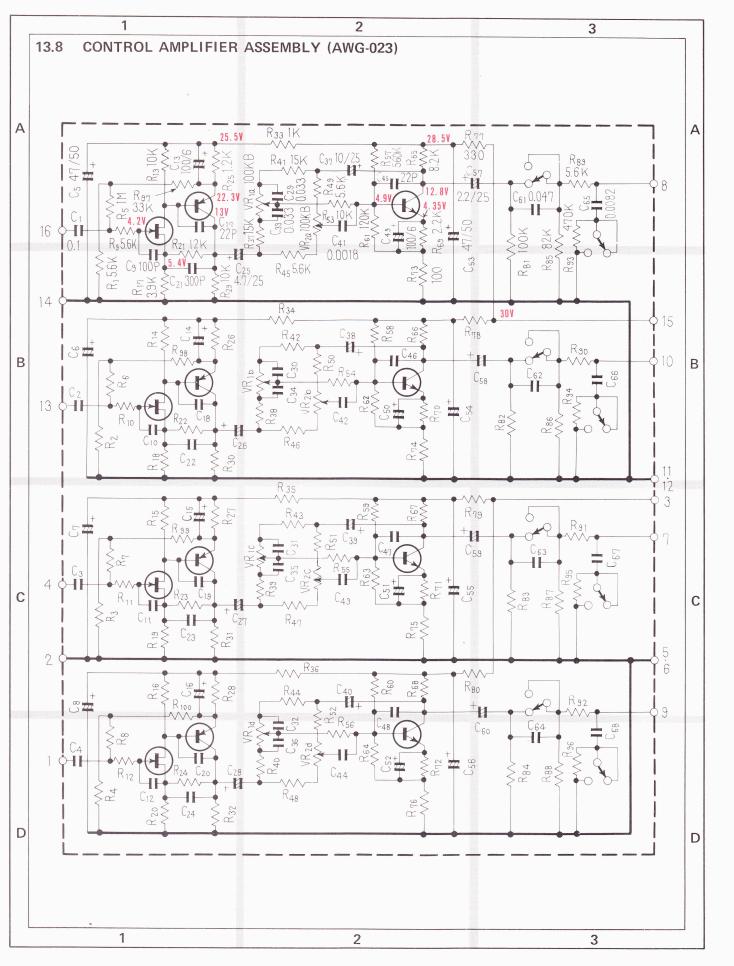
Symbol	Desc	cription	Part No.
R36	Carbon film	2.2k	RD1/4PM 222J
R37	Carbon film	15k	RD1/4PM 153J
R38	Carbon film	47k	RD1/4PM 473J

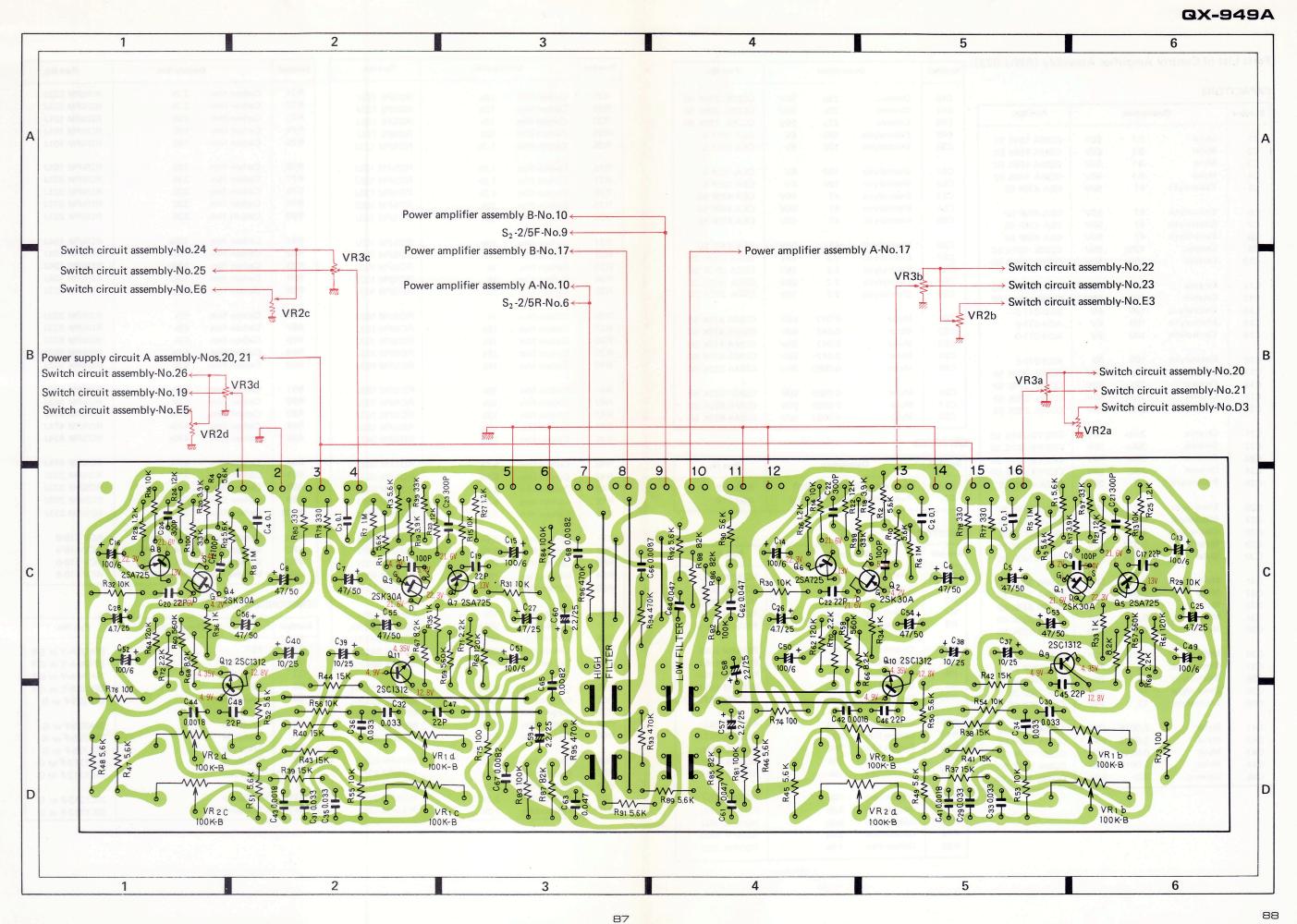
SEMICONDUCTORS

RESISTORS

R1 R2	0 1 (1)			
R2	Carbon film	3.3k		RD%PM 332J
	Carbon film	3.3k		RD1/4PM 332J
R3	Carbon film	3.3k		RD1/2PM 332J
R4	Carbon film	3.3k		RD%PM 332J
R5	Carbon film	3.3k		RD¼PM 332J
R6	Carbon film	3.3k		RD%PM 332J
R7	Carbon film	3.3k		RD1/4PM 332J
R8	Carbon film	3.3k		RD1/4PM 332J
R9	Carbon film	15k		RD1/4PM 153J
R10	Carbon film	15k		RD%PM 153J
R11	Carbon film	15k		RD%PM 153J
R12	Carbon film	15k		RD%PM 153J
R13	Carbon film	15k		RD1/2PM 153J
R14	Carbon film	15k		RD1/2PM 153J
R15	Carbon film	15k		RD%PM 153J
R16	Carbon film	15k		RD1/2PM 153J
R17	Carbon film	47k		RD1/2PM 473J
R18	Carbon film	47k		RD1/2PM 473J
R19	Carbon film	47k		RD1/4PM 473J
R20	Carbon film	47k		RD1/2PM 473J
R21	Carbon film	1.5k		RD%PM 152J
R22	Carbon film	1.5k		RD1/2PM 152J
R23	Carbon film	82		RD1/4PM 820J
R24	Carbon film	82		RD1/4PM 820J
R25	Carbon film	5.6k		RD1/4PM 562J
R26	Carbon film	15k		RD¼PM 153J
R27	Carbon film	15k		RD%PM 153J
R28	Carbon film	91k		RD%PM 913J
R29	Carbon film	8.2k		RD%PM 822J
R30	Carbon film	5.6k		RD1/4PM 562J
R31	Carbon film	56k		RD¼PM 563J
R32	Carbon film	10k		RD%PM 103J
R33	Carbon film	27k		RD%PM 273J
R34	Carbon film	22		RD¼PM 220J
R35	Metal oxide	91	1 W	RS1P 910J

Symbol	Description	Part No.
Q.1	Transistor	2SC869-C, B or D (2SC1515K)
Q2	Transistor	2SC869-C, B or D (2SC1515K)
Q3	Transistor	2SC869-C, B or D (2SC1515K)
Q4	Transistor	2SC869-C, B or D (2SC1515K)
Q5	Transistor	2SC945-R or Q
Q6	Transistor	2SC945-R or Q
Q7	Transistor	2SA733-R or Q
0.8	Transistor	2SC945-R or Q
Q9	Transistor	2SC1384-Q or R
D1	Diode	1S2472
D2	Diode	1S2472
D3	Diode	1S2472
D4	Diode	1S2472
D5	Diode	1S2472
D6	Diode	1S2472
D7	Diode	1S2472
D8	Diode	1S2472
D9	Diode	1S2472
D10	Diode	1S2473
D11	Diode	1S2473
D12	Diode	1S2473





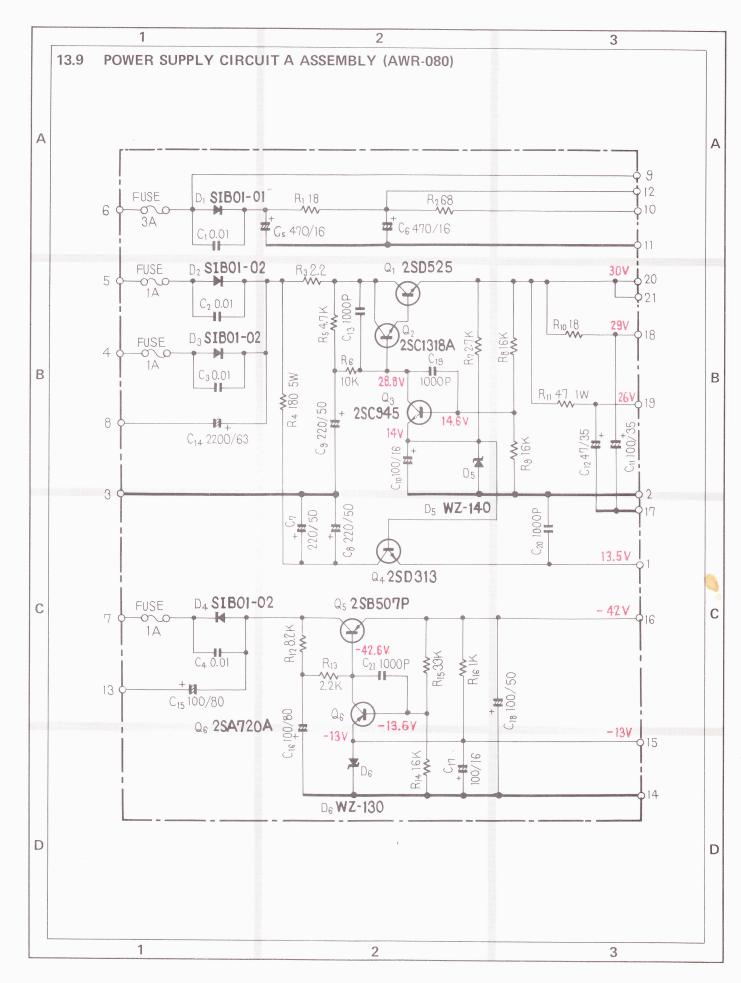
Parts List of Control Amplifier Assembly (AWG-023)

mbol	De	scription		Part No.
C1	Mylar	0.1	50V	COMA 104K 50
C2	Mylar	0.1	50V	COMA 104K 50
23	Mylar	0.1	50V	COMA 104K 50
C4	Mylar	0.1	50V	COMA 104K 50
25	Electrolytic	47	50V	CEA 470P 50
26	Electrolytic	47	50V	CEA 470P 50
27	Electrolytic	47	50V	CEA 470P 50
28	Electrolytic	47	50V	CEA 470P 50
29	Ceramic	100p	50V	CCDSL 101K 50
:10	Ceramic	100p	50V	CCDSL 101K 50
:11	Ceramic	100p	50V	CCDSL 101K 50
212	Ceramic	100p	50V	CCDSL 101K 50
213	Electrolytic	100	6V	ACH-311-0
214	Electrolytic	100	6V	ACH-311-0
15	Electrolytic	100	6V	ACH-311-0
16	Electrolytic	100	6V	ACH-311-0
:17	Ceramic	22p	50V	CCDSL 220K 50
:18	Ceramic	22p	50V	CCDSL 220K 50
19	Ceramic	22p	50V	CCDSL 220K 50
20	Ceramic	22p	50V	CCDSL 220K 50
21	Ceramic	300p	50V	CKDYB 301K 50
22	Ceramic	300p	50V	CKDYB 301K 50
23	Ceramic	300p	50V	CKDYB 301K 50
24	Ceramic	300p	50V	CKDYB 301K 50
25	Electrolytic	4.7	25V	CSZA 4R7P 25
26	Electrolytic	4.7	25V	CSZA 4R7P 25
27	Electrolytic	4.7	25V	CSZA 4R7P 25
28	Electrolytic	4.7	25V	CSZA 4R7P 25
29	Mylar	0.033	50V	COMA 333K 50
30	Mylar	0.033	50V	CQMA 333K 50
31	Mylar	0.033	50V	CQMA 333K 50
32	Mylar	0.033	50V	CQMA 333K 50
33	Mylar	0.033	50V	CQMA 333K 50
34	Mylar	0.033	50V	COMA 333K 50
85	Mylar	0.033	50V	CQMA 333K 50
36	Mylar	0.033	50V	СОМА 333К 50
37	Electrolytic	10	25V	CEA 100P 25
38	Electrolytic	10	25V	CEA 100P 25
39	Electrolytic	10	25V	CEA 100P 25
0	Electrolytic	10	25V	CEA 100P 25
1	Mylar	0.0018	50V	COMA 182K 50
42	Mylar	0.0018	50V	COMA 182K 50
13	Mylar	0.0018	50V	CQMA 182K 50
4	Mylar	0.0018	50V	COMA 182K 50
5	Ceramic	22p	50V	CCDSL 220K 50

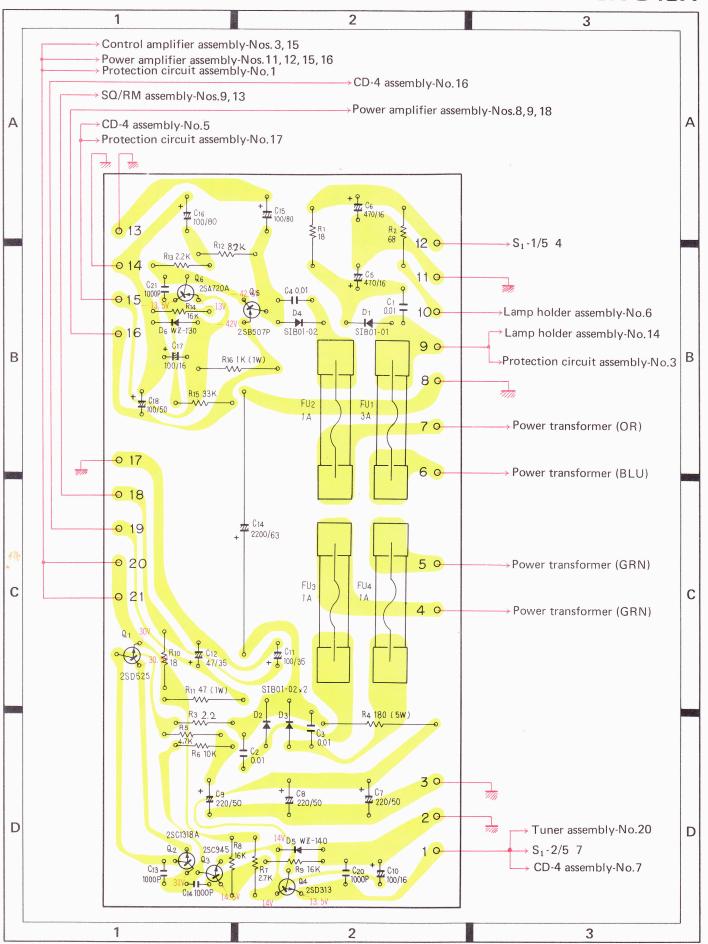
Symbol	Des	cription		Part No.
C46	Ceramic	22p	50V	CCDSL 220K 50
C47	Ceramic	22p	50V	CCDSL 220K 50
C48	Ceramic	22p	50V	CCDSL 220K 50
C49	Electrolytic	100	6V	CEA 101P 6
C50	Electrolytic	100	6V	CEA 101P 6
C51	Electrolytic	100	6V	CEA 101P 6
C52	Electrolytic	100	6V	CEA 101P 6
C53	Electrolytic	47	50V	CEA 470P 50
C54	Electrolytic	47	50V	CEA 470P 50
C55	Electrolytic	47	50V	CEA 470P 50
C56	Electrolytic	47	50V	CEA 470P 50
C57	Electrolytic	2.2	25V	CSZA 2R2P 25
C58	Electrolytic	2.2	25V 25V	CSZA 2R2P 25
C59	Electrolytic	2.2	25V 25V	CSZA 2R2P 25
C60	Electrolytic	2.2	25V 25V	CSZA 2R2P 25
C61	Mular	0.047	EOV /	COMA 470K 50
C61	Mylar	0.047	50V	COMA 473K 50
C62	Mylar	0.047	50V	COMA 473K 50
C63	Mylar	0.047	50V	COMA 473K 50
064	Mylar	0.047	50V	COMA 473K 50
C65	Mylar	0.0082	50V	COMA 822K 50
C66	Mylar	0.0082	50V	COMA 822K 50
C67	Mylar	0.0082	50V	CQMA 822K 50
C68	Mylar	0.0082	50V	CQMA 822K 50
Symbol	Description			Part No.
S1	Push switch (L	.OW FILTE		ASG-019
	Push switch (L Push switch (H	.OW FILTE		
S1	Push switch (H	.OW FILTE		ASG-019
S1 S2	Push switch (F	.OW FILTE		ASG-019
S1 S2 ESISTO Symbol R1	Push switch (H RS Desc Carbon film	OW FILTE HIGH FILT ription 5.6k		ASG-019 ASG-019 Part No. RD%PM 562J
S1 S2 ESISTO Symbol R1 R2	Push switch (F RS Desc Carbon film Carbon film	OW FILTE HIGH FILT ription 5.6k 5.6k		ASG-019 ASG-019 Part No. RD%PM 562J RD%PM 562J
S1 S2 ESISTO Symbol R1 R2 R3	Push switch (F RS Carbon film Carbon film Carbon film	OW FILTE HIGH FILT cription 5.6k 5.6k 5.6k 5.6k		ASG-019 ASG-019 Part No. RD%PM 562J RD%PM 562J RD%PM 562J
S1 S2 ESISTO Symbol R1 R2 R3 R4	Push switch (F RS Carbon film Carbon film Carbon film Carbon film Carbon film	OW FILTE HIGH FILT 5.6k 5.6k 5.6k 5.6k 5.6k		ASG-019 ASG-019 Part No. RD%PM 562J RD%PM 562J RD%PM 562J RD%PM 562J
S1 S2 ESISTO Symbol R1 R2 R3	Push switch (F RS Carbon film Carbon film Carbon film	OW FILTE HIGH FILT cription 5.6k 5.6k 5.6k 5.6k		ASG-019 ASG-019 Part No. RD%PM 562J RD%PM 562J RD%PM 562J
S1 S2 ESISTO Symbol R1 R2 R3 R4 R5 R6	Push switch (H RS Carbon film Carbon film Carbon film Carbon film Carbon film	OW FILTE HIGH FILT 5.6k 5.6k 5.6k 5.6k 5.6k 1M		ASG-019 ASG-019 Part No. RD%PM 562J RD%PM 562J RD%PM 562J RD%PM 562J RD%PM 105J RD%PM 105J
S1 S2 ESISTO Symbol R1 R2 R3 R4 R5 R6 R7	Push switch (H RS Carbon film Carbon film Carbon film Carbon film Carbon film Carbon film Carbon film	OW FILTE HIGH FILT 5.6k 5.6k 5.6k 5.6k 1M 1M 1M		ASG-019 ASG-019 Part No. RD%PM 562J RD%PM 562J RD%PM 562J RD%PM 562J RD%PM 105J
S1 S2 ESISTO Symbol R1 R2 R3 R4 R5 R6 R7 R8	Push switch (F RS Carbon film Carbon film Carbon film Carbon film Carbon film Carbon film Carbon film Carbon film	OW FILTE HIGH FILT 5.6k 5.6k 5.6k 5.6k 1M 1M 1M 1M		ASG-019 ASG-019 Part No. RD%PM 562J RD%PM 562J RD%PM 562J RD%PM 562J RD%PM 105J RD%PM 105J
S1 S2 ESISTO Wmbol R1 R2 R3 R4 R5 R6 R7 R8 R9	Push switch (H RS Carbon film Carbon film Carbon film Carbon film Carbon film Carbon film Carbon film Carbon film Carbon film Carbon film	OW FILTE HIGH FILT 5.6k 5.6k 5.6k 5.6k 1M 1M 1M		ASG-019 ASG-019 Part No. RD%PM 562J RD%PM 562J RD%PM 562J RD%PM 105J RD%PM 105J RD%PM 105J
S1 S2 ESISTO Symbol R1 R2 R3 R4 R5 R6 R7 R8	Push switch (F RS Carbon film Carbon film Carbon film Carbon film Carbon film Carbon film Carbon film Carbon film	OW FILTE HIGH FILT 5.6k 5.6k 5.6k 5.6k 1M 1M 1M 1M		ASG-019 ASG-019 Part No. RD%PM 562J RD%PM 562J RD%PM 562J RD%PM 105J RD%PM 105J RD%PM 105J RD%PM 105J RD%PM 105J
S1 S2 ESISTO Xymbol R1 R2 R3 R4 R5 R6 R7 R8 R9	Push switch (H RS Carbon film Carbon film Carbon film Carbon film Carbon film Carbon film Carbon film Carbon film Carbon film Carbon film	OW FILTE HIGH FILT 5.6k 5.6k 5.6k 5.6k 1M 1M 1M 1M 1M 5.6k		ASG-019 ASG-019 Part No. RD%PM 562J RD%PM 562J RD%PM 562J RD%PM 105J RD%PM 105J RD%PM 105J RD%PM 105J RD%PM 105J RD%PM 105J RD%PM 562J
S1 S2 ESISTO Symbol R1 R2 R3 R4 R5 R4 R5 R6 R7 R8 R9 R10	Push switch (H RS Carbon film Carbon film Carbon film Carbon film Carbon film Carbon film Carbon film Carbon film Carbon film Carbon film	OW FILTE HIGH FILT 5.6k 5.6k 5.6k 5.6k 1M 1M 1M 1M 5.6k 5.6k 5.6k		ASG-019 ASG-019 Part No. RD%PM 562J RD%PM 562J RD%PM 562J RD%PM 105J RD%PM 105J RD%PM 105J RD%PM 105J RD%PM 105J RD%PM 562J RD%PM 562J
S1 S2 ESISTO Symbol R1 R2 R3 R4 R5 R6 R7 R8 R9 R10 R11	Push switch (H RS Carbon film Carbon film Carbon film Carbon film Carbon film Carbon film Carbon film Carbon film Carbon film Carbon film	OW FILTE HIGH FILT 5.6k 5.6k 5.6k 5.6k 1M 1M 1M 1M 5.6k 5.6k 5.6k 5.6k 5.6k		ASG-019 ASG-019 Part No. RD%PM 562J RD%PM 562J RD%PM 562J RD%PM 105J RD%PM 105J RD%PM 105J RD%PM 105J RD%PM 562J RD%PM 562J RD%PM 562J
S1 S2 ESISTO Symbol R1 R2 R3 R4 R5 R6 R7 R8 R9 R10 R11 R12	Push switch (H RS Carbon film Carbon film	OW FILTE HIGH FILT 5.6k 5.6k 5.6k 5.6k 1M 1M 1M 1M 5.6k 5.6k 5.6k 5.6k 5.6k 5.6k		ASG-019 ASG-019 Part No. RD%PM 562J RD%PM 562J RD%PM 562J RD%PM 105J RD%PM 105J RD%PM 105J RD%PM 105J RD%PM 562J RD%PM 562J RD%PM 562J RD%PM 562J
S1 S2 ESISTO Symbol R1 R2 R3 R4 R5 R6 R7 R8 R9 R10 R11 R12 R11 R12 R13	Push switch (H RS Carbon film Carbon film	OW FILTE HIGH FILT 5.6k 5.6k 5.6k 5.6k 1M 1M 1M 1M 5.6k 5.6k 5.6k 5.6k 5.6k 5.6k 5.6k 5.6k		ASG-019 ASG-019 ASG-019 Part No. RD%PM 562J RD%PM 562J RD%PM 562J RD%PM 105J RD%PM 105J RD%PM 105J RD%PM 105J RD%PM 562J RD%PM 562J RD%PM 562J RD%PM 562J RD%PM 562J RD%PM 562J RD%PM 562J
S1 S2 ESISTO Symbol R1 R2 R3 R4 R5 R6 R7 R8 R9 R10 R11 R12 R13 R14 R15	Push switch (H RS Carbon film Carbon film	OW FILTE HIGH FILT 5.6k 5.6k 5.6k 5.6k 1M 1M 1M 1M 1M 5.6k 5.6k 5.6k 5.6k 5.6k 5.6k 5.6k 10k 10k 10k		ASG-019 ASG-019 ASG-019 Part No. RD%PM 562J RD%PM 562J RD%PM 562J RD%PM 105J RD%PM 105J RD%PM 105J RD%PM 105J RD%PM 105J RD%PM 562J RD%PM 562J RD%PM 562J RD%PM 562J RD%PS 103J RD%PS 103J RD%PS 103J
S1 S2 ESISTO Symbol R1 R2 R3 R4 R5 R6 R7 R8 R9 R10 R11 R12 R13 R14 R15 R16	Push switch (H RS Carbon film Carbon film	OW FILTE HIGH FILT 5.6k 5.6k 5.6k 5.6k 1M 1M 1M 1M 1M 5.6k 5.6k 5.6k 5.6k 5.6k 5.6k 5.6k 10k 10k 10k		ASG-019 ASG-019 ASG-019 Part No. RD%PM 562J RD%PM 562J RD%PM 562J RD%PM 105J RD%PM 105J RD%PM 105J RD%PM 105J RD%PM 105J RD%PM 562J RD%PM 562J RD%PM 562J RD%PM 562J RD%PM 562J RD%PS 103J RD%PS 103J RD%PS 103J
S1 S2 ESISTO R1 R2 R3 R4 R5 R6 R7 R8 R9 R10 R11 R12 R13 R14 R15 R16 R17	Push switch (H RS Carbon film Carbon film	OW FILTE HIGH FILT 5.6k 5.6k 5.6k 5.6k 5.6k 1M 1M 1M 1M 1M 5.6k 5.6k 5.6k 5.6k 5.6k 5.6k 5.6k 10k 10k 10k 10k 10k 3.9k		ASG-019 ASG-019 ASG-019 Part No. RD%PM 562J RD%PM 562J RD%PM 562J RD%PM 105J RD%PM 105J RD%PM 105J RD%PM 105J RD%PM 562J RD%PM 562J RD%PM 562J RD%PM 562J RD%PM 562J RD%PM 562J RD%PM 562J RD%PM 562J RD%PM 562J RD%PS 103J RD%PS 103J RD%PS 103J RD%PS 103J RD%PS 103J
S1 S2 ESISTO Symbol R1 R2 R3 R4 R5 R6 R7 R8 R9 R10 R11 R12 R13 R14 R15 R16	Push switch (H RS Carbon film Carbon film	OW FILTE HIGH FILT 5.6k 5.6k 5.6k 5.6k 1M 1M 1M 1M 1M 5.6k 5.6k 5.6k 5.6k 5.6k 5.6k 5.6k 10k 10k 10k		ASG-019 ASG-019 Part No. RD%PM 562J RD%PM 562J RD%PM 562J RD%PM 105J RD%PM 105J RD%PM 105J RD%PM 105J RD%PM 105J RD%PM 562J RD%PM 562J RD%PM 562J RD%PM 562J RD%PM 562J RD%PM 562J RD%PM 562J RD%PM 503J RD%PS 103J

	escription	D	Symbol	Part No.	cription	Des	Symbol
RD1	2.2k	Carbon film	R71	RD%PS 123J	12k	Carbon film	R21
RD)	2.2k	Carbon film	R72	RD ¹ / ₄ PS 123J		Carbon film	R22
RD3	100	Carbon film	R73	RD%PS 123J	12k	Carbon film	23
RD)	100	Carbon film	R74	RD%PS 123J	12k	Carbon film	23
RD3	100	Carbon film	R75	RD%PM 122J	12k 1.2k	Carbon film	R25
RD%	100	Carbon film	R76	RD¼PM 122J	1.2k	Carbon film	R26
RD1/	330	Carbon film	R77	RD%PM 122J	1.2k	Carbon film	327
RD%	330	Carbon film	R78	RD%PM 122J	1.2k	Carbon film	127
RD%	330	Carbon film	R79	RD%PM 103J	1.2k	Carbon film	R29
RD%	330	Carbon film	R80	RD%PM 103J	10k	Carbon film	R30
RD%	100k	Carbon film	R81	RD%PM 103J	10k	Carbon film	R31
RD%	100k	Carbon film	R82	RD%PM 103J	10k	Carbon film	R32
RD%	100k	Carbon film	R83	RD%PM 102J	10k 1k	Carbon film	R33
RD%	100k	Carbon film	R84	RD%PM 102J	lk 1k	Carbon film	R34
RD%	82k	Carbon film	R85	RD%PM 102J	1k 1k	Carbon film	R35
RD%	82k	Carbon film	R86	RD%PM 102J	41	Caultana (ila)	D 26
RD%	82k	Carbon film	R87		1k	Carbon film	R36
RD%	82k	Carbon film	R88	RD%PM 153J	15k	Carbon film	R37
RD%	5.6k	Carbon film	R89	RD%PM 153J	15k	Carbon film	R38
RD%	5.6k	Carbon film	R90	RD%PM 153J RD%PM 153J	15k 15k	Carbon film Carbon film	R39 R40
RD%	5.6k	Carbon film	R91	RD%PM 153J	45	Carlan film	R41
RD2	5.6k	Carbon film	R92	RD%PM 153J	15k	Carbon film Carbon film	
RD2	470k	Carbon film	R93	RD%PM 153J	15k		R42 R43
RD2	470k	Carbon film	R94	RD%PM 153J	15k	Carbon film	R44
RD%	470k	Carbon film	R95	RD%PM 562J	15k 5.6k	Carbon film Carbon film	R45
RD%	470k	Carbon film	R96	RD%PM 562J	5.6k	Carbon film	R46
RD%	33k	Carbon film	R97	RD%PM 562J		Carbon film	R47
RD%	33k	Carbon film	R98	RD%PM 562J	5.6k	Carbon film	848
RD%	33k	Carbon film	R99	RD%PM 562J	5.6k	Carbon film	749
RD3	33k	Carbon film	R100	RD%PM 562J	5.6k 5.6k	Carbon film	R50
ACV	or dual 100k-B	Variable resisto	VR1	RD%PM 562J	E 01	Carbon film	R51
ACV		Variable resisto	VR2	RD%PM 562J	5.6k	Carbon film	1
ACV		Variable resisto	VR3	RD%PM 103J	5.6k	Carbon film	R52
ACV		Variable resisto	VR4	RD%PM 103J	10k	Carbon film	R53
				RD%PM 103J	10k 10k	Carbon film Carbon film	R54 R55
		IDUCTORS	SEMICON				
	•			RD¼PM 103J	10k	Carbon film	R56
P	Description		Symbol	RD%PS 564JNL	560k	Carbon film	R57
001/1		FET	Q1	RD%PS 564JNL	560k	Carbon film	R58
28K3 28K3		FET	02	RD%PS 564JNL	560k	Carbon film	R59
25K. 25K.		FET	0.2	RD%PS 564JNL	560k	Carbon film	R60
2SK		FET	Q4	RD%PS 124JNL	120k	Carbon film	R61
2SA		Transistor	Q5	RD%PS 124JNL	120k	Carbon film	R62
				RD%PS 124JNL	120k	Carbon film	763
2SA		Transistor	Q6	RD%PS 124JNL	120k	Carbon film	R64
2SA7		Transistor	Q7	RD%PM 822J	8.2k	Carbon film	R65
2SA7		Transistor	Q8	10741 11 0220	Jien		
2SC1		Transistor	Q9	RD1/2PM 822J	8.2k	Carbon film	766
2SC1		Transistor	Q10	RD¼PM 822J	8.2k	Carbon film	867
2001				RD%PM 822J	8.2k	Carbon film	368
			Q11	1			169
2SC1		Transistor		RD¼PM 222J	2.2k	Carbon film	09 1

Part No.			
RD¼PM 222J		$\bigcap $	
RD%PM 222J RD%PM 222J			
RD¼PM 101J RD¼PM 101J			
RD%PM 101J RD%PM 101J			
RD%PM 101J			
RD%PM 331J			
RD¼PM 331J			
RD%PM 331J RD%PM 331J			
RD¼PM 104J RD¼PM 104J			
RD%PM 104J			
RD%PM 104J RD%PM 823J			
RD%PM 823J RD%PM 823J		\frown	
RD%PM 823J		N. C.	
RD%PM 562J RD%PM 562J			
RD%PM 562J RD%PM 562J			
RD%PM 474J			
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		_	
RD¼PM 474J RD¼PM 333J			
RD%PM 333J		and the second sec	
RD¼PM 333J RD¼PM 333J			
110/41 10 3333			
ACV-110-0 ACV-110-0			
ACV-110-0			
ACV-110-0			
	L.		
Part No.			
2SK30A-Y or GR			
2SK30A-Y or GR 2SK30A-Y or GR			
2SK30A-Y or GR		-	
2SA725-F or G			
2SA725-F or G			
2SA725-F or G 2SA725-F or G			
2SC1312-F or G			
2SC1312-F or G			
2SC1312-F or G			
2SC1312-F or G			
		\frown	
		$\left(\left \cdot \right\rangle \right) =$	



QX-949A



Parts List of Power Supply Circuit A Assembly (AWR-080)

CAPACITORS

Symbol	Des	cription		Part No.
C1	Ceramic	0.01	150V	ACG-004
C2	Ceramic	0.01	150V	ACG-004
C3	Ceramic	0.01	150V	ACG-004
C4	Ceramic	0.01	150V	ACG-004
C5	Electrolytic	470	16V	CEA 471P 16
C6	Electrolytic	470	16V	CEA 471P 16
C7	Electrolytic	220	50V	CEA 221P 50
C8	Electrolytic	220	50V	CEA 221P 50
C9	Electrolytic	220	50V	CEA 221P 50
C10	Electrolytic	100	16V	CEA 101P 16
C11	Electrolytic	100	35V	CEA 101P 35
C12	Electrolytic	47	35V	CEA 470P 35
C13	Ceramic	0.01	50V	CKDYF 103Z 50
C14	Electrolytic	2,200	63V	CEB 222P 63
C15	Electrolytic	100	80V	CEA 101P 80
C16	Electrolytic	100	80V	CEA 101P 80
C17	Electrolytic	100	16V	CEA 101P 16
C18	Electrolytic	100	50V	CEA 101P 50
C19	Ceramic	0.01	50V	CKDYF 103Z 50
C20	Ceramic	0.01	50V	CKDYF 103Z 50
C21	Ceramic	0.01	50V	CKDYF 103Z 50

SEMICONDUCTORS

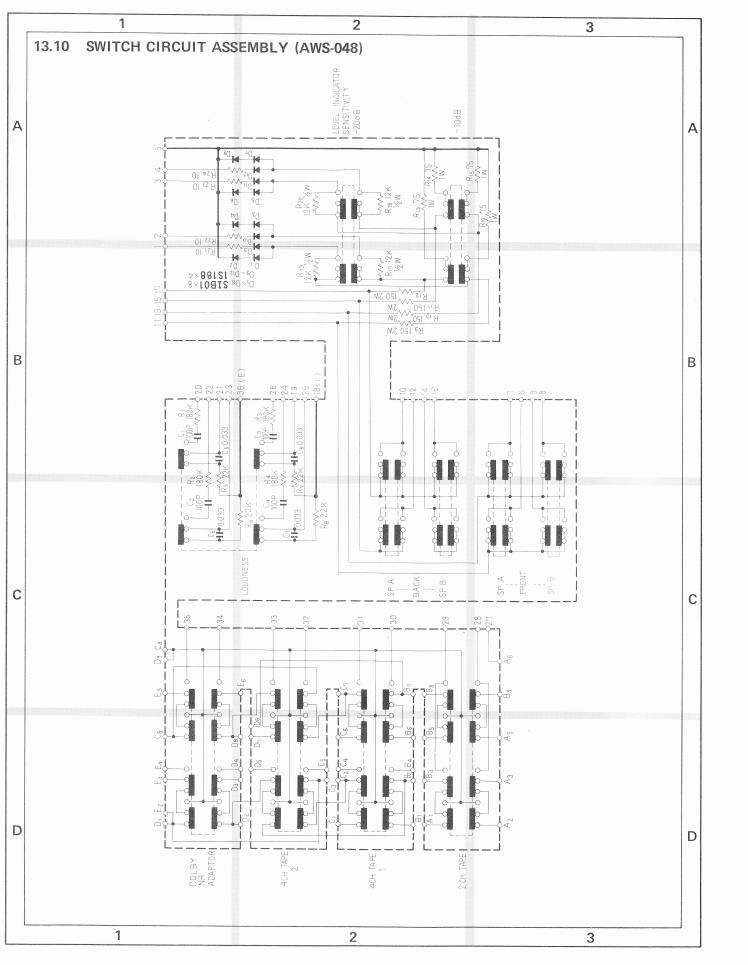
Symbol	Description	Part No.
Q1	Transistor	2SD525-0 or R
Q2	Transistor	2SC1318A-Q or R
Q3	Transistor	2SC945-R or Q
Q4	Transistor	2SD313-E or D
Q5	Transistor	2SB507P-E or D
Q6	Transistor	2SA720A-Q or R
D1	Diode	SIB01-01
		(1S1885)
D2	Diode	SIB01-02
		(1S1886)
D3	Diode	SIB01-02
D4	Diode	SIB01-02
~		(1S1886)
D5	Zener diode	WZ-140
D6	Zener diode	WZ-130

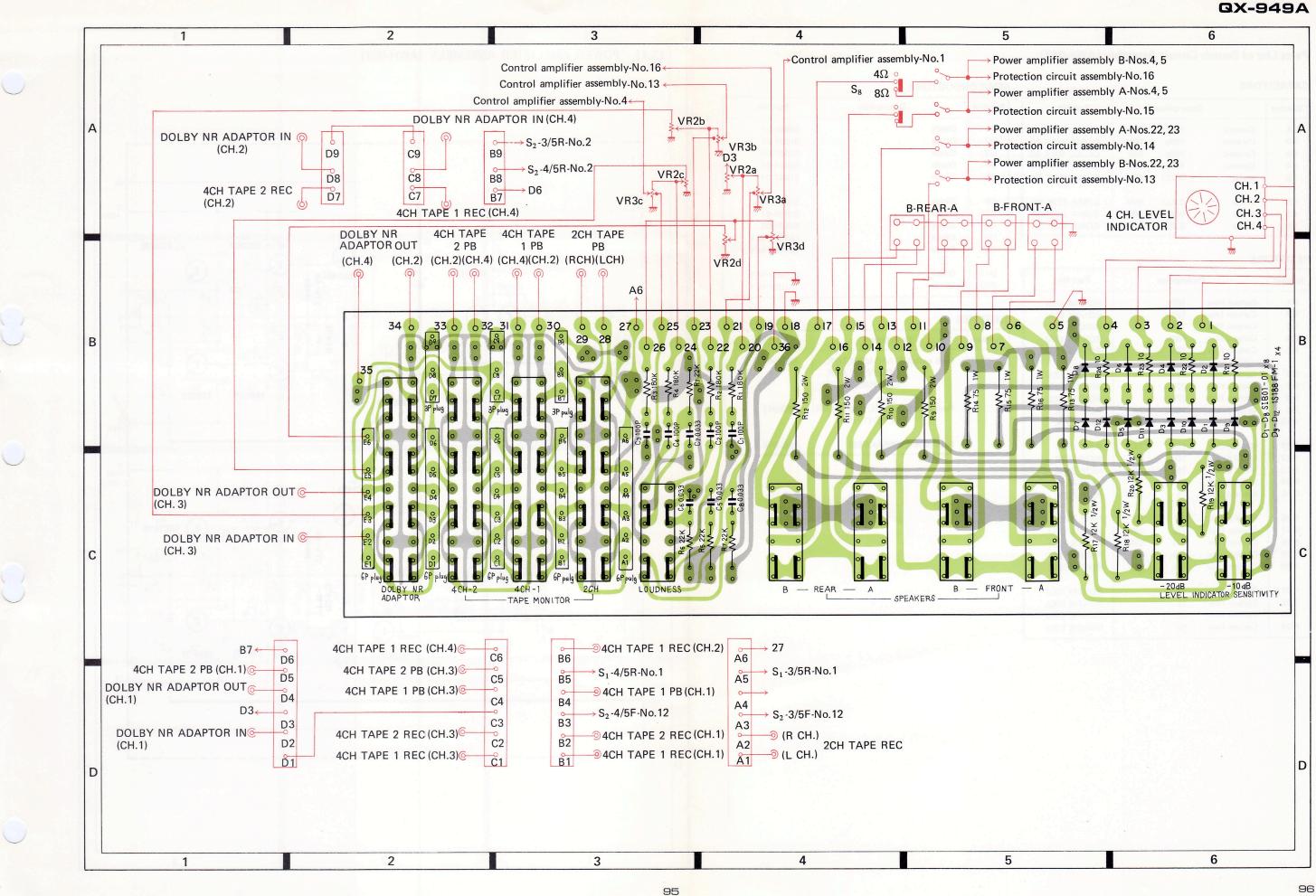
OTHERS

Symbol	Description	Part No.
	Tr socket	AKH-002
	Insulator wafer	AEC-043
	Fuse clip	AKR-013

RESISTORS

Symbol	Des	cription		Part No.
R1	Carbon film	18	5W	RD%PS 180J
R2	Carbon film	68		RD%PS 680J
R3	Carbon film	2.2		RD%PS 2R2J
R4	Wire wound	180		RT5B 181K
R5	Carbon film	4.7k		RD%PS 472J
R6	Carbon film	10k		RD¼PS 103J
R7	Carbon film	2.7k		RD¼PS 272J
R8	Carbon film	16k		RD¼PS 163J
R9	Carbon film	16k		RD¼PS 163J
R10	Carbon film	18		RD¼PS 180J
R11	Metal oxide	47	1W	RS1P 470J
R12	Carbon film	8.2k		RD%PS 822J
R13	Carbon film	2.2k		RD%PS 222J
R14	Carbon film	16k		RD%PS 163J
R15	Carbon film	33k		RD%PS 333J
R16	Metal oxide	1k	1W	RS1P 102J





Parts List of Switch Circuit Assembly (AWS-048)

CAPACITORS

Symbol	Description			Part No.
C1	Ceramic	100p	50V	CKDSL 101K 50
C2	Ceramic	100p	50V	CKDSL 101K 50
C3	Ceramic	100p	50V	CKDSL 101K 50
C4	Ceramic	100p	50V	CKDSL 101K 50
C5	Mylar	0.033	50V	CQMA 333K 50
C6	Mylar	0.033	50V	CQMA 333K 50
C7	Mylar	0.033	50V	CQMA 333K 50
C8	Mylar	0.033	50V	CQMA 333K 50

RESISTORS

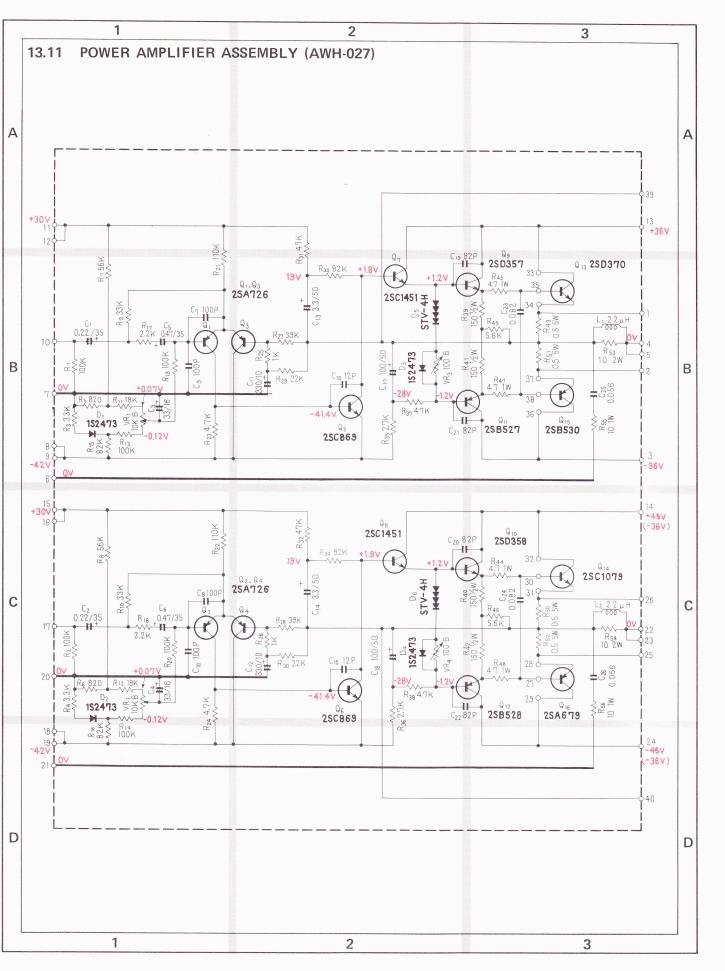
Symbol	D	escription		Part No.
R1	Carbon film	180k		RD1/2PM 184J
R2	Carbon film	180k		RD¼PM 184J
R3	Carbon film	180k		RD1/2 PM 184J
R4	Carbon film	180k		RD%PM 184J
R5	Carbon film	22k		RD¼PM 223J
R6	Carbon film	22k		RD%PM 223J
R7	Carbon film	22k		RD¼PM 223J
R8	Carbon film	22k		RD%PM 223J
R9	Metal oxide	150	2W	RS2P 151K
R10	Metal oxide	150	2W	RS2P 151K
R11	Metal oxide	150	2W	RS2P 151K
R12	Metal oxide	150	2W	RS2P 151K
R13	Metal oxide	75	1vv	RS1P 750K
R14	Metal oxide	75	1W	RS1P 750K
R15	Metal oxide	75	1W	RS1P 750K
R16	Metal oxide	75	1W	RS1P 750K
R17	Carbon film	12k	1/2W	RD1/2PS 123J
R18	Carbon film	12k	1/2W	RD1/2PS 123J
R19	Carbon film	12k	1/2W	RD½PS 123J
R20	Carbon film	12k	½₩	RD½PS 123J
R21	Carbon film	10		RD%PM 100J
R22	Carbon film	10		RD¼PM 100J
R23	Carbon film	10		RD%PM 100J
R24	Carbon film	10		RD%PM 100J

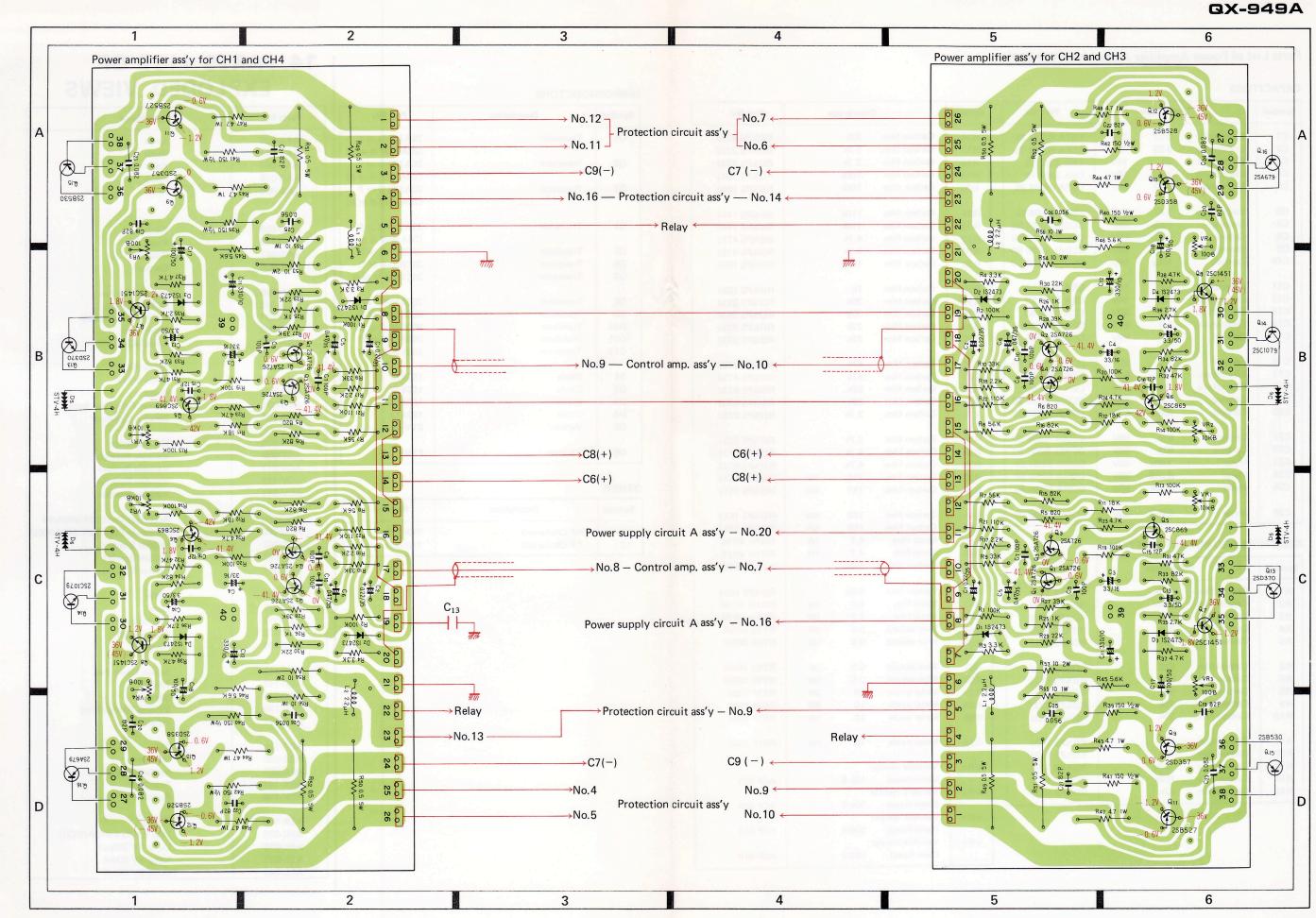
SEMICONDUCTORS

Symbol	Description	Part No.
D1	Diode	SIB01-01
D2	Diode	SIB01-01
D3	Diode	SIB01-01
D4	Diode	SIB01-01
D5	Diode	SIB01-01
D6	Diode	SIB01-01
D7	Diode	SIB01-01
D8	Diode	SIB01-01
D9	Diode	1S188 FM-1
D10	Diode	1S188 FM-1
		An 1997 - Construction Anno 1997-1997 - 19
D11	Diode	1S188 FM-1
D12	Diode	1S188 FM-1

SWITCHES

Symbol	Description	Part No.
	Push switch (TAPE MONITOR, DOLBY NR ADP, LOUDNESS)	ASG-049
	Push switch (LEVEL INDCATOR SENSITIVITY)	ASG-047
	Push switch (SPEAKERS)	ASG-046



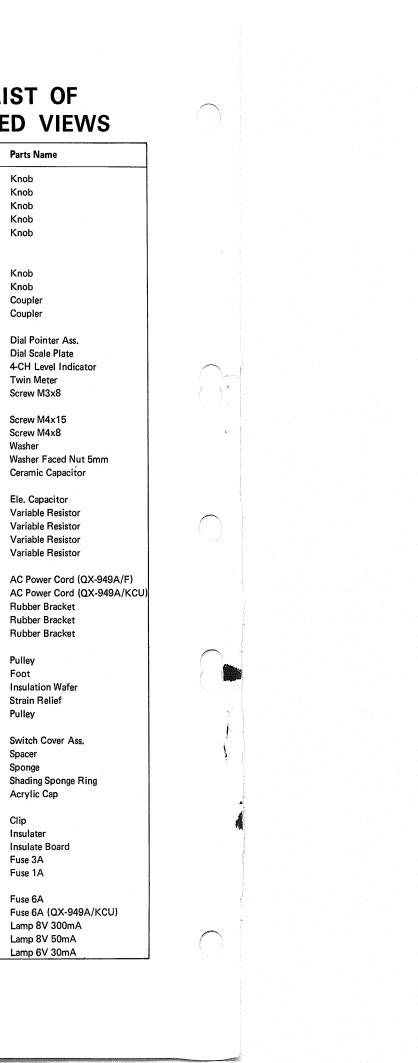


Parts List of Power Amplifier Assembly (AWH-027)

CAPACITORS

Symbol	C	Description		Part No.	Symbol	ана с с	Description	1	Part No.
C1	Electrolytic	0.22	35V	CSZA R22M 35	R16	Carbon film	82k	-	RD%PS 823J
C2	Electrolytic	0.22	35V	CSZA R22M 35	R17	Carbon film	2.2k		RD%PS 222J
C3	Electrolytic	33	16V	CEA 330P 16	R18	Carbon film	2.2k		RD%PS 222J
C4	Electrolytic	33	16V		R19	Carbon film	100k		
C5		0.47		CEA 330P 16		Carbon film	100k		RD%PS 104J
5	Electrolytic	0.47	35V	CSZA R47M 35	R20		TOUK		RD%PS 104J
C6	Electrolytic	0.47	35V	CSZA R47M 35	R21	Carbon film	110k		RD%PS 114J
C7	Ceramic	100p	50V	CCDSL 101K 50	R22	Carbon film	110k		RD%PS 114J
C8	Ceramic	100p	50V	CCDSL 101K 50	R23	Carbon film	4.7k		RD%PS 472J
C9	Ceramic	100p	50V	CCDSL 101K 50	R24	Carbon film	4.7k		RD%PS 472J
C10	Ceramic	100p	50V	CCDSL 101K 50	R25	Carbon film	1k		RD%PS 102J
C11	Electrolutio	220	101/	054 2210 10		0. h. Ch.			
C11	Electrolytic	330	10V	CEA 331P 10	R26	Carbon film	1k		RD%PS 102J
C12	Electrolytic	330	10V	CEA 331P 10	R27	Carbon film	39k		RD%PS 393.
C13	Electrolytic	3.3	50V	CEA 3R3P 50	R28	Carbon film	39k		RD%PS 393J
C14	Electrolytic	3.3	50V	CEA 3R3P 50	R29	Carbon film	22k		RD%PS 223J
C15	Ceramic	12p	50V	CCDSL 120K 50	R30	Carbon film	22k		RD%PS 223.
C16	Ceramic	12p	50V	CCDSL 120K 50	R31	Carbon film	47k		RD%PS 473.
C17	Electrolytic	100	50V	CEA 101P 50	R32	Carbon film	47k		RD%PS 473.
C18	Electrolytic	100	50V	CEA 101P 50	R33	Carbon film	82k		RD%PS 823.
C19	Ceramic	82p	50V	CCDSL 820K 50	R34	Carbon film	82k		RD%PS 823.
C20	Ceramic	82p	50V	CCDSL 820K 50	R35	Carbon film	2.7k		RD%PS 272.
C21	Ceramic	82p	50V	CCDSL 820K 50	R36	Carbon film	2.7k		RD%PS 272.
C22	Ceramic	82p	50V	CCDSL 820K 50	R37	Carbon film	4.7k		RD%PS 472.
C23	Mylar	0.082	50V	CQMA 823M 50	R38	Carbon film	4.7k		RD%PS 472.
C24	Mylar	0.082	50V	CQMA 823M 50	R39	Carbon film	150	1/2W	RD%PS 151.
C25	Mylar	0.056	50V	CQMA 563M 50	R40	Carbon film	150	.%W	RD%PS 151.
C26	Mylar	0.056	50V	CQMA 563M 50	DA1	Carbon film	150	1⁄2W	
020	iviyiai	0.000	500	CUIVIA 505IVI 50	R41				RD%PS 151J
					R42	Carbon film	150	½W	RD%PS 151.
ESISTORS AND POTENTIOMETERS				R43	Metal film	4.7	1W	RN1H 4R7K	
					R44 R45	Metal film Carbon film	4.7 5.6k	1W	RN1H 4R7K RD%PS 562.
Symbol	D	escription	<u> </u>	Part No.	1145	our boilt mini	0.00		10/41 0 0020
R1	Carbon film	100k		RD%PS 104J	R46	Carbon film	5.6k		RD%PS 562J
R2	Carbon film	100k		RD1/4PS 104J	R47	Metal film	4.7	1W	RN1H 4R7K
R3	Carbon film	3.3k		RD%PS 332J	R48	Metal film	4.7	1W	RN1H 4R7K
R4	Carbon film	3.3k		RD%PS 332J	R49	Wire wound	0.5	5W	RT5B 0R5K
R5	Carbon film	820		RD%PS 821J	R50	Wire wound	0.5	5W	RT5B 0R5K
DC	Carbon fil-	020			DE1	Wire wound	0 5	E 14/	
R6	Carbon film	820		RD%PS 821J	R51		0.5	5W	RT5B 0R5K
R7	Carbon film	56k		RD%PS 563J	R52	Wire wound	0.5	5W	RT5B 0R5K
R8	Carbon film	56k		RD%PS 563J	R53	Metal oxide	10	2W	RS2P 100J
R9	Carbon film	33k		RD%PS 333J	R54	Metal oxide	10	2W	RS2P 100J
R10	Carbon film	33k		RD%PS 333J	R55	Metal oxide	10	1W	RS1P 100J
R11	Carbon film	18k		RD%PS 183J	R56	Metal oxide	10	1W	RS1P 100J
R12	Carbon film	18k		RD1/4PS 183J					
R13	Carbon film	100k		RD%PS 104J	VR1	Variable resisto	or		1.1.1
R14	Carbon film	100k		RD%PS 104J		(Semi-fixed)	10k-B		ACP-029
	Carbon film	82k		RD%PS 823J	VR2	Variable resisto			
R15						(Semi-fixed)	10k-B		ACP-029
R15						Variable resisto			
R15					VR3				1. Sec. 1. Sec
R15					VR3	(Semi-fixed)	100-B		ACP-019
R15					VR3 VR4		100-B		ACP-019

			14. PARTS LIST OF EXPLODED VIEV		
Symbol	DUCTORS Description	Part No.	Parts No.	Parts Name	
Q1	Transistor	2SA726-G or F	AAA-023	Knob	
		(2SA763F-6 or 5)	AAB-056	Knob	
Q2	Transistor	2SA726-G or F	AAB-065	Knob	
		(2SA763F-6 or 5)	AAB-079	Knob	
Q3	Transistor	2SA726-G or F	AAB-080	Knob	
		(2SA763F-6 or 5)			
Q4	Transistor	2SA726-G or F	AAD-055	Knob	
		(2SA763F-6 or 5)	AAD-108	Knob	
Q5	Transistor	2SC869-C or D	AAE-007	Coupler	
Q6	Transistor	2SC869-C or D	AAE-008	Coupler	
Q7	Transistor	2SC1451-V or B			
			AAF-036	Dial Pointer Ass.	
Q8	Transistor	2SC1451-V or B	AAG-063	Dial Scale Plate	
Q9 [.]	Transistor	2SD357-C or D	AAW-021	4-CH Level Indic	
Q10	Transistor	2SD358-C or D	AAW-042	Twin Meter	
Q11	Transistor	2SB527-C or D	ABA-002	Screw M3x8	
Q12	Transistor	2SB528-C or D			
			ABA-010	Screw M4x15	
D1	Diode	1S2473	ABA-012	Screw M4x8	
D2	Diode	1S2473	ABE-006	Washer	
D3	Diode	1S2473	ABN-008	Washer Faced Nu	
D4	Diode	1S2473	ACG-001	Ceramic Capacito	
D5	Varistor	STV-4			
			ACH-029	Ele. Capacitor	
D6	Varistor	STV-4	ACT-009	Variable Resistor	
			ACV-017	Variable Resistor	
			ACV-110	Variable Resistor	
THER			ACV-311	Variable Resistor	
Symbol	Description	Part No.	ADG-004	AC Power Cord	
L1	AF Choke coil	T63-009	ADG-005	AC Power Cord (
L2	AF Choke coil	т63-009	AEB-042	Rubber Bracket	
			AEB-043	Rubber Bracket	
			AEB-044	Rubber Bracket	
			AEC-017	Pulley	
			AEC-027	Foot	
			AEC-076	Insulation Wafer	
			AEC-079	Strain Relief	
			AEC-101	Pulley	
			AEC-110	Switch Cover As	
			AEC-116	Spacer	
			AEC-119	Sponge	
			AEC-120	Shading Sponge	
			AEC-121	Acrylic Cap	
			AEC-136	Clip	
			AEE-008	Insulater	
			AEE-009	Insulate Board	
			AEK-101	Fuse 3A	
			AEK-106	Fuse 1A	
			AEK-109	Fuse 6A	
			AEK-205	Fuse 6A (QX-94	
		· · ·	AEL-015	Lamp 8V 300mA	
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			AEL-022 AEL-025	Lamp 8V 50mA Lamp 6V 30mA	



PIONEER ELECTRONIC CORPORATION

4-1, Meguro 1-Chome, Meguro-ku, Tokyo 153, Japan
 U.S. PIONEER ELECTRONICS CORPORATION
 75 Oxford Drive, Moonachie, New Jersey 07074, U.S.A.
 PIONEER ELECTRONIC (EUROPE) N.V.
 Luithagensteenweg no. 9, 2030 Antwerp, Belgium
 PIONEER ELECTRONICS AUSTRALIA PTY. LTD.
 178-184 Boundary Road, Braeside, Victoria 3195, Australia

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